

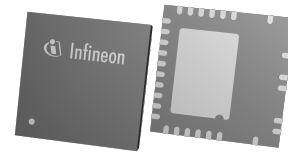
# XDP700-002 Hot-swap Controller

Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



## Features

- Compatible with Infineon's OptiMOST™
- Compatible with Infineon's Linear FET
- Wide input voltage range: -6.5 V to -80 V
- Transient withstand: up to -100 V for 500 ms
- Dedicated current and voltage ADCs: 12-bit
- Programmable and pre-set FET active SOA protection
- Integrated gate driver for external N-Channel MOSFET
- Configurable fast FET's shut down: two step turn-off or 1.5 A pull-down current
- PMBus interface: 1 MHz
- Precision input and output voltage monitoring and reporting:  $\leq 0.5\%$
- Precision FET's current monitoring and reporting:  $\leq 1.3\%$  at full ADC range
- Precision input power monitoring and reporting:  $\leq 1.8\%$
- Energy monitoring and reporting
- Programmable input and output OV and UV protections
- Support for external temperature sensor and OT protection
- Sequential turn-on capability
- 29-lead (6 mm x 6 mm) VQFN package
- -40°C to 125°C junction temperature



## Potential applications

- -48 V Pre-Isolated DC/DC Telecom infrastructure
- -24 V/-48 V Industrial systems
- Power distribution systems
- Intelligent e-fuse
- Network router and switches

## Product validation

Qualified for industrial applications according to the relevant tests of JEDEC47/20/22.

## Description

XDP700 is a wide input voltage Hot Swap and System monitoring Controller IC that drives a single or multiple parallel N-Channel MOSFETs. In addition to a controlled turn ON, XDP700 provides continuous system health monitoring and communication to the main MCU via PMBus interface. The high speed communication through PMBus allows system designers to disable the downstream sub-systems fully or partially.

It incorporates an extensive variety of system protections for safety operation and generates various protection responses depending on the severity of the incident. Latch off, reset, system shutdown and retry are some examples of response types. Its SOA protection effectively ensures that the system FET always operates under safe condition.

## XDP700-001 - XDP700-002 Comparison table

The following is a summary of the improvements and features added to XDP700-002

- Support SMBAlert, Connector good disconnect (CGDN) pin feature
- Supports SMBus alert response address (ARA)
- PMBus enable, LED and Restart features added.
- Configurable Vin UV Fault hysteresis.
- More Infineon FETs SOA profiles added.
- Size of turn off control register has been increased to 10-bits to allow more control over FET turn off.
- More options added to Watchdog timer, UV\_EN deglitch timer, SOAD timer and Startup current limit (IST).
- Modifications to boost mode with addition of full boost feature.
- Programmable multiplication factor for boost mode.

# XDP700-002 Hot-swap Controller

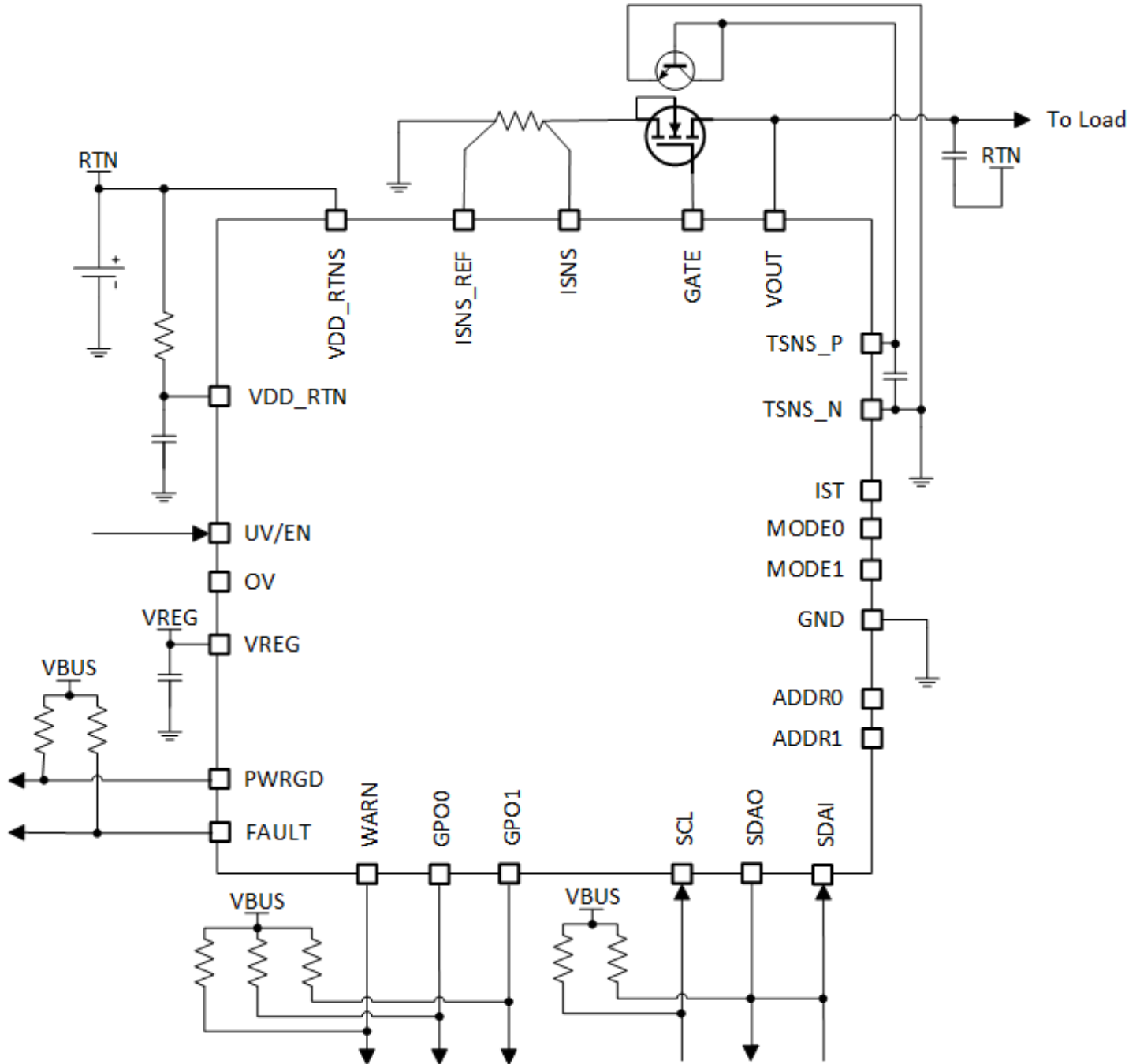
## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### Description

- Minimum regulation current down to 0.25A is achievable.
- Improved telemetry accuracy

Besides these added features, all erratas have been fixed and some features were improved in XDP700-002. For more information please consult XDP7xx-001 - XDP7xx-002 compatibility and migration application note.



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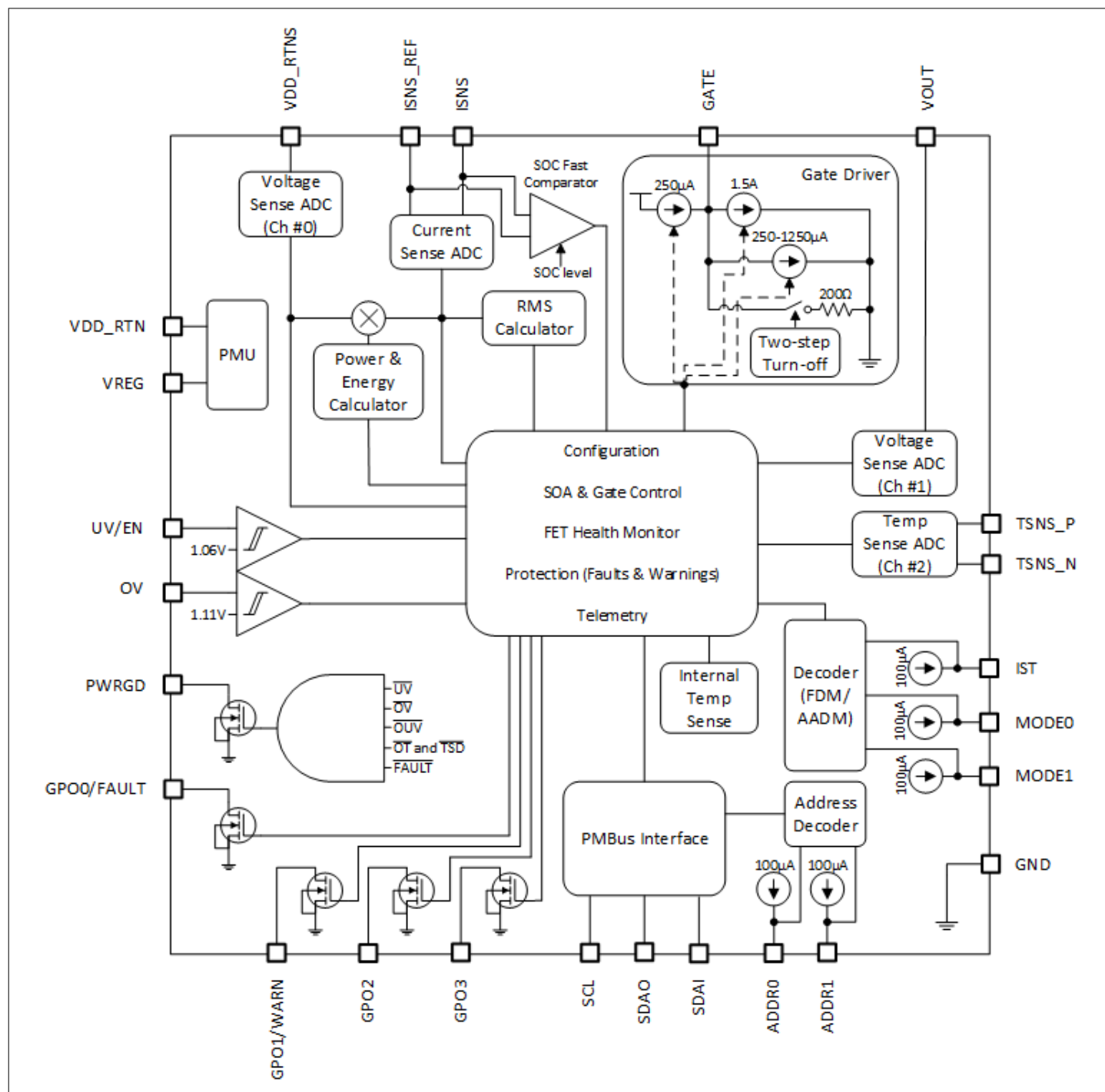
## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



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## 1 Block diagram



**Figure 1** Block diagram

## 2 Pin configuration and package

**Table 1** XDP700 pinout

| Pin # | Name                 | I/O | Type | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           | Connection if unused                               |
|-------|----------------------|-----|------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------|
| 1     | VDD_RTN              |     | P    | <b>Return path</b> pin. Power supply. A 100nF capacitor from this pin to GND is strongly recommended.                                                                                                                                                                                                                                                                                                                                                                                                                 | VDD_RTN                                            |
| 2     | GND                  |     | G    | <b>Ground</b> reference. Pin must be connected to system negative input.                                                                                                                                                                                                                                                                                                                                                                                                                                              | GND                                                |
| 3     | UV/EN                | I   | A    | <b>Undervoltage detection/enable</b> input. A voltage lower than $V_{UVEN\_LTH}$ on this pin turns off the FET.                                                                                                                                                                                                                                                                                                                                                                                                       | VREG                                               |
| 4     | OV                   | I   | A    | <b>Overvoltage detection</b> input. A voltage higher than $V_{OV\_UTH}$ on this pin turns off the FET.                                                                                                                                                                                                                                                                                                                                                                                                                | GND                                                |
| 5     | GND                  |     | G    | <b>Ground</b> reference. Pin must be connected to system negative input.                                                                                                                                                                                                                                                                                                                                                                                                                                              | GND                                                |
| 6     | VREG                 |     | P    | <b>VREG</b> (internal 5 V regulator) output. Connect a 1 $\mu$ F capacitor from this pin to GND.                                                                                                                                                                                                                                                                                                                                                                                                                      | Connect a 1 $\mu$ F capacitor from this pin to GND |
| 7     | PWRGD                | O   | D    | <b>Power good open drain</b> output. Pin is asserted when VOUT has reached its final level and steady state, FET is fully enhanced and no faults are detected. Its polarity is configurable.                                                                                                                                                                                                                                                                                                                          | Open                                               |
| 8     | GPO0/FAULT/SMBALERT# | O   | D    | <p><b>General-purpose digital output 0.</b> Pin configuration is programmable.</p> <p><b>Fault open drain output</b> if configured, the pin asserts High/Low (programmable) when a fault occurs. The faults that can trigger the pin can be configured.</p> <p><b>SMBALERT# open drain output</b> if configured, the pin asserts low when a fault or warning occurs (depending on configuration). The faults and warnings that can trigger the pin can be configured.</p> <p><b>Default configuration:</b> FAULT.</p> | Open                                               |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 2 Pin configuration and package

**Table 1** (continued) XDP700 pinout

| Pin # | Name                            | I/O | Type | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                      | Connection if unused                       |
|-------|---------------------------------|-----|------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------|
| 9     | GPO1/<br>WARN/LED#              | O   | D    | <p><b>General-purpose digital output 1.</b> Pin configuration is programmable.</p> <p><b>Warning open drain output</b> if configured, the pin asserts High/Low (programmable) when a warning occurs. The warnings that can trigger the pin can be configured.</p> <p><b>LED# open drain output</b> if configured, the pin asserts low when a fault occurs. The faults that can trigger the pin can be configured.</p> <p><b>Default configuration:</b> WARN.</p> | Open                                       |
| 10    | GPO2/CGDN                       | I/O | D    | <p><b>General-purpose digital output 2.</b> Pin configuration is programmable.</p> <p><b>Connector Good (CGDN)</b> if configured, if this pin is pulled externally low, the controller is allowed to turn on the FET.</p> <p><b>Default configuration:</b> Disabled.</p>                                                                                                                                                                                         | Open                                       |
| 11    | GPO3/<br>SMBALERT#/<br>PMBUS_EN | I/O | D    | <p><b>General-purpose digital output 3.</b> Pin configuration is programmable.</p> <p><b>SMBALERT# open drain output</b> if configured, the pin asserts low when a fault or warning occurs (depending on configuration). The faults and warnings that can trigger the pin can be configured.</p> <p><b>PMBUS_EN:</b> if configured, enabled or disabled PMBus communication.</p> <p><b>Default configuration:</b> Disabled.</p>                                  | Open                                       |
| 12    | SCL                             | I   | D    | <b>PMBus clock</b> input. The interface is rated to 1 MHz.                                                                                                                                                                                                                                                                                                                                                                                                       | Pull-up to VREG or external voltage source |
| 13    | SDAO                            | O   | D    | <b>PMBus data output.</b> Open drain pin. The serial data is split into an input and an output for easy use with isolators.                                                                                                                                                                                                                                                                                                                                      | Pull-up to VREG or external voltage source |
| 14    | SDAI                            | I   | D    | <b>PMBus data input.</b> The serial data is split into an input and an output for easy use with isolators.                                                                                                                                                                                                                                                                                                                                                       | Pull-up to VREG or external voltage source |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 2 Pin configuration and package

**Table 1** (continued) XDP700 pinout

| Pin # | Name   | I/O | Type | Description                                                                                                                                                                                                                                                   | Connection if unused |
|-------|--------|-----|------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------|
| 15    | ADDR0  | I   | A    | <b>Device address configuration 0 and 1</b> inputs. These pins can be tied to GND, left open or tied to GND through a resistor for a total of 16 unique PMBus device addresses.                                                                               | Open                 |
| 16    | ADDR1  | I   | A    |                                                                                                                                                                                                                                                               |                      |
| 17    | MODE0  | I   | A    | <b>Mode of operation 0 and 1</b> inputs. These pins can be tied to GND, left open or tied to GND through a resistor to select between FDM and AADM. Leave both pins open to select FDM.                                                                       | Open                 |
| 18    | MODE1  | I   | A    |                                                                                                                                                                                                                                                               |                      |
| 19    | IST    | I   | A    | <b>Start-up Current</b> setting input. A resistor to GND on this pin limits the maximum current allowed at start-up phase. This pin is used in AADM and it is to be kept open in FDM.                                                                         | Open                 |
| 20    | DNC    |     |      | Shall be kept open (unconnected).                                                                                                                                                                                                                             | Open                 |
| 21    | TSNS_N | I   | A    | <b>Temperature sense negative</b> terminal. Tie this pin to the emitter of an external NPN BJT to sense the FET's temperature. Connect a 1nF capacitor from this pin to TSNS_P. This pin must be connected locally to GND.                                    | GND                  |
| 22    | TSNS_P | I   | A    | <b>Temperature sense positive</b> terminal. Tie this pin to the base and collector of an external NPN BJT to sense the FET's temperature. Connect a 1nF capacitor from this pin to TSNS_N. If unused, this pin must be connected to GND.                      | GND                  |
| 23    | GND    |     | G    | <b>Ground</b> reference. Pin must be connected to system negative input.                                                                                                                                                                                      | GND                  |
| 24    | VOUT   | I   | A    | <b>Output voltage sense</b> input.                                                                                                                                                                                                                            | VOUT                 |
| 25    | GATE   | O   | A    | <b>Gate driver</b> output of single or multiple parallel external N channel FETs, which is/are regulated to a maximum allowed current by regulating the GATE pin voltage. GATE is pulled down when the supply is not within UV and OV limits or fault occurs. | GATE                 |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 2 Pin configuration and package

**Table 1** (continued) XDP700 pinout

| Pin # | Name     | I/O | Type | Description                                                                                                                          | Connection if unused |
|-------|----------|-----|------|--------------------------------------------------------------------------------------------------------------------------------------|----------------------|
| 26    | ISNS     | I   | A    | <b>Current Sense</b> input. Must be connected to the sense resistor pin that is connected to the source of the FET.                  | ISNS                 |
| 27    | ISNS_REF | I   | A    | <b>Current Sense</b> input. Must be connected to the sense resistor pin that's connected to system negative input (GND of the chip). | ISNS_REF             |
| 28    | DNC      |     |      | <b>Do not connect</b> pin (to provide isolation between high and low voltage signals).                                               | Open                 |
| 29    | VDD_RTNS | I   | A    | <b>Return Path Sense</b> input. Power supply sense input.                                                                            | VDD_RTN              |
| EP    | GND      |     | G    | <b>Ground</b> reference. The exposed pad must be connected to system negative input.                                                 | GND                  |

2 Pin configuration and package

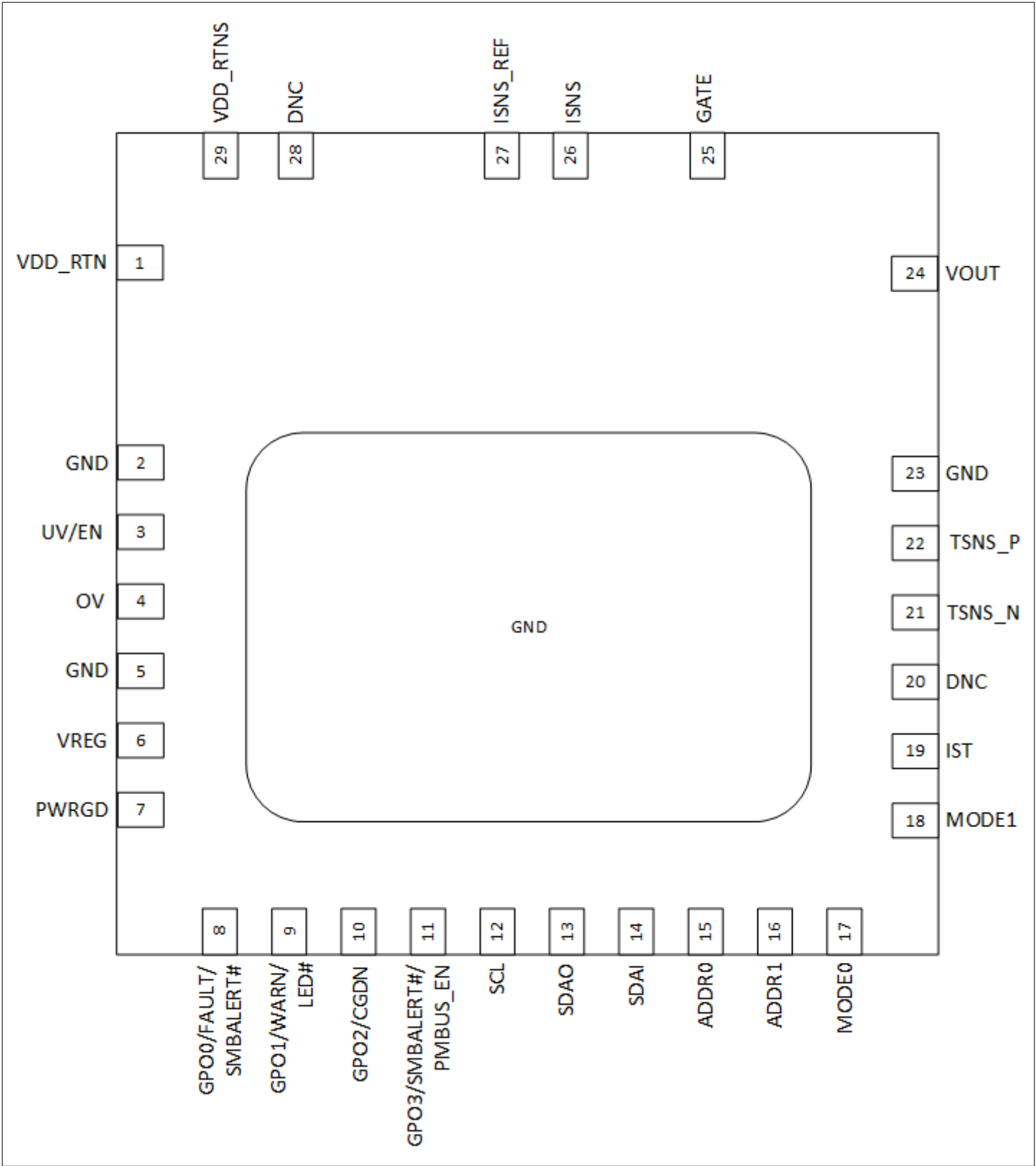


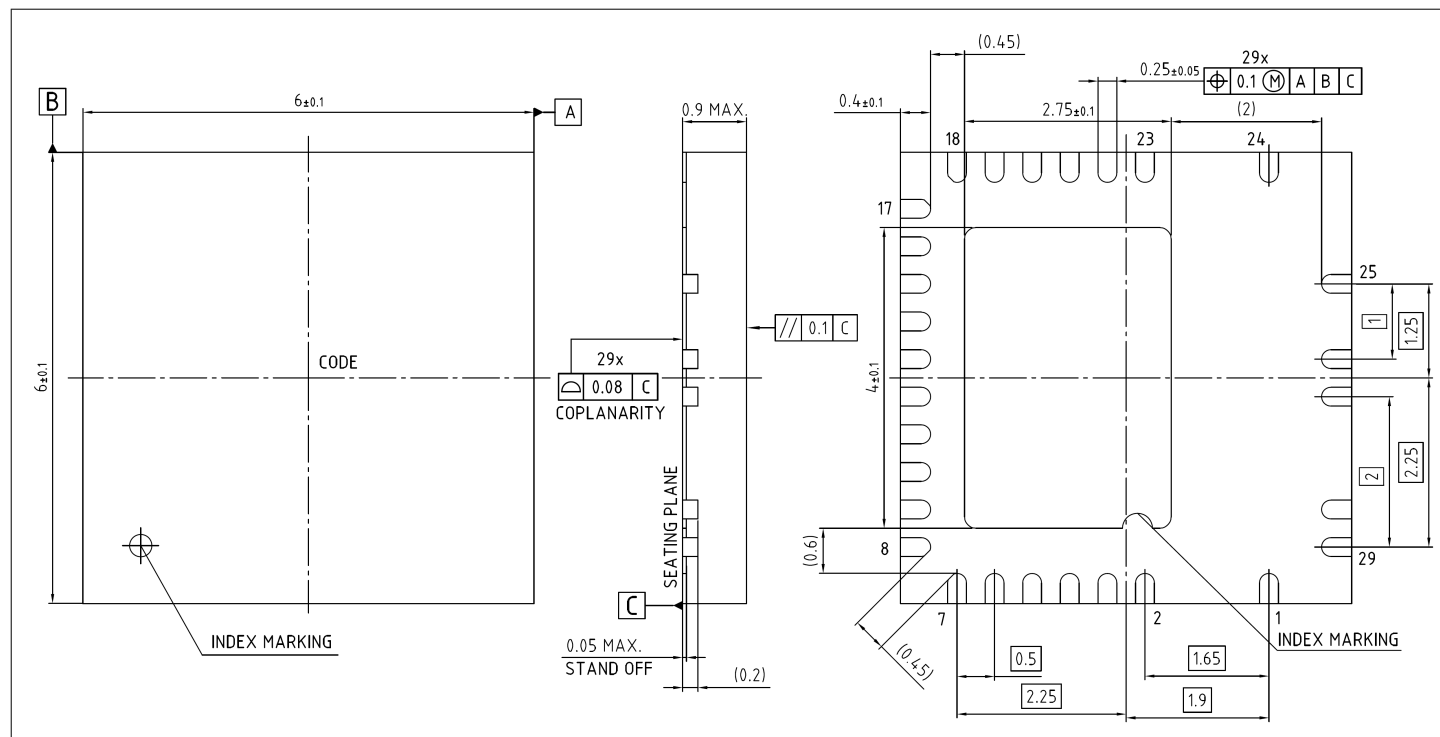
Figure 2 VQFN-29 6x6 pin-out

# XDP700-002 Hot-swap Controller

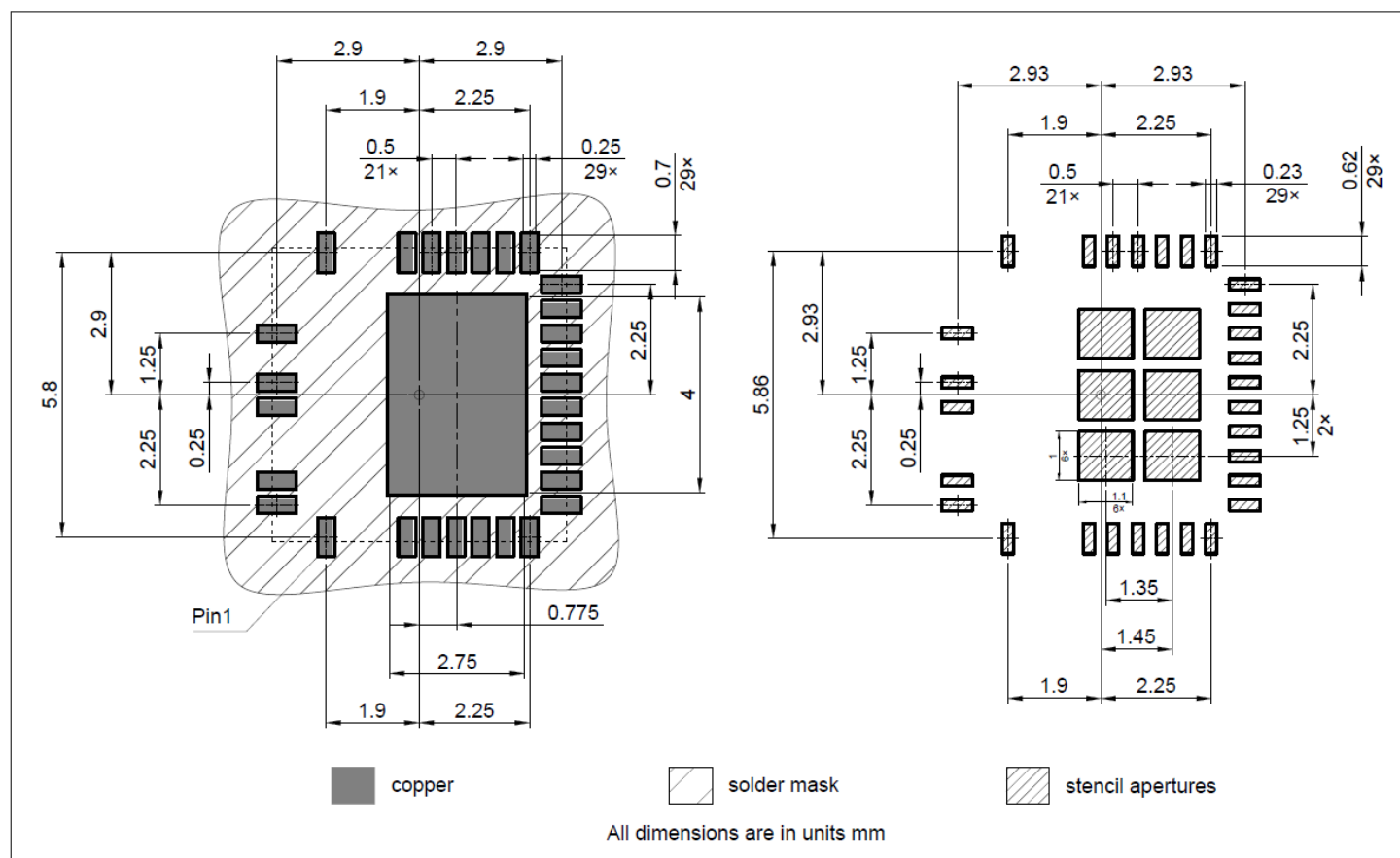
## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 2 Pin configuration and package



**Figure 3** Package dimensions



**Figure 4** Recommended footprint

## 3 General product characteristics

### 3.1 Absolute maximum ratings

**Table 2 Absolute maximum ratings**

The following operating conditions must not be exceeded in order to ensure correct operation and reliability of the device. All voltage parameters are referenced to GND unless otherwise specified, positive currents are flowing into the pin.

| Parameter                                                                 | Symbol                                                                                                                  | Values |      |      | Unit | Note or condition                                                                                                                                     |
|---------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------|--------|------|------|------|-------------------------------------------------------------------------------------------------------------------------------------------------------|
|                                                                           |                                                                                                                         | Min.   | Typ. | Max. |      |                                                                                                                                                       |
| Supply voltage at VDD_RT <sub>N</sub> pin                                 | VDD_RT <sub>N</sub> DC                                                                                                  | -0.3   | –    | 80   | V    |                                                                                                                                                       |
| Supply voltage transients at VDD_RT <sub>N</sub> pin                      | VDD_RT <sub>N</sub> AC                                                                                                  | –      | –    | 100  | V    | For 500 ms maximum.                                                                                                                                   |
| Voltage slew rate at VDD_RT <sub>N</sub> pin                              | VDD_RT <sub>N</sub> SR                                                                                                  | –      | –    | ±80  | V/μs | The RC filter (i.e. 10 Ω / 100 nF, or 100 Ω / 10 nF, etc.) on the pin is recommended, especially for high voltage (i.e. 48 V) applications.           |
| Voltage slew rate at VDD_RT <sub>NS</sub> pin                             | VDD_RT <sub>NS</sub> SR                                                                                                 | –      | –    | ±2   | V/ns | Max is defined by hot plug scenario. The resistor (i.e. 10 Ω) in series to the pin is recommended if an excessive dV/dt may occur in the application. |
| Voltage slew rate at VOUT pin                                             | VOUT <sub>SR</sub>                                                                                                      | –      | –    | ±80  | V/μs | An output cap (10 μF min) limits a slew rate on the pin.                                                                                              |
| Output voltage at GATE pin                                                | V <sub>GATE</sub>                                                                                                       | -0.3   | –    | 15   | V    |                                                                                                                                                       |
| GATE to SOURCE voltage                                                    | V <sub>GATE-SOURCE</sub> DC                                                                                             | -0.3   | –    | 12   | V    |                                                                                                                                                       |
| GATE to SOURCE voltage transients                                         | V <sub>GATE-SOURCE</sub> AC                                                                                             | –      | –    | 15   | V    | For 500ms max                                                                                                                                         |
| Output voltage at VREG pin                                                | V <sub>VREG</sub>                                                                                                       | -0.3   | –    | 6    | V    |                                                                                                                                                       |
| Digital pins output voltage (PWRGD, FAULT, WARN, GPO <sub>x</sub> , SDAO) | V <sub>PWRGD</sub> ,<br>V <sub>FAULT</sub> ,<br>V <sub>WARN</sub> , V <sub>GPO<sub>x</sub></sub> ,<br>V <sub>SDAO</sub> | -0.3   | –    | 6    | V    |                                                                                                                                                       |
| Input voltage at VDD_RT <sub>NS</sub> pin                                 | VDD_RT <sub>NS</sub> DC                                                                                                 | -0.3   | –    | 80   | V    |                                                                                                                                                       |
| Input voltage transients at VDD_RT <sub>NS</sub> pin                      | VDD_RT <sub>NS</sub> AC                                                                                                 | –      | –    | 100  | V    | For 500 ms maximum.                                                                                                                                   |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Table 2** (continued) Absolute maximum ratings

The following operating conditions must not be exceeded in order to ensure correct operation and reliability of the device. All voltage parameters are referenced to GND unless otherwise specified, positive currents are flowing into the pin.

| Parameter                                                                                                              | Symbol                                                                                                                                        | Values |      |      | Unit | Note or condition   |
|------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------|--------|------|------|------|---------------------|
|                                                                                                                        |                                                                                                                                               | Min.   | Typ. | Max. |      |                     |
| Input voltage at VOUT pin                                                                                              | VOUT <sub>DC</sub>                                                                                                                            | -1     | –    | 80   | V    |                     |
| Input voltage transients at VOUT pin                                                                                   | VOUT <sub>AC</sub>                                                                                                                            | –      | –    | 100  | V    | For 500 ms maximum. |
| Input voltage at ISNS_REF pin                                                                                          | V <sub>ISNS_REF</sub>                                                                                                                         | -0.3   | –    | 0.3  | V    |                     |
| Input voltage at ISNS pin                                                                                              | V <sub>ISNS</sub>                                                                                                                             | -0.8   | –    | 0.8  | V    |                     |
| Current Sense input voltage (ISNS_REF - ISNS)                                                                          | V <sub>ΔISNS</sub>                                                                                                                            | -0.8   | –    | 0.8  | V    |                     |
| Analog pins input voltage (UV/EN, OV, ADDR <sub>x</sub> , MODE <sub>x</sub> , V <sub>IST</sub> , V <sub>TSNS_N</sub> ) | V <sub>UV_EN</sub> , V <sub>OV</sub> , V <sub>ADDR<sub>x</sub></sub> , V <sub>MODE<sub>x</sub></sub> , V <sub>IST</sub> , V <sub>TSNS_N</sub> | -0.3   | –    | 6    | V    |                     |
| Input voltage at TSNS_P pin                                                                                            | V <sub>TSNS_P</sub>                                                                                                                           | -0.3   | –    | 2.5  | V    |                     |
| Digital pins input voltage (SCL, SDAI)                                                                                 | V <sub>SCL</sub> , V <sub>SDAI</sub>                                                                                                          | -0.3   | –    | 6    | V    |                     |
| Junction temperature range                                                                                             | T <sub>J</sub>                                                                                                                                | -40    | –    | 150  | °C   |                     |
| Storage temperature range                                                                                              | T <sub>S</sub>                                                                                                                                | -55    | –    | 150  | °C   |                     |

## 3.2 Functional range

**Table 3** Functional and performance ranges description

| Absolute voltage range at VDD_RT <sub>N</sub> | Communication interface | FET gate                | VREG |
|-----------------------------------------------|-------------------------|-------------------------|------|
| 0 ≤ V <sub>in</sub> < 6.5                     | Off                     | Off (passive pull-down) | Off  |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Table 3** (continued) Functional and performance ranges description

| Absolute voltage range at VDD_RTN | Communication interface | FET gate                                                                                               | VREG              |
|-----------------------------------|-------------------------|--------------------------------------------------------------------------------------------------------|-------------------|
| $6.5 \leq V_{in} < 9$             | On                      | Limited operation: - Off (active pull-down); - limited SOA regulation depending on gate driver supply; | 4.5V (minimum)    |
| $9 \leq V_{in} < 14$              |                         | - On/enhancement is not guaranteed (but $\geq 4.5$ V)                                                  | 5.0 V (typically) |
| $14 \leq V_{in} \leq 80$          |                         | Full operation: - Off (active pull-down); - full SOA regulation; - On/enhancement (typically 10.5 V)   |                   |

**Table 4** Functional range

The following operating conditions must not be exceeded in order to ensure correct operation and reliability of the device. All voltage parameters are referenced to GND unless otherwise specified, positive currents are flowing into the pin,  $T_A = 25^\circ\text{C}$ .

| Parameter                                                                          | Symbol                                                                                                                  | Values |            |      | Unit | Note or condition                                                                                                                |
|------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------|--------|------------|------|------|----------------------------------------------------------------------------------------------------------------------------------|
|                                                                                    |                                                                                                                         | Min.   | Typ.       | Max. |      |                                                                                                                                  |
| Supply voltage at VDD_RTN pin                                                      | VDD_RTN                                                                                                                 | 6.5    |            | 80   | V    |                                                                                                                                  |
| Supply voltage at VDD_RTN pin to enable all features                               | VDD_RTN <sub>EN</sub>                                                                                                   | 14     | –          | –    | V    | See <a href="#">Table 3</a> .                                                                                                    |
| VDD_RTNS sense pin input voltage                                                   | VDD_RTNS                                                                                                                | 6.5    | 12, 24, 48 | 80   | V    |                                                                                                                                  |
| VOUT sense pin input voltage                                                       | VOUTS                                                                                                                   | 0      | –          | 80   | V    |                                                                                                                                  |
| Current sense input voltage (ISNS_REF - ISNS)                                      | V <sub>ΔISNS</sub>                                                                                                      | -0.4   | –          | 0.4  | V    |                                                                                                                                  |
| Minimum overcurrent setting                                                        | I <sub>OC_MIN</sub>                                                                                                     | 5      | –          | –    | A    | Minimum I <sub>OC</sub> ( $I_{OC} = V_{SNS\_CS} / R_{SNS}$ , see <a href="#">Setting I<sub>OC</sub></a> ) for optimum stability. |
| Analog pins input voltage (UV/EN, OV, ADDR <sub>x</sub> , MODE <sub>x</sub> , IST) | V <sub>UV_EN</sub> , V <sub>OV</sub> , V <sub>ADDR<sub>x</sub></sub> , V <sub>MODE<sub>x</sub></sub> , V <sub>IST</sub> | 0      | –          | 5.5  | V    |                                                                                                                                  |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Table 4** (continued) Functional range

The following operating conditions must not be exceeded in order to ensure correct operation and reliability of the device. All voltage parameters are referenced to GND unless otherwise specified, positive currents are flowing into the pin,  $T_A = 25^\circ\text{C}$ .

| Parameter                                                    | Symbol                                               | Values |      |      | Unit             | Note or condition           |
|--------------------------------------------------------------|------------------------------------------------------|--------|------|------|------------------|-----------------------------|
|                                                              |                                                      | Min.   | Typ. | Max. |                  |                             |
| Digital pins input voltage (SCL, SDAI)                       | $V_{SCL}, V_{SDAI}$                                  | 0      | –    | 5.5  | V                |                             |
| Output voltage at VREG pin                                   | $V_{VREG}$                                           | 4.5    | 5    | 5.5  | V                | At 10 mA max external load. |
| Digital pins output voltage (PWRGD, FAULT, WARN, GPOX, SDAO) | $V_{PWRGD}, V_{FAULT}, V_{WARN}, V_{GPOX}, V_{SDAO}$ | 0      | –    | 5.5  | V                |                             |
| Junction temperature range                                   | $T_J$                                                | -40    | –    | 125  | $^\circ\text{C}$ |                             |

### 3.3 Thermal characteristics

**Table 5** Thermal characteristics

| Parameter                                    | Symbol               | Values |      |      | Unit | Note or condition                                              |
|----------------------------------------------|----------------------|--------|------|------|------|----------------------------------------------------------------|
|                                              |                      | Min.   | Typ. | Max. |      |                                                                |
| Thermal resistance Junction-to-case (bottom) | $R_{\theta JC\_Bot}$ | –      | 5    | –    | K/W  | PCB simulation setup as described in <a href="#">Table 6</a> . |
| Thermal resistance Junction-to-case (top)    | $R_{\theta JC\_Top}$ | –      | 30   | –    | K/W  | PCB simulation setup as described in <a href="#">Table 6</a> . |
| Thermal resistance Junction-to-Ambient       | $R_{\theta JA}$      | –      | 33   | –    | K/W  | PCB simulation setup as described in <a href="#">Table 6</a> . |
| Package power dissipation                    | $P_{PAK}$            | –      | –    | 0.8  | W    |                                                                |

**Table 6** PCB characteristics for thermal simulation

|                                 |                                   | $\lambda_{therm}$ [W/m-K] |
|---------------------------------|-----------------------------------|---------------------------|
| Metalization                    | JEDEC 2s2p (JESD 51-7, JESD 51-5) | 388                       |
| Cooling Area [mm <sup>2</sup> ] | none                              | 388                       |

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Note:** Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

**Note:** This thermal data was generated in accordance with JEDEC JESD51 standards. For more information, go to [www.jedec.org](http://www.jedec.org)

## 3.4 Current consumption

**Table 7** Current consumption

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = [V_{ISNS\_REF} - V_{ISNS}] = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter           | Symbol    | Values |      |      | Unit | Note or condition                                                |
|---------------------|-----------|--------|------|------|------|------------------------------------------------------------------|
|                     |           | Min.   | Typ. | Max. |      |                                                                  |
| Current consumption | $I_{VDD}$ | –      | 6    | 10   | mA   | VDD_RTN supply current:<br><br>FET is fully ON, telemetry in ON. |

## 3.5 ESD robustness

**Table 8** ESD robustness

| Parameter          | Symbol         | Values |      |            | Unit | Note or condition                                             |
|--------------------|----------------|--------|------|------------|------|---------------------------------------------------------------|
|                    |                | Min.   | Typ. | Max.       |      |                                                               |
| ESD Robustness HBM | $V_{ESD\_HBM}$ | –      | –    | $\pm 2000$ | V    | Human Body Model sensitivity as per ANSI/ESDA/JEDEC JS-001    |
| ESD Robustness CDM | $V_{ESD\_CDM}$ | –      | –    | $\pm 500$  | V    | Charge Device Model sensitivity as per ANSI/ESDA/JEDEC JS-002 |

## 3.6 Electrical characteristics

**Table 9** Electrical characteristics

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter | Symbol | Values |      |      | Unit | Note or condition |
|-----------|--------|--------|------|------|------|-------------------|
|           |        | Min.   | Typ. | Max. |      |                   |

### UV/EN and OV

|                       |                                    |      |      |      |   |  |
|-----------------------|------------------------------------|------|------|------|---|--|
| Input upper threshold | $V_{UVEN\_UTH}$ ,<br>$V_{OV\_UTH}$ | 1.09 | 1.11 | 1.13 | V |  |
| Input lower threshold | $V_{UVEN\_LTH}$ ,<br>$V_{OV\_LTH}$ | 1.04 | 1.06 | 1.08 | V |  |

### TSNS\_P, TSNS\_N

|                                |               |      |   |   |   |  |
|--------------------------------|---------------|------|---|---|---|--|
| TSNS_P operating voltage range | $V_{TSNS\_P}$ | 0.25 | – | 1 | V |  |
|--------------------------------|---------------|------|---|---|---|--|

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Table 9 (continued) Electrical characteristics**

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                                     | Symbol         | Values               |       |       | Unit | Note or condition                                                                                                                                                    |
|-----------------------------------------------|----------------|----------------------|-------|-------|------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|                                               |                | Min.                 | Typ.  | Max.  |      |                                                                                                                                                                      |
| TSNS_N operating voltage                      | $V_{TSNS\_N}$  | –                    | 0     | –     | V    |                                                                                                                                                                      |
| <b>ISNS_REF, ISNS</b>                         |                |                      |       |       |      |                                                                                                                                                                      |
| Minimum detectable differential voltage level | $V_{SNS\_MIN}$ | $0.01 * V_{SNS\_CS}$ | –     | –     | mV   | Between ISNS_REF and ISNS pins.                                                                                                                                      |
| Current sense differential voltage range      | $V_{SNS\_CS}$  | –                    | 12.5  | –     | mV   | Set by CS_RNG[1:0] bits: CS_RNG[1:0] = 00                                                                                                                            |
| Current sense differential voltage range      | $V_{SNS\_CS}$  | –                    | 25    | –     | mV   | Set by CS_RNG[1:0] bits: CS_RNG[1:0] = 01                                                                                                                            |
| Current sense differential voltage range      | $V_{SNS\_CS}$  | –                    | 50    | –     | mV   | Set by CS_RNG[1:0] bits: CS_RNG[1:0] = 10                                                                                                                            |
| Current sense differential voltage range      | $V_{SNS\_CS}$  | –                    | 100   | –     | mV   | Set by CS_RNG[1:0] bits: CS_RNG[1:0] = 11                                                                                                                            |
| SOC Differential voltage level                | $V_{SNS\_SOC}$ | 9.5                  | 12.5  | 15.5  | mV   | Set by SOC_FAULT_LIMIT[2:0] and CS_RNG[1:0] bits:<br>SOC_FAULT_LIMIT[2:0] = 000 and CS_RNG[1:0] = 00 or 01                                                           |
| SOC Differential voltage level                | $V_{SNS\_SOC}$ | 15.75                | 18.75 | 21.75 | mV   | Set by SOC_FAULT_LIMIT[2:0] and CS_RNG[1:0] bits:<br>SOC_FAULT_LIMIT[2:0] = 001 and CS_RNG[1:0] = 00 or 01                                                           |
| SOC Differential voltage level                | $V_{SNS\_SOC}$ | 22                   | 25    | 28    | mV   | Set by SOC_FAULT_LIMIT[2:0] and CS_RNG[1:0] bits:<br>SOC_FAULT_LIMIT[2:0] = 010 and CS_RNG[1:0] = 00 or 01; or SOC_FAULT_LIMIT[2:0] = 000 and CS_RNG[1:0] = 10 or 11 |
| SOC Differential voltage level                | $V_{SNS\_SOC}$ | 34.5                 | 37.5  | 40.5  | mV   | Set by SOC_FAULT_LIMIT[2:0] and CS_RNG[1:0] bits:<br>SOC_FAULT_LIMIT[2:0] = 011 and CS_RNG[1:0] = 00 or 01; or SOC_FAULT_LIMIT[2:0] = 001 and CS_RNG[1:0] = 10 or 11 |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Table 9 (continued) Electrical characteristics**

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                      | Symbol             | Values |      |      | Unit | Note or condition                                                                                                                                                    |
|--------------------------------|--------------------|--------|------|------|------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|                                |                    | Min.   | Typ. | Max. |      |                                                                                                                                                                      |
| SOC Differential voltage level | $V_{SNS\_SOC}$     | 47     | 50   | 53   | mV   | Set by SOC_FAULT_LIMIT[2:0] and CS_RNG[1:0] bits:<br>SOC_FAULT_LIMIT[2:0] = 100 and CS_RNG[1:0] = 00 or 01; or SOC_FAULT_LIMIT[2:0] = 010 and CS_RNG[1:0] = 10 or 11 |
| SOC Differential voltage level | $V_{SNS\_SOC}$     | 71     | 75   | 79   | mV   | Set by SOC_FAULT_LIMIT[2:0] and CS_RNG[1:0] bits:<br>SOC_FAULT_LIMIT[2:0] = 101 and CS_RNG[1:0] = 00 or 01; or SOC_FAULT_LIMIT[2:0] = 011 and CS_RNG[1:0] = 10 or 11 |
| SOC Differential voltage level | $V_{SNS\_SOC}$     | 96     | 100  | 104  | mV   | Set by SOC_FAULT_LIMIT[2:0] and CS_RNG[1:0] bits:<br>SOC_FAULT_LIMIT[2:0] = 110 and CS_RNG[1:0] = 00 or 01; or SOC_FAULT_LIMIT[2:0] = 100 and CS_RNG[1:0] = 10 or 11 |
| SOC Differential voltage level | $V_{SNS\_SOC}$     | 145    | 150  | 155  | mV   | Set by SOC_FAULT_LIMIT[2:0] and CS_RNG[1:0] bits:<br>SOC_FAULT_LIMIT[2:0] = 111 and CS_RNG[1:0] = 00 or 01; or SOC_FAULT_LIMIT[2:0] = 101 and CS_RNG[1:0] = 10 or 11 |
| SOC Differential voltage level | $V_{SNS\_SOC}$     | 193    | 200  | 207  | mV   | Set by SOC_FAULT_LIMIT[2:0] and CS_RNG[1:0] bits:<br>SOC_FAULT_LIMIT[2:0] = 110 and CS_RNG[1:0] = 10 or 11                                                           |
| SOC Differential voltage level | $V_{SNS\_SOC}$     | 290    | 300  | 310  | mV   | Set by SOC_FAULT_LIMIT[2:0] and CS_RNG[1:0] bits:<br>SOC_FAULT_LIMIT[2:0] = 111 and CS_RNG[1:0] = 10 or 11                                                           |
| Current sense ADC resolution   | ADC <sub>RES</sub> | –      | 12   | –    | bits |                                                                                                                                                                      |
| Max allowed negative current   | $I_{NEG\_MAX}$     | –      | 240  | –    | mA   | To trigger INEG warning.<br>$V_{SNS\_CS} = 12.5\text{ mV}$ , $R_{sns} = 1\text{ m}\Omega$ .                                                                          |
| Max allowed negative current   | $I_{NEG\_MAX}$     | –      | 520  | –    | mA   | To trigger INEG warning.<br>$V_{SNS\_CS} = 25\text{ mV}$ , $R_{sns} = 1\text{ m}\Omega$ .                                                                            |
| Max allowed negative current   | $I_{NEG\_MAX}$     | –      | 1100 | –    | mA   | To trigger INEG warning.<br>$V_{SNS\_CS} = 50\text{ mV}$ , $R_{sns} = 1\text{ m}\Omega$ .                                                                            |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Table 9 (continued) Electrical characteristics**

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                    | Symbol         | Values |      |      | Unit | Note or condition                                                                          |
|------------------------------|----------------|--------|------|------|------|--------------------------------------------------------------------------------------------|
|                              |                | Min.   | Typ. | Max. |      |                                                                                            |
| Max allowed negative current | $I_{NEG\_MAX}$ | –      | 2200 | –    | mA   | To trigger INEG warning.<br>$V_{SNS\_CS} = 100\text{ mV}$ , $R_{sns} = 1\text{ m}\Omega$ . |

#### GATE

|                                           |                           |       |      |       |               |                                                                                                                                          |
|-------------------------------------------|---------------------------|-------|------|-------|---------------|------------------------------------------------------------------------------------------------------------------------------------------|
| Gate voltage                              | $V_{GATE}$                | 8.5   | 10.5 | 12.0  | V             | $14\text{ V} \leq V_{DD\_RTN} \leq 80\text{ V}$ , $I_{GATE} \leq 5\text{ }\mu\text{A}$ , FET is fully ON.                                |
| Gate voltage                              | $V_{GATE}$                | 4.5   | –    | –     | V             | $6.5\text{ V} \leq V_{DD\_RTN} < 14\text{ V}$ , $I_{GATE} \leq 5\text{ }\mu\text{A}$ .                                                   |
| Pull-up current                           | $I_{GATE\_PU}$            | 200   | 250  | 300   | $\mu\text{A}$ | At $V_{GATE} = 5\text{ V}$                                                                                                               |
| Fast pull-down current                    | $I_{GATE\_FPD}$           | 0.825 | 1.5  | 2.175 | A             | Set by GATE_FAST_PD[0]: GATE_FAST_PD[0] = 0                                                                                              |
| GATE pin two step turn-off fast pull-down | $R_{GATE\_2ST\_FAST\_PD}$ | 156   | 200  | 244   | $\Omega$      | Set by GATE_FAST_PD[0]: GATE_FAST_PD[0] = 1                                                                                              |
| Slow pull-down current                    | $I_{GATE\_SPD}$           | 200   | 250  | 300   | $\mu\text{A}$ | Set by GATE_SLOW_PD[1:0] bits: GATE_SLOW_PD[1:0] = 00<br>Used for both regular/slow pull-down and second phase of the two-step turn-off. |
| Slow pull-down current                    | $I_{GATE\_SPD}$           | 400   | 500  | 600   | $\mu\text{A}$ | Set by GATE_SLOW_PD[1:0] bits: GATE_SLOW_PD[1:0] = 01<br>Used for both regular/slow pull-down and second phase of the two-step turn-off. |
| Slow pull-down current                    | $I_{GATE\_SPD}$           | 600   | 750  | 900   | $\mu\text{A}$ | Set by GATE_SLOW_PD[1:0] bits: GATE_SLOW_PD[1:0] = 10<br>Used for both regular/slow pull-down and second phase of the two-step turn-off. |
| Slow pull-down current                    | $I_{GATE\_SPD}$           | 1000  | 1250 | 1500  | $\mu\text{A}$ | Set by GATE_SLOW_PD[1:0] bits: GATE_SLOW_PD[1:0] = 11<br>Used for both regular/slow pull-down and second phase of the two-step turn-off. |

#### VDD\_RTNS

|                                                                                          |                 |   |    |   |               |                                                               |
|------------------------------------------------------------------------------------------|-----------------|---|----|---|---------------|---------------------------------------------------------------|
| Input current                                                                            | $I_{VDD\_RTNS}$ | – | 15 | – | $\mu\text{A}$ | At 48 V                                                       |
| On-chip input over voltage upper threshold for on-chip input overvoltage fault assertion | $OV_{IN\_UTH}$  | – | 70 | – | V             | Set by OVIN_FAULT_LIMIT[1:0] bits: OVIN_FAULT_LIMIT[1:0] = 00 |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Table 9** (continued) Electrical characteristics

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                                                                                | Symbol         | Values |                             |      | Unit | Note or condition                                                        |
|------------------------------------------------------------------------------------------|----------------|--------|-----------------------------|------|------|--------------------------------------------------------------------------|
|                                                                                          |                | Min.   | Typ.                        | Max. |      |                                                                          |
| On-chip input over voltage upper threshold for on-chip input overvoltage fault assertion | $OV_{IN\_UTH}$ | –      | 75                          | –    | V    | Set by $OVIN\_FAULT\_LIMIT[1:0]$<br>bits: $OVIN\_FAULT\_LIMIT[1:0] = 01$ |
| On-chip input over voltage upper threshold for on-chip input overvoltage fault assertion | $OV_{IN\_UTH}$ | –      | 80                          | –    | V    | Set by $OVIN\_FAULT\_LIMIT[1:0]$<br>bits: $OVIN\_FAULT\_LIMIT[1:0] = 10$ |
| On-chip input over voltage upper threshold for on-chip input overvoltage fault assertion | $OV_{IN\_UTH}$ | –      | 85                          | –    | V    | Set by $OVIN\_FAULT\_LIMIT[1:0]$<br>bits: $OVIN\_FAULT\_LIMIT[1:0] = 11$ |
| On-chip input over voltage lower threshold for on-chip input overvoltage fault release   | $OV_{IN\_LTH}$ | –      | $OV_{IN\_UTH} - 5\text{ V}$ | –    | V    | For on-chip input overvoltage fault release.                             |

### VOUT

|                                                                            |                 |   |    |   |               |                                                                              |
|----------------------------------------------------------------------------|-----------------|---|----|---|---------------|------------------------------------------------------------------------------|
| Input current                                                              | $I_{VOUT}$      | – | 15 | – | $\mu\text{A}$ | At 48 V                                                                      |
| Output over voltage upper threshold for output overvoltage fault assertion | $OV_{OUT\_UTH}$ | – | 70 | – | V             | Set by $OVOUT\_FAULT\_LIMIT [1:0]$<br>bits: $OVOUT\_FAULT\_LIMIT [1:0] = 00$ |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Table 9 (continued) Electrical characteristics**

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                                                                  | Symbol          | Values |                             |      | Unit | Note or condition                                                 |
|----------------------------------------------------------------------------|-----------------|--------|-----------------------------|------|------|-------------------------------------------------------------------|
|                                                                            |                 | Min.   | Typ.                        | Max. |      |                                                                   |
| Output over voltage upper threshold for output overvoltage fault assertion | $OV_{OUT\_UTH}$ | –      | 75                          | –    | V    | Set by OVOUT_FAULT_LIMIT [1:0] bits: OVOUT_FAULT_LIMIT [1:0] = 01 |
| Output over voltage upper threshold for output overvoltage fault assertion | $OV_{OUT\_UTH}$ | –      | 80                          | –    | V    | Set by OVOUT_FAULT_LIMIT [1:0] bits: OVOUT_FAULT_LIMIT [1:0] = 10 |
| Output over voltage upper threshold for output overvoltage fault assertion | $OV_{OUT\_UTH}$ | –      | 85                          | –    | V    | Set by OVOUT_FAULT_LIMIT [1:0] bits: OVOUT_FAULT_LIMIT [1:0] = 11 |
| Output over voltage lower threshold for output overvoltage fault release   | $OV_{OUT\_LTH}$ | –      | $OV_{OUT\_UTH} - 5\text{V}$ | –    | V    | For output overvoltage fault release.                             |

#### Telemetry

|                                                     |            |    |            |           |   |                                                                                                                                                                   |
|-----------------------------------------------------|------------|----|------------|-----------|---|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Monitored voltage range (input and output voltages) | $V_{TLM}$  | 22 | –          | 88        | V | Set by VTLM_RNG[1:0] bits: <ul style="list-style-type: none"> <li>2'b00: 88 V</li> <li>2'b01: 44 V</li> <li>2'b10: 22 V</li> <li>2'b11: n.a.</li> </ul>           |
| Input voltage measurements accuracy                 | $A_{VIN}$  | –  | $\pm 0.2$  | $\pm 0.4$ | % | At $V_{DD\_RTNS}$ vs GND: $V_{DD\_RTNS} = 20\text{ V}$ to $40\text{ V}$ or $10\text{ V}$ to $20\text{ V}$ depending on corresponding programmed range $V_{TLM}$ . |
| Output voltage measurements accuracy                | $A_{VOUT}$ | –  | $\pm 0.2$  | $\pm 0.4$ | % | At $V_{OUT}$ vs GND: $V_{OUT} = 20\text{ V}$ to $40\text{ V}$ or $10\text{ V}$ to $20\text{ V}$ depending on corresponding programmed range $V_{TLM}$ .           |
| Input voltage measurements accuracy                 | $A_{VIN}$  | –  | $\pm 0.25$ | $\pm 0.5$ | % | At $V_{DD\_RTNS}$ vs GND: $V_{DD\_RTNS} = 40\text{ V}$ to $80\text{ V}$ , $V_{TLM} = 88\text{ V}$ .                                                               |

(table continues...)

**Table 9** (continued) **Electrical characteristics**

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                            | Symbol     | Values |            |           | Unit | Note or condition                                                                                                                                                                                                                                  |
|--------------------------------------|------------|--------|------------|-----------|------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|                                      |            | Min.   | Typ.       | Max.      |      |                                                                                                                                                                                                                                                    |
| Output voltage measurements accuracy | $A_{VOUT}$ | –      | $\pm 0.25$ | $\pm 0.5$ | %    | At $V_{OUT}$ vs $GND$ : $V_{OUT} = 40\text{ V}$ to $80\text{ V}$ , $V_{TLM} = 88\text{ V}$ .                                                                                                                                                       |
| Current measurement accuracy         | $A_{IIN}$  | –      | $\pm 0.1$  | $\pm 0.2$ | %    | Between $ISNS\_REF$ & $ISNS$ pins. $V_{\Delta ISNS} = V_{SNS\_CS}$ , where $V_{SNS\_CS} = 100\text{ mV}$ or $50\text{ mV}$ .                                                                                                                       |
| Current measurement accuracy         | $A_{IIN}$  | –      | $\pm 0.2$  | $\pm 0.3$ | %    | Between $ISNS\_REF$ & $ISNS$ pins. $V_{\Delta ISNS} = V_{SNS\_CS} / 2$ , where $V_{SNS\_CS} = 100\text{ mV}$ or $50\text{ mV}$ .                                                                                                                   |
| Current measurement accuracy         | $A_{IIN}$  | –      | $\pm 0.35$ | $\pm 0.5$ | %    | Between $ISNS\_REF$ & $ISNS$ pins. $V_{\Delta ISNS} = V_{SNS\_CS} / 4$ , where $V_{SNS\_CS} = 100\text{ mV}$ or $50\text{ mV}$ .                                                                                                                   |
| Current measurement accuracy         | $A_{IIN}$  | –      | $\pm 0.16$ | $\pm 0.7$ | %    | Between $ISNS\_REF$ & $ISNS$ pins. $V_{\Delta ISNS} = V_{SNS\_CS}$ , where $V_{SNS\_CS} = 25\text{ mV}$ .                                                                                                                                          |
| Current measurement accuracy         | $A_{IIN}$  | –      | $\pm 0.4$  | $\pm 1.2$ | %    | Between $ISNS\_REF$ & $ISNS$ pins. $V_{\Delta ISNS} = V_{SNS\_CS} / 2$ , where $V_{SNS\_CS} = 25\text{ mV}$ .                                                                                                                                      |
| Current measurement accuracy         | $A_{IIN}$  | –      | $\pm 0.8$  | $\pm 2.3$ | %    | Between $ISNS\_REF$ & $ISNS$ pins. $V_{\Delta ISNS} = V_{SNS\_CS} / 4$ , where $V_{SNS\_CS} = 25\text{ mV}$ .                                                                                                                                      |
| Current measurement accuracy         | $A_{IIN}$  | –      | $\pm 0.4$  | $\pm 1.3$ | %    | Between $ISNS\_REF$ & $ISNS$ pins. $V_{\Delta ISNS} = V_{SNS\_CS}$ , where $V_{SNS\_CS} = 12.5\text{ mV}$ .                                                                                                                                        |
| Current measurement accuracy         | $A_{IIN}$  | –      | $\pm 0.8$  | $\pm 2.6$ | %    | Between $ISNS\_REF$ & $ISNS$ pins. $V_{\Delta ISNS} = V_{SNS\_CS} / 2$ , where $V_{SNS\_CS} = 12.5\text{ mV}$ .                                                                                                                                    |
| Current measurement accuracy         | $A_{IIN}$  | –      | $\pm 1.5$  | $\pm 5.4$ | %    | Between $ISNS\_REF$ & $ISNS$ pins. $V_{\Delta ISNS} = V_{SNS\_CS} / 4$ , where $V_{SNS\_CS} = 12.5\text{ mV}$ .                                                                                                                                    |
| Calculated input power accuracy      | $A_{PIN}$  | –      | $\pm 0.35$ | $\pm 0.7$ | %    | At $V_{DD\_RTNS}$ vs $GND$ : $V_{DD\_RTNS} = 40\text{ V}$ to $80\text{ V}$ , $V_{TLM} = 88\text{ V}$ .<br>And voltage between $ISNS\_REF$ & $ISNS$ pins: $V_{\Delta ISNS} = V_{SNS\_CS}$ , where $V_{SNS\_CS} = 100\text{ mV}$ or $50\text{ mV}$ . |
| Calculated input power accuracy      | $A_{PIN}$  | –      | $\pm 0.41$ | $\pm 1.2$ | %    | At $V_{DD\_RTNS}$ vs $GND$ : $V_{DD\_RTNS} = 40\text{ V}$ to $80\text{ V}$ , $V_{TLM} = 88\text{ V}$ .<br>And voltage between $ISNS\_REF$ & $ISNS$ pins: $V_{\Delta ISNS} = V_{SNS\_CS}$ , where $V_{SNS\_CS} = 25\text{ mV}$ .                    |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Table 9 (continued) Electrical characteristics**

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                                | Symbol        | Values |            |            | Unit             | Note or condition                                                                                                                                                                                                                            |
|------------------------------------------|---------------|--------|------------|------------|------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|                                          |               | Min.   | Typ.       | Max.       |                  |                                                                                                                                                                                                                                              |
| Calculated input power accuracy          | $A_{PIN}$     | –      | $\pm 0.65$ | $\pm 1.8$  | %                | At $V_{DD\_RTNS}$ vs GND: $V_{DD\_RTNS} = 40\text{ V}$ to $80\text{ V}$ , $V_{TLM} = 88\text{ V}$ .<br>And voltage between $ISNS\_REF$ & $ISNS$ pins: $V_{\Delta ISNS} = V_{SNS\_CS}$ , where $V_{SNS\_CS} = 12.5\text{ mV}$ .               |
| Calculated energy accuracy               | $A_{EIN}$     | –      | 1.4        | 2.1        | %                | At $V_{DD\_RTNS}$ vs GND: $V_{DD\_RTNS} = 40\text{ V}$ to $80\text{ V}$ , $V_{TLM} = 88\text{ V}$ . And voltage between $ISNS\_REF$ & $ISNS$ pins: $V_{\Delta ISNS} = V_{SNS\_CS}$ , where $V_{SNS\_CS} = 100\text{ mV}$ or $50\text{ mV}$ . |
| Calculated energy accuracy               | $A_{EIN}$     | –      | 1.4        | 2.7        | %                | At $V_{DD\_RTNS}$ vs GND: $V_{DD\_RTNS} = 40\text{ V}$ to $80\text{ V}$ , $V_{TLM} = 88\text{ V}$ . And voltage between $ISNS\_REF$ & $ISNS$ pins: $V_{\Delta ISNS} = V_{SNS\_CS}$ , where $V_{SNS\_CS} = 25\text{ mV}$ .                    |
| Calculated energy accuracy               | $A_{EIN}$     | –      | 1.7        | 3.3        | %                | At $V_{DD\_RTNS}$ vs GND: $V_{DD\_RTNS} = 40\text{ V}$ to $80\text{ V}$ , $V_{TLM} = 88\text{ V}$ . And voltage between $ISNS\_REF$ & $ISNS$ pins: $V_{\Delta ISNS} = V_{SNS\_CS}$ , where $V_{SNS\_CS} = 12.5\text{ mV}$ .                  |
| On-chip temperature monitored range      | $T_{ON-CHIP}$ | -40    | –          | 150        | $^\circ\text{C}$ |                                                                                                                                                                                                                                              |
| On-chip temperature measurement accuracy | $A_{T2}$      | -5     | –          | 5          | $^\circ\text{C}$ |                                                                                                                                                                                                                                              |
| Temperature measurements accuracy        | $A_{T1}$      | –      | $\pm 4.0$  | $\pm 12.5$ | $^\circ\text{C}$ | Sourcing currents in $TSNS\_P$ pin.<br>Sense the voltage between $TSNS\_P$ & $TSNS\_N$ pins.<br>External transistor is: MMBT3904.                                                                                                            |

#### VREG

|                |           |     |     |     |   |                                                                                                                                                                                                           |
|----------------|-----------|-----|-----|-----|---|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Output voltage | $V_{REG}$ | 4.7 | 5.0 | 5.3 | V | $9\text{ V} \leq V_{DD\_RTN} \leq 80\text{ V}$ .<br>$C_{VREG} = 1\text{ }\mu\text{F}$ .<br>Internal load + external load.<br>Package maximum power dissipation limit ( $P_{PAK}$ ) must not be violated.  |
| Output voltage | $V_{REG}$ | 4.5 | –   | –   | V | $6.5\text{ V} \leq V_{DD\_RTN} \leq 9\text{ V}$ .<br>$C_{VREG} = 1\text{ }\mu\text{F}$ .<br>Internal load + external load.<br>Package maximum power dissipation limit ( $P_{PAK}$ ) must not be violated. |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Table 9 (continued) Electrical characteristics**

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                                  | Symbol    | Values |      |      | Unit | Note or condition |
|--------------------------------------------|-----------|--------|------|------|------|-------------------|
|                                            |           | Min.   | Typ. | Max. |      |                   |
| Current capability to supply external load | $I_{REG}$ | –      | –    | 10   | mA   |                   |

#### PWRGD, GPOx, FAULT, WARN, SMBALERT#, CGDN, LED#

|                         |                |     |   |     |               |                          |
|-------------------------|----------------|-----|---|-----|---------------|--------------------------|
| Output low voltage      | $V_{OL}$       | –   | – | 0.4 | V             | At 10 mA                 |
| Input Low Voltage       | $V_{IL}$       | –   | – | 0.8 | V             |                          |
| Input High Voltage      | $V_{IH}$       | 2.0 | – | –   | V             |                          |
| Leakage current         | $i_{LEAK}$     | –   | – | 5   | $\mu\text{A}$ | At 5.5 V, output is HiZ. |
| Current sink capability | $i_{GPO\_max}$ | –   | – | 10  | mA            |                          |

#### SDAI, SDAO, SCL

|                                 |            |     |            |     |               |          |
|---------------------------------|------------|-----|------------|-----|---------------|----------|
| Input high voltage              | $V_{IH}$   | 2.0 | –          | –   | V             |          |
| Input low voltage               | $V_{IL}$   | –   | –          | 0.8 | V             |          |
| Output low voltage              | $V_{OL}$   | –   | –          | 0.4 | V             | At 20 mA |
| Leakage current                 | $i_{LEAK}$ | –   | –          | 5.0 | $\mu\text{A}$ | At 5.5 V |
| Nominal bus voltage             | $V_{BUS}$  | 3.0 | 3.3 or 5.0 | 5.5 | V             |          |
| Capacitive load per bus segment | $C_L$      | –   | –          | 400 | pF            |          |
| Pin capacitance                 | $C_P$      | –   | 5          | 10  | pF            |          |

#### ADDRx

|                              |                  |   |     |   |               |                                             |
|------------------------------|------------------|---|-----|---|---------------|---------------------------------------------|
| Pin sense current            | $I_{ADDR}$       | – | 100 | – | $\mu\text{A}$ |                                             |
| Programmability voltage step | $V_{ADDR\_STEP}$ | – | 0.8 | – | V             | See <a href="#">Table 13</a> for more info. |

#### MODEx

|                          |            |   |     |   |               |  |
|--------------------------|------------|---|-----|---|---------------|--|
| MODEx pins sense current | $I_{MODE}$ | – | 100 | – | $\mu\text{A}$ |  |
|--------------------------|------------|---|-----|---|---------------|--|

(table continues...)

**Table 9** (continued) **Electrical characteristics**

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                    | Symbol          | Values |      |      | Unit | Note or condition                           |
|------------------------------|-----------------|--------|------|------|------|---------------------------------------------|
|                              |                 | Min.   | Typ. | Max. |      |                                             |
| Programmability voltage step | $V_{MODE-STEP}$ | –      | 0.8  | –    | V    | See <a href="#">Table 12</a> for more info. |

#### IST

|                              |                |   |                              |   |               |  |
|------------------------------|----------------|---|------------------------------|---|---------------|--|
| Pin sense current            | $I_{IST}$      | – | 100                          | – | $\mu\text{A}$ |  |
| Programmability voltage step | $V_{IST-STEP}$ | – | See <a href="#">Table 19</a> | – | V             |  |

#### On-chip thermal shut down

|                                                   |               |     |                    |     |                  |                                                                                                                                                                                                                                                                                  |
|---------------------------------------------------|---------------|-----|--------------------|-----|------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Protection trigger upper threshold                | $T_{TS\_UTH}$ | 130 | –                  | 145 | $^\circ\text{C}$ | Set by ONCHIP_TSD_FAULT_LIMIT[1:0] bits:<br><ul style="list-style-type: none"> <li>2'b00: 130<math>^\circ\text{C}</math></li> <li>2'b01: 135<math>^\circ\text{C}</math></li> <li>2'b10: 140<math>^\circ\text{C}</math></li> <li>2'b11: 145<math>^\circ\text{C}</math></li> </ul> |
| Protection trigger lower threshold                | $T_{TS\_LTH}$ | –   | $T_{TS\_UTH} - 10$ | –   | $^\circ\text{C}$ |                                                                                                                                                                                                                                                                                  |
| On-chip thermal shut-down warning upper limit     | $TSDW_{UTH}$  | –   | 125                | –   | $^\circ\text{C}$ |                                                                                                                                                                                                                                                                                  |
| On-chip thermal shut-down warning lower threshold | $TSDW_{LTH}$  | –   | 115                | –   | $^\circ\text{C}$ |                                                                                                                                                                                                                                                                                  |

## 3.7 Timing characteristics

**Table 10** **Timing characteristics**

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                       | Symbol         | Values |      |      | Unit          | Note or condition                          |
|---------------------------------|----------------|--------|------|------|---------------|--------------------------------------------|
|                                 |                | Min.   | Typ. | Max. |               |                                            |
| UV/EN input fixed deglitch time | $t_{UVEN\_DG}$ | 6.5    | 10   | 13.5 | $\mu\text{s}$ | Input filter before processing the signal. |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Table 10 (continued) Timing characteristics**

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                                               | Symbol         | Values |      |      | Unit | Note or condition                                                                                                                                                                                                                                                                                                                               |
|---------------------------------------------------------|----------------|--------|------|------|------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|                                                         |                | Min.   | Typ. | Max. |      |                                                                                                                                                                                                                                                                                                                                                 |
| UV/EN deglitch time on rising edge before start the FET | $t_{UVEN\_ON}$ | 0      | –    | 512  | ms   | Defined by bits EN_DG[3:0] : <ul style="list-style-type: none"> <li>3'b0000: 0 ms</li> <li>3'b0001: 4 ms</li> <li>3'b0010: 8 ms</li> <li>3'b0011: 16 ms</li> <li>3'b0100: 32 ms</li> <li>3'b0101: 64 ms</li> <li>3'b0110: 128 ms</li> <li>3'b0111: 256 ms</li> <li>3'b1000: 300 ms</li> <li>3'b1001: 400 ms</li> <li>3'b1010: 512 ms</li> </ul> |

#### OV

|                              |              |     |    |      |               |                                            |
|------------------------------|--------------|-----|----|------|---------------|--------------------------------------------|
| OV input fixed deglitch time | $t_{OV\_DG}$ | 6.5 | 10 | 13.5 | $\mu\text{s}$ | Input filter before processing the signal. |
|------------------------------|--------------|-----|----|------|---------------|--------------------------------------------|

#### PWRGD

|                                                       |                    |     |     |     |    |                                                   |
|-------------------------------------------------------|--------------------|-----|-----|-----|----|---------------------------------------------------|
| Power good assertion deglitch time                    | $t_{PG\_DGR}$      | 0   | –   | 15  | ms | Configurable by means of PWRGD_DG_TMR[3:0] bits.  |
| Power good assertion deglitch time programming step   | $t_{PG\_DGR\_STP}$ | 0.9 | 1.0 | 1.1 | ms |                                                   |
| Power good deassertion deglitch time                  | $t_{PG\_DGF}$      | 0   | –   | 15  | ms | Configurable by means of PWRGDN_DG_TMR[3:0] bits. |
| Power good deassertion deglitch time programming step | $t_{PG\_DGF\_STP}$ | 0.9 | 1.0 | 1.1 | ms |                                                   |

#### ADC

|                                                     |               |   |       |   |               |  |
|-----------------------------------------------------|---------------|---|-------|---|---------------|--|
| Conversion rate of current and voltage measurements | $t_{ADC\_IV}$ | – | 102.4 | – | $\mu\text{s}$ |  |
|-----------------------------------------------------|---------------|---|-------|---|---------------|--|

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Table 10** (continued) Timing characteristics

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                                                      | Symbol               | Values |      |      | Unit          | Note or condition                                                                                                                                                                                                                                   |
|----------------------------------------------------------------|----------------------|--------|------|------|---------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|                                                                |                      | Min.   | Typ. | Max. |               |                                                                                                                                                                                                                                                     |
| Conversion rate of temperature measurements                    | $t_{ADC\_t}$         | –      | 200  | –    | ms            |                                                                                                                                                                                                                                                     |
| <b>Faults, warnings and timers</b>                             |                      |        |      |      |               |                                                                                                                                                                                                                                                     |
| Time for any gate discharge in fault state                     | $t_{FLT\_PD\_GATE}$  | 9      | 10   | 11   | ms            | In FAULT state, when any gate pull down/discharge method is activated, a timer starts simultaneously. If FET's $V_{GS}$ does not go below 1.04 V before this timer expires, SGD fault will be triggered.                                            |
| Fault strong pull down activation time for fast gate discharge | $t_{FLT\_PD\_FAST}$  | 13.5   | 15   | 16.5 | $\mu\text{s}$ | When strong/fast gate pull down is configured, the 1.5 A switch is activated for this time.                                                                                                                                                         |
| Fault reaction time                                            | $t_{FLT\_GATE\_OFF}$ | –      | 0.3  | 1.0  | $\mu\text{s}$ | Response time from fault triggered to activation of gate pin turn-off.<br>In the case of timer dependent faults, fault triggered means "after timer has expired".                                                                                   |
| FAULT pin hold time                                            | $t_{FAULT\_MIN}$     | 20     | –    | –    | $\mu\text{s}$ | Hold time of the FAULT signal when it is set<br>Open-drain output: At $C_L = 50\text{ pF}$ ; External pull-up resistor of $10\text{ k}\Omega$ .                                                                                                     |
| Hot swap retry cool down period                                | $t_{COOL}$           | 0      | –    | 64   | s             | Defined by bits COOLD_TMR[2:0]: <ul style="list-style-type: none"> <li>3'b000: 0 s</li> <li>3'b001: 1 s</li> <li>3'b010: 2 s</li> <li>3'b011: 4 s</li> <li>3'b100: 8 s</li> <li>3'b101: 16 s</li> <li>3'b110: 32 s</li> <li>3'b111: 64 s</li> </ul> |
| Retry OK deglitch timer                                        | $t_{RETRY\_DEG}$     | 0      | –    | 8    | s             | Defined by bits RETD_TMR[2:0]: <ul style="list-style-type: none"> <li>3'b000: 0 s</li> <li>3'b000: 0.5 s</li> <li>3'b000: 1 s</li> <li>3'b000: 2 s</li> <li>3'b000: 3 s</li> <li>3'b000: 4 s</li> <li>3'b000: 6 s</li> <li>3'b000: 8 s</li> </ul>   |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Table 10** (continued) Timing characteristics

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                   | Symbol                                | Values |      |       | Unit          | Note or condition                                                                                                                                                                                                                                                                                                                                                                                                                               |
|-----------------------------|---------------------------------------|--------|------|-------|---------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|                             |                                       | Min.   | Typ. | Max.  |               |                                                                                                                                                                                                                                                                                                                                                                                                                                                 |
| First step power-down timer | $t_{STEP1}$                           | 0      | –    | 25575 | ns            | Set by GATE_PD_TMR[9:0]<br>Configurable in 25 ns steps.                                                                                                                                                                                                                                                                                                                                                                                         |
| UV timer                    | $t_{UV}$                              | 0      | –    | 1000  | ms            | Set by bits UV_TMR[2:0]: <ul style="list-style-type: none"> <li>3'b000: 0 ms</li> <li>3'b001: 1 ms</li> <li>3'b010: 5 ms</li> <li>3'b011: 10 ms</li> <li>3'b100: 50 ms</li> <li>3'b101: 100 ms</li> <li>3'b110: 500 ms</li> <li>3'b111: 1000 ms</li> </ul>                                                                                                                                                                                      |
| OV timer                    | $t_{OV}$                              | 0      | –    | 1000  | ms            | set by OV_TMR[2:0] bits: <ul style="list-style-type: none"> <li>3'b000: 0 ms</li> <li>3'b001: 1 ms</li> <li>3'b010: 5 ms</li> <li>3'b011: 10 ms</li> <li>3'b100: 50 ms</li> <li>3'b101: 100 ms</li> <li>3'b110: 500 ms</li> <li>3'b111: 1000ms</li> </ul>                                                                                                                                                                                       |
| OVin, OVout detection time  | $t_{OVin\_DET}$ ,<br>$t_{OVout\_DET}$ | –      | –    | 2.0   | $\mu\text{s}$ |                                                                                                                                                                                                                                                                                                                                                                                                                                                 |
| OVin deglitch timer         | $t_{OV\_DGLTCH}$                      | 0      | –    | 1000  | $\mu\text{s}$ | Set by OVIN_TMR[2:0] bits: <ul style="list-style-type: none"> <li>3'b000: 0 <math>\mu\text{s}</math></li> <li>3'b001: 10 <math>\mu\text{s}</math></li> <li>3'b010: 20 <math>\mu\text{s}</math></li> <li>3'b011: 50 <math>\mu\text{s}</math></li> <li>3'b100: 100 <math>\mu\text{s}</math></li> <li>3'b101: 200 <math>\mu\text{s}</math></li> <li>3'b110: 500 <math>\mu\text{s}</math></li> <li>3'b111: 1000 <math>\mu\text{s}</math></li> </ul> |

(table continues...)

**Table 10** (continued) **Timing characteristics**

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                 | Symbol           | Values |      |       | Unit          | Note or condition                                                                                                                                                                                                                                                                                                                                                                                                                                    |
|---------------------------|------------------|--------|------|-------|---------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|                           |                  | Min.   | Typ. | Max.  |               |                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| OUV timer                 | $t_{OUV}$        | 0      | –    | 1000  | ms            | Set by OUV_TMR[2:0] bits: <ul style="list-style-type: none"> <li>3'b000: 0 ms</li> <li>3'b001: 1 ms</li> <li>3'b010: 5 ms</li> <li>3'b011: 10 ms</li> <li>3'b100: 50 ms</li> <li>3'b101: 100 ms</li> <li>3'b110: 500 ms</li> <li>3'b111: 1000 ms</li> </ul>                                                                                                                                                                                          |
| OVout FET minimum on time | $t_{OVOUT\_min}$ | 25     | –    | –     | $\mu\text{s}$ |                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| OVout hold timer          | $t_{OV\_HOLD}$   | 0      | –    | 1000  | $\mu\text{s}$ | Set by OVOUT_HOLD[2:0] bits: <ul style="list-style-type: none"> <li>3'b000: 0 <math>\mu\text{s}</math></li> <li>3'b001: 100 <math>\mu\text{s}</math></li> <li>3'b010: 250 <math>\mu\text{s}</math></li> <li>3'b011: 400 <math>\mu\text{s}</math></li> <li>3'b100: 550 <math>\mu\text{s}</math></li> <li>3'b101: 700 <math>\mu\text{s}</math></li> <li>3'b110: 850 <math>\mu\text{s}</math></li> <li>3'b111: 1000 <math>\mu\text{s}</math></li> </ul> |
| Watchdog timer            | $t_{WATCHDOG}$   | 5      | –    | 15000 | ms            | Set by WATCHDOG[3:0] bits.                                                                                                                                                                                                                                                                                                                                                                                                                           |
| OC/SOA deglitch timer     | $t_{SOAD}$       | 0      | –    | 10    | ms            | Set by SOAD_TMR[2:0] bits: <ul style="list-style-type: none"> <li>2'b00: 0 ms</li> <li>2'b01: 0.5 ms</li> <li>2'b10: 1 ms</li> <li>2'b11: 2 ms</li> <li>2'b00: 4 ms</li> <li>2'b01: 6.1 ms</li> <li>2'b10: 8 ms</li> <li>2'b11: 10 ms</li> </ul>                                                                                                                                                                                                     |

(table continues...)

**Table 10** (continued) **Timing characteristics**

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                               | Symbol                | Values |      |        | Unit          | Note or condition                                                                                                                                                                                                                                               |
|-----------------------------------------|-----------------------|--------|------|--------|---------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|                                         |                       | Min.   | Typ. | Max.   |               |                                                                                                                                                                                                                                                                 |
| OC/SOA regulation timer                 | $t_{SOAR}$            | 0      | –    | 1000   | ms            | Set by SOAR_TMR[2:0] bits: <ul style="list-style-type: none"> <li>3'b000: 0 ms</li> <li>3'b001: 1 ms</li> <li>3'b010: 5 ms</li> <li>3'b011: 10 ms</li> <li>3'b100: 50 ms</li> <li>3'b101: 100 ms</li> <li>3'b110: 500 ms</li> <li>3'b111: 1000 ms</li> </ul>    |
| RMS current calculator integration time | $t_{RMS}$             | 1.64   | –    | 838.86 | ms            | Set by RMS_SAMPLE_TMR[1:0] bits: <ul style="list-style-type: none"> <li>2'b00: 1.64 ms (16 samples)</li> <li>2'b01: 13.11 ms (128 samples)</li> <li>2'b10: 104.86 ms (1024 samples)</li> <li>2'b11: 838.86 ms (8192 samples)</li> </ul>                         |
| SOC fault digital deglitch timer        | $t_{SOC\_DDEG}$       | 0      | –    | 1000   | ms            | Set by SOC_TMR[2:0] bits: <ul style="list-style-type: none"> <li>3'b000: 0 ms</li> <li>3'b001: 0.01 ms</li> <li>3'b010: 0.1 ms</li> <li>3'b011: 1 ms</li> <li>3'b100: 10 ms</li> <li>3'b101: 100 ms</li> <li>3'b110: 500 ms</li> <li>3'b111: 1000 ms</li> </ul> |
| SOC fault analog deglitch timer         | $t_{SOC\_ADEG}$       | 0      | –    | 1000   | ns            | Set by SOC_DG_TMR[1:0] bits: <ul style="list-style-type: none"> <li>2'b00: 0 ns</li> <li>2'b01: 200 ns</li> <li>2'b10: 500 ns</li> <li>2'b11: 1000 ns</li> </ul>                                                                                                |
| Gate voltage fast recovery              | $t_{GATE\_FAST\_REC}$ | –      | –    | 100    | $\mu\text{s}$ | After SOC fault<br>At $6.5\text{ V} \leq V_{DD\_RTN} < 14\text{ V}$ : when $V_{GATE} \geq 4\text{ V}$ .<br>At $14\text{ V} \leq V_{DD\_RTN} \leq 100\text{ V}$ : when controller enters ON state.                                                               |

**Boost mode**

|                   |                    |     |   |   |    |                                                                                                               |
|-------------------|--------------------|-----|---|---|----|---------------------------------------------------------------------------------------------------------------|
| Boost pulse timer | $t_{BOOST\_PULSE}$ | 0.1 | – | 1 | ms | Set by BOOSTMODE_TMR[0]: <ul style="list-style-type: none"> <li>1'b0: 0.1 ms</li> <li>1'b1: 1.0 ms</li> </ul> |
|-------------------|--------------------|-----|---|---|----|---------------------------------------------------------------------------------------------------------------|

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 3 General product characteristics

**Table 10** (continued) Timing characteristics

$V_{DD\_RTN} - GND = 48\text{ V}$ ,  $V_{ISNS\_REF} = 0\text{ V}$ ,  $V_{\Delta ISNS} = (V_{ISNS\_REF} - V_{ISNS}) = 0\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.

| Parameter                                      | Symbol                  | Values |      |      | Unit          | Note or condition                                                                                                                                                                           |
|------------------------------------------------|-------------------------|--------|------|------|---------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|                                                |                         | Min.   | Typ. | Max. |               |                                                                                                                                                                                             |
| Boost mode duty cycle                          | $t_{\text{BOOST-DC}}$   | 2      | –    | 50   | %             | Set by BOOSTMODE_DC[2:0] bits.                                                                                                                                                              |
| <b>PMBus</b>                                   |                         |        |      |      |               |                                                                                                                                                                                             |
| Clock frequency                                | $f_{\text{SCL}}$        | 10     | –    | 1000 | KHz           |                                                                                                                                                                                             |
| Detect clock low timeout                       | $t_{\text{TIMEOUT}}$    | 25     | –    | 35   | ms            |                                                                                                                                                                                             |
| Bus free time between STOP and START Condition | $t_{\text{BUF}}$        | 0.5    | –    | –    | $\mu\text{s}$ | See <a href="#">Figure 13</a>                                                                                                                                                               |
| Hold time after (REPEATED) START Condition     | $t_{\text{HD:STA}}$     | 0.26   | –    | –    | $\mu\text{s}$ | After this period, the first clock is generated.<br>See <a href="#">Figure 13</a>                                                                                                           |
| REPEATED START condition setup time            | $t_{\text{SU:STA}}$     | 0.26   | –    | –    | $\mu\text{s}$ | See <a href="#">Figure 13</a>                                                                                                                                                               |
| STOP condition setup time                      | $t_{\text{SU:STO}}$     | 0.26   | –    | –    | $\mu\text{s}$ | See <a href="#">Figure 13</a>                                                                                                                                                               |
| Data hold time                                 | $t_{\text{HD:DAT}}$     | 0      | –    | –    | ns            | See <a href="#">Figure 13</a>                                                                                                                                                               |
| Data setup time                                | $t_{\text{SU:DAT}}$     | 50     | –    | –    | ns            | See <a href="#">Figure 13</a>                                                                                                                                                               |
| Clock low period                               | $t_{\text{LOW}}$        | 0.5    | –    | –    | $\mu\text{s}$ | See <a href="#">Figure 13</a>                                                                                                                                                               |
| Clock high period                              | $t_{\text{HIGH}}$       | 0.26   | –    | 50   | $\mu\text{s}$ | See <a href="#">Figure 13</a>                                                                                                                                                               |
| Clock/data fall time                           | $t_{\text{F}}$          | –      | –    | 120  | ns            | The fall time measurement limits are defined as follows:<br>Fall time limits: $(V_{\text{IHMIN}} + 0.15\text{ V})$ to $(V_{\text{ILMAX}} - 0.15\text{ V})$<br>See <a href="#">Figure 13</a> |
| Clock/data rise time                           | $t_{\text{R}}$          | –      | –    | 120  | ns            | The rise time measurement limits are defined as follows:<br>Rise time limits: $(V_{\text{ILMAX}} - 0.15\text{ V})$ to $(V_{\text{IHMIN}} + 0.15\text{ V})$<br>See <a href="#">Figure 13</a> |
| PMBus deglitch time                            | $t_{\text{DGL\_PMBUS}}$ | 50     | –    | –    | ns            |                                                                                                                                                                                             |

## 4 Product features

### 4.1 Functional description

#### 4.1.1 Modes of operation

##### Fully Digital Mode (FDM)

This mode is recognized by keeping MODE0 and 1 pins open. In this mode, FET to be used can be selected by means of the FET\_SELECT bits in the MODE PMBus command or a FET SOA can be programmed accurately in the SOA PMBus command so that controller effectively protects FET from going out of SOA. For pre-programmed FETs, there are two different SOA options to select from: DC line and 10 ms line. If second one is chosen, application has to be designed so that output capacitor is charged within this time and both watchdog and SOAR\_TMR have to be programmed also to this time for protection. The programmed SOA line will be used for both INIT\_SOA\_REG and I\_REG regulation described in [Operational States](#). Other lines can be selected or programmed manually if desired by means of the SOA programmable section of the OTP memory.

If desired, analog comparators at the OV and UV/EN pins, which have a faster response than digital comparators, can be used for OV and UV protection. This is specified by clearing the MODE bit in the MODE PMBus command, which selects the analog comparators mode (ACM).

Digital comparators can be used by leaving the MODE bit to its default (digital comparators mode, DCM). All other XDP700 features like voltage and current faults and warnings limits and timers can be programmed digitally too, including the IST limit, which is set in the START\_ILIM bits in the I\_SNS\_CFG PMBus command. This reduces the amount of external components, as shown in [Figure 32](#). If the MODE bit is left to its default value of 1, UV/EN pin does not have a UV fault functionality, but it's only used to enable or disable the device.

The PMBus address can be set at ADDR1 and ADDR0 (see [Table 13](#)) pins by keeping them open or tying to GND directly or via external resistors, or in PMBUS\_CFG command. If PMBUS\_CFG command is used for programming the address, different addresses can be programmed in multiple devices connected to a single bus by means of the PMBus enable feature mapped onto GPO3.

##### Analog Assisted Digital Mode (AADM)

Use simple analog programming at MODE0 and 1 pins for selecting the pre-programmed configurations for controlled FETs. FET can be selected by tying these pins through a resistor to GND.

MODE bit in MODE command is ignored in AADM. In this case, OV and UV faults limits are set via voltage dividers at the OV and UV/EN pins. Voltages are sensed via analog comparators at the corresponding pins. Warnings are disabled by default, unless they are enabled and programmed digitally.

The Current Sense Range ( $V_{SNS\_CS}$ ) and IST limit can be set by means of a resistor at the IST pin as shown in [Table 19](#), therefore the CS\_RNG and START\_ILIM bits in I\_SNS\_CFG PMBus command are ignored.

The PMBus address shall be set at ADDR1 and ADDR0 (see [Table 11](#)) pins by keeping them open or tying to GND directly or via external resistors.

**Table 11** Modes of operation

| Mode of operation | MODEx pins | MODE bit | Device address                                              | FET selection                        | OV/UV detection                | IST                             |
|-------------------|------------|----------|-------------------------------------------------------------|--------------------------------------|--------------------------------|---------------------------------|
| FDM               | Open       | 1        | Set by means of ADDR <sub>x</sub> pins or PMBUS_CFG command | Selected by means of FET_SELECT bits | Digital Comparators Mode (DCM) | Set by means of START_ILIM bits |

(table continues...)

**Table 11** (continued) Modes of operation

| Mode of operation | MODEx pins      | MODE bit | Device address                                              | FET selection                   | OV/UV detection               | IST                     |
|-------------------|-----------------|----------|-------------------------------------------------------------|---------------------------------|-------------------------------|-------------------------|
|                   |                 | 0        |                                                             |                                 | Analog Comparators Mode (ACM) |                         |
| AADM              | Resistor to GND | X        | Set by means of ADDR <sub>x</sub> pins or PMBUS_CFG command | Selected by means of MODEx pins | Analog Comparators Mode (ACM) | Set by means of IST pin |

### Configuration of MODE1/0 Pins

Setting the voltage level (between 0.8 V and 2.4 V) at MODE1 and MODE0 pins shall be done using external resistors (see [Setting the voltage at MODE1/0 pins in AADM](#)).

**Table 12** Configuration of MODE1/0 pins

| MODE1 pin voltage, V | MODE1 pin resistance, K $\Omega$ | MODE0 pin voltage, V | MODE0 pin resistance, K $\Omega$ | FET selection           |
|----------------------|----------------------------------|----------------------|----------------------------------|-------------------------|
| MODE1 < 0.8          | GND                              | MODE0 < 0.8          | GND                              | BSC027N10NS5ATMA1       |
| MODE1 < 0.8          | GND                              | 0.8 ≤ MODE0 < 1.6    | 12                               | BSC035N10NS5ATMA1       |
| MODE1 < 0.8          | GND                              | 1.6 ≤ MODE0 < 2.4    | 20                               | BSC040N10NS5ATMA1       |
| MODE1 < 0.8          | GND                              | MODE0 ≥ 2.4          | Open                             | IPTG011N08NM5           |
| 0.8 ≤ MODE1 < 1.6    | 12                               | MODE0 < 0.8          | GND                              | IPTC012N08NM5           |
| 0.8 ≤ MODE1 < 1.6    | 12                               | 0.8 ≤ MODE0 < 1.6    | 12                               | IPB017N10N5LFATMA1      |
| 0.8 ≤ MODE1 < 1.6    | 12                               | 1.6 ≤ MODE0 < 2.4    | 20                               | BSC093N15NS5            |
| 0.8 ≤ MODE1 < 1.6    | 12                               | MODE0 ≥ 2.4          | Open                             | BSC074N15NS5            |
| 1.6 ≤ MODE1 < 2.4    | 12                               | MODE0 < 0.8          | GND                              | IPTG014N10NM5           |
| 1.6 ≤ MODE1 < 2.4    | 20                               | 0.8 ≤ MODE0 < 1.6    | 12                               | IPTC015N10NM5           |
| 1.6 ≤ MODE1 < 2.4    | 20                               | 1.6 ≤ MODE0 < 2.4    | 20                               | IPT015N10N5ATMA1        |
| 1.6 ≤ MODE1 < 2.4    | 20                               | MODE0 ≥ 2.4          | Open                             | IPB017N10N5ATMA1        |
| MODE1 ≥ 2.4          | Open                             | MODE0 < 0.8          | GND                              | IPB018N10NM6            |
| MODE1 ≥ 2.4          | Open                             | 0.8 ≤ MODE0 < 1.6    | 12                               | IPT013N08NM5LF          |
| MODE1 ≥ 2.4          | Open                             | 1.6 ≤ MODE0 < 2.4    | 20                               | IPB020N10N5ATMA1        |
| MODE1 ≥ 2.4          | Open                             | MODE0 ≥ 2.4          | Open                             | FET_SELECT (ROM or OTP) |

### Configuration of ADDR1/0 Pins

These pins can be tied to GND, left floating or tied low through a resistor for a total of 16 unique PMBus device addresses according to [Table 13](#).

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 4 Product features

Setting the voltage level (between 0.8 V and 2.4 V) at ADDR1 and ADDR0 pins shall be done using external resistors (see [Setting the voltage at ADDR1/0 pins](#)).

**Table 13 Configuration of ADDR1/0 pins**

| ADDR1 pin voltage, V   | ADDR1 pin resistance, K $\Omega$ | ADDR0 pin voltage, V   | ADDR0 pin resistance, K $\Omega$ | Base address field [6:4]                             | Device address field [3:0] |
|------------------------|----------------------------------|------------------------|----------------------------------|------------------------------------------------------|----------------------------|
| ADDR1 < 0.8            | GND                              | ADDR0 < 0.8            | GND                              | As configured in PMBUS_CFG command.<br>Default = 001 | 0000                       |
| ADDR1 < 0.8            | GND                              | 0.8 $\leq$ ADDR0 < 1.6 | 12                               |                                                      | 0001                       |
| ADDR1 < 0.8            | GND                              | 1.6 $\leq$ ADDR0 < 2.4 | 20                               |                                                      | 0010                       |
| ADDR1 < 0.8            | GND                              | ADDR0 $\geq$ 2.4       | Open                             |                                                      | 0011                       |
| 0.8 $\leq$ ADDR1 < 1.6 | 12                               | ADDR0 < 0.8            | GND                              |                                                      | 0100                       |
| 0.8 $\leq$ ADDR1 < 1.6 | 12                               | 0.8 $\leq$ ADDR0 < 1.6 | 12                               |                                                      | 0101                       |
| 0.8 $\leq$ ADDR1 < 1.6 | 12                               | 1.6 $\leq$ ADDR0 < 2.4 | 20                               |                                                      | 0110                       |
| 0.8 $\leq$ ADDR1 < 1.6 | 12                               | ADDR0 $\geq$ 2.4       | Open                             |                                                      | 0111                       |
| 1.6 $\leq$ ADDR1 < 2.4 | 20                               | ADDR0 < 0.8            | GND                              |                                                      | 1000                       |
| 1.6 $\leq$ ADDR1 < 2.4 | 20                               | 0.8 $\leq$ ADDR0 < 1.6 | 12                               |                                                      | 1001                       |
| 1.6 $\leq$ ADDR1 < 2.4 | 20                               | 1.6 $\leq$ ADDR0 < 2.4 | 20                               |                                                      | 1010                       |
| 1.6 $\leq$ ADDR1 < 2.4 | 20                               | ADDR0 $\geq$ 2.4       | Open                             |                                                      | 1011                       |
| ADDR1 $\geq$ 2.4       | Open                             | ADDR0 < 0.8            | GND                              |                                                      | 1100                       |
| ADDR1 $\geq$ 2.4       | Open                             | 0.8 $\leq$ ADDR0 < 1.6 | 12                               |                                                      | 1101                       |
| ADDR1 $\geq$ 2.4       | Open                             | 1.6 $\leq$ ADDR0 < 2.4 | 20                               |                                                      | 1110                       |
| ADDR1 $\geq$ 2.4       | Open                             | ADDR0 $\geq$ 2.4       | Open                             |                                                      | Program in OTP (PMBUS_CFG) |

## 4.1.2 Operational states

**Table 14 Operational states**

|                       | State | Name     | Description                                                                                  | Next state No fault | Next state fault |
|-----------------------|-------|----------|----------------------------------------------------------------------------------------------|---------------------|------------------|
| <b>Initialization</b> | 0     | POR_INIT | Internal circuitry is initialized as soon as VDD_RTN > 6.5 V.                                | READ_CFG            | NA               |
|                       | 1     | READ_CFG | POR and initialization complete. OTP and external pins configuration are read at this point. | CHK_FET             | NA               |

(table continues...)

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 4 Product features

**Table 14** (continued) Operational states

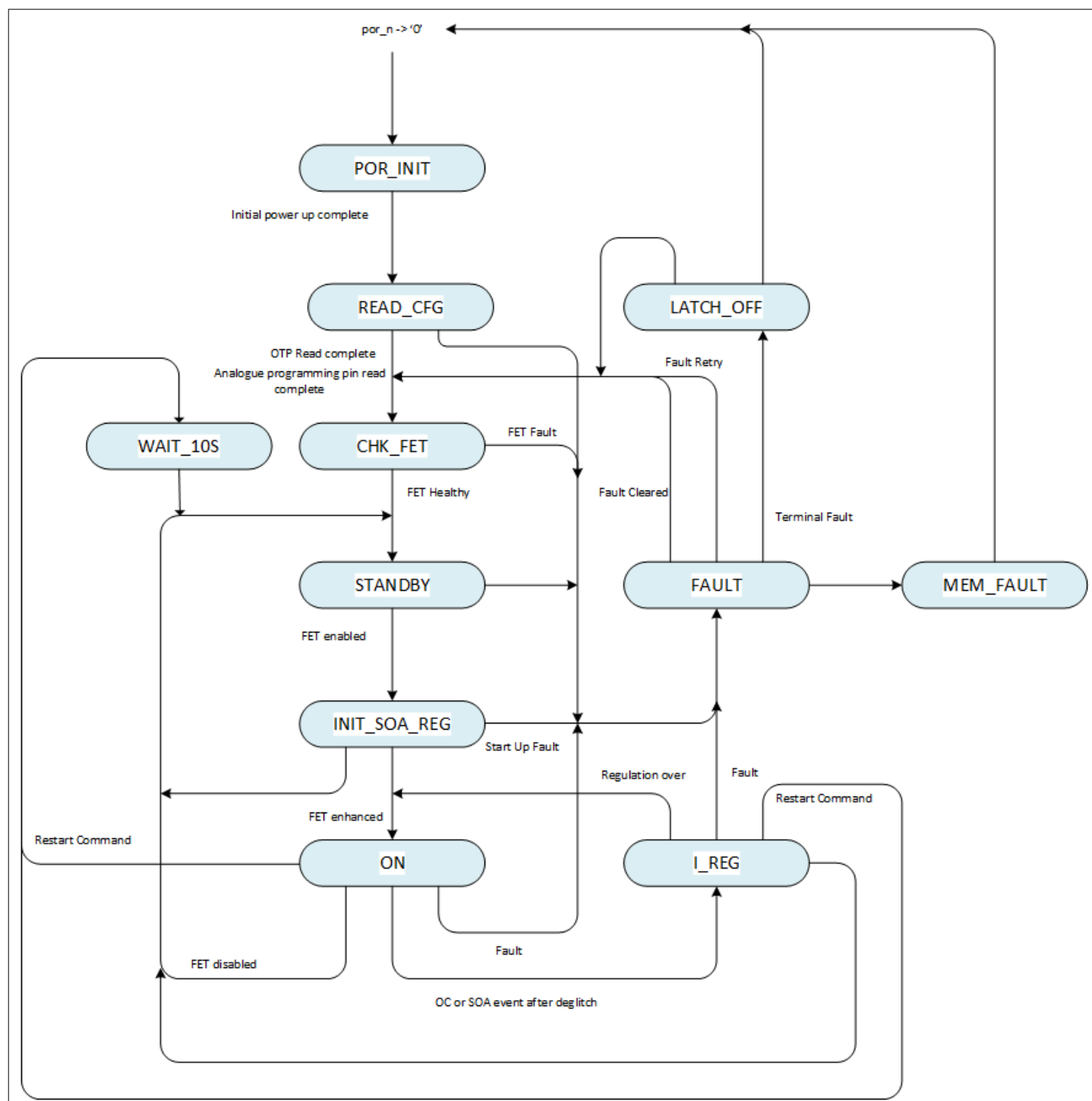
|                               | State | Name         | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      | Next state<br>No fault      | Next state<br>fault |
|-------------------------------|-------|--------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------|---------------------|
| <b>Power-up<br/>procedure</b> | 2     | CHK_FET      | Controller checks FET for drain to source or gate to drain shorts.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               | STANDBY                     | FAULT               |
|                               | 3     | STANDBY      | Controller checks that VDD_RTN is within a valid range (within UV and OV), device temperature is in appropriate range and EN signal is deasserted or ON bit in OPERATION command is cleared. Before going out of STANDBY and into INIT_SOA_REG state, XDP700 checks the input voltage level according to OV, UV and OVin limits. If it's out of range, it will go to FAULT state.                                                                                                                                                                                | INIT_SOA_REG                | FAULT               |
|                               | 4     | INIT_SOA_REG | EN signal is asserted and ON bit in OPERATION command is set. Turn-on Watchdog timer starts running. SOA regulation phase: Controller regulates the current according to the programmed SOA (see section Current Limit During Operation for more info), depending on VDS value in order to charge the output capacitor. INIT_SOA_REG phase stops when $FET V_{DS} < 1.0 V$ , $V_{GS} > 7.8 V$ and no faults are detected during this procedure. Due to the current regulation nature of the Power-up algorithm, start-up time depends on the output capacitance. | ON                          | FAULT               |
|                               | 5     | ON           | Normal operation phase starts. FET is fully enhanced. Current regulation can start again if OC is detected or FET SOA is violated. Turn-on watchdog reset procedure starts at this point.                                                                                                                                                                                                                                                                                                                                                                        | ON,<br>I_REG or<br>WAIT_10S | FAULT               |

**Normal  
operation**

(table continues...)

**Table 14** (continued) Operational states

|      | State | Name      | Description                                                                                                                                                                                                                                                                                                                        | Next state<br>No fault                                                       | Next state<br>fault |
|------|-------|-----------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------|---------------------|
|      | 6     | I_REG     | If $I_{OC}$ level is exceeded or programmed FET SOA limits are violated, SOAD_TMR timer will start. If condition persists after SOAD_TMR timer expires, the SOA regulation timer SOAR_TMR starts and FET's current will be regulated at $I_{OC}$ or FET SOA level by lowering FET VGS.                                             | ON or<br>WAIT_10S                                                            | FAULT               |
| Idle | 7     | FAULT     | Fault that turns off the FET has occurred. System will stay idle in FAULT state until:<br>a) Fault conditions are cleared in the case of non-retry dependent faults.<br>b) Cool down timer expires in the case of retry dependent faults.<br>If retry counter has expired, system will go to LATCH_OFF state directly after FAULT. | CHK_FET/<br>STANDBY<br>or LATCH_OFF                                          | NA                  |
|      | 8     | LATCH_OFF | If the maximum number of retries has been reached, system will latch off until faults are cleared and restart has been issued (power cycling or PMBus command).                                                                                                                                                                    | POR_INIT<br>(power cycling)<br>or CHK_FET<br>(PMBus command)<br>or LATCH_OFF | NA                  |
|      | 9     | MEM_FAULT | If an OTP read or write error is detected, XDP700 will go to FAULT and consecutively MEM_FAULT state, which initiates controller's latch-off. A power cycle is required in order to go out of MEM_FAULT.                                                                                                                           | POR_INIT<br>(power cycling)                                                  | NA                  |
|      | 10    | WAIT_10S  | A RESTART command has been issued. XDP700 turns off the FET and stays in this state for 10 seconds. After this time, system goes to STANDBY and, if the necessary conditions are met, FET is automatically turned back on, going to ON state.                                                                                      | STANDBY                                                                      | NA                  |



**Figure 5** XDP700-002 State machine.

### 4.1.3 Enable and disable

The PMBus interface communication and controller's programmability is functional at minimum operative VDD\_RTN. XDP700's gate pin can be enabled or disabled by means of the UV/EN pin or PMBus command. By default, it starts up as soon as the necessary conditions are detected: proper voltage level between UV and OV pins. In order to disable this "enabled by default" feature, the corresponding bit has to be programmed accordingly in OPERATION PMBus command.

In DCM, the UV/EN pin has a deglitch timer EN\_DG[3:0], which deglitches every UV/EN transition. This timer starts running as soon as the voltage at this pin rises above  $V_{UVEN\_UTH}$ . The system turns on as soon as it expires if voltage is still above this level.

When UV/EN pin is tied low, FET turns off, but communication circuitry is still available. When device is disabled but in STANDBY state, VREG and communication via PMBus will still be enabled so that the device can be programmed and FAULT status bits will keep their latest status.

Also in DCM, it is possible to implement a manual input voltage deglitch by delaying the toggling of the UV/EN signal. Faults detection starts when UV/EN signal is toggled. In this case, EN\_DG can be set to 0.

In ACM, the EN\_DG[3:0] debounces the input voltage in a hot-plug event instead of the UV/EN pin and only runs after POR. If the supply voltage is enough to power up the controller, the EN\_DG timer will run regardless of the voltage level at UV/EN pin. Subsequent transitions at UV/EN pin in ACM don't make the EN\_DG timer run either.

The UV input (under-voltage monitoring input to support the UV fault) and EN input are combined in one pin.

The UV/EN pin configuration is dependent on mode of operation:

**Table 15 UV/EN Input Configuration**

| Mode of operation                                    | UV/EN pin configuration |
|------------------------------------------------------|-------------------------|
| FDM - DCM (digital comparators for OV and UV faults) | EN input                |
| FDM - ACM (analog comparators for OV and UV faults)  | UV input                |
| AADM                                                 | UV input                |

If the pin is configured as UV input its voltage is sensed by an analog comparator to support UV fault detection and release. Turn-on and off of the device can still be controlled by toggling the pin high or low respectively. When pin is toggled low, XDP700 follows the configured UV fault procedure before turning off.

If pin is configured as EN, turn-on and off of the device can be controlled without following UV fault procedure.

The EN input controls the state of the controlled FET together with PMBus OPERATION command:

- EN = Low (voltage level is  $\leq V_{UVEN\_LTH}$ ) --> FET is OFF;
- EN = High (voltage level is  $\geq V_{UVEN\_UTH}$ ) --> the FET's state depends on the PMBus OPERATION command.

The EN High-to-Low transition clears any fault (including ones that cause Latch-off) as it is described in [Latch-off](#). Only the memory OTP (MEM) fault is not affected.

The Connector Good Negated input (CGDN) provides a way to detect if a connector is correctly plugged to the system. If pulled externally Low (voltage level is  $\leq V_{IL\_Max}$ ), the controller is allowed to turn FET on. When the pin is floating or pulled externally High (voltage level is  $\geq V_{IH\_Min}$ ), the FET is turned off. This reduces arcing by turning off the FET before the connector is removed.

The table below shows the relations between OPERATION command and state of UV/EN and CGDN (if configured) pins:

| OPERATION command | Inputs |      | State of the FET                                     |
|-------------------|--------|------|------------------------------------------------------|
|                   | UV/EN  | CGDN |                                                      |
| ON                | H      | L    | Active<br>(can be ON / Regulated / OFF due to fault) |
| OFF               | H      | L    | OFF                                                  |
| ON                | L      | L    | OFF                                                  |
| OFF               | L      | L    | OFF                                                  |
| ON                | H      | H    | OFF                                                  |
| OFF               | H      | H    | OFF                                                  |

|     |   |   |     |
|-----|---|---|-----|
| ON  | L | H | OFF |
| OFF | L | H | OFF |

#### 4.1.4 Control of FET's current

XDP700 controls the FET's current according to four different limits:

- **Programmed FET SOA limit:** To protect the FET, current flow through the FET is regulated according to its  $V_{DS}$ , following the FET's SOA line, which is stored in ROM or OTP. Pre-programmed SOA lines correspond to 65°C or 125°C temperature, this is in order to account for systems that will be working at temperatures higher than the usual ambient of 25°C. They are selectable between DC and 10 ms in FDM. DC only in AADM. Care must be taken to program the corresponding SOA fault timers according to the voltage and current levels so that maximum FET capabilities are not exceeded. If FET temperature monitoring feature (TSNS\_x pins) is used, the SOA line to be used is adjusted automatically according to the sensed temperature. Below 105°C, the 65°C line is used, and above 105°C, the 125°C line is used. SOA can also be manually programmed to give the user the flexibility to work with different SOA curves or limit the power allowed;
- **Overcurrent (OC) limit:** To protect the load and source, this limit is normally set according to the maximum allowed current flow through the circuit by means of  $I_{OC}$ . This limit is active during INIT\_SOA\_REG, ON and I\_REG states. See [Setting  \$I\_{OC}\$](#)  for info about how to set it.
- **FET Start-up current (IST) limit:** To reduce voltage overshoots due to the output capacitance by increasing start-up time, this limit can be set in case SOA and OC limits are too high. This limit is taken into account during INIT\_SOA\_REG state only and disregarded as soon as ON state is reached.
- **SOC limit:** The severe overcurrent limit provides a fast response in case current reaches critical levels.

##### 4.1.4.1 MOSFET's Power-up - Continuous Safe Operating Area (SOA) Control

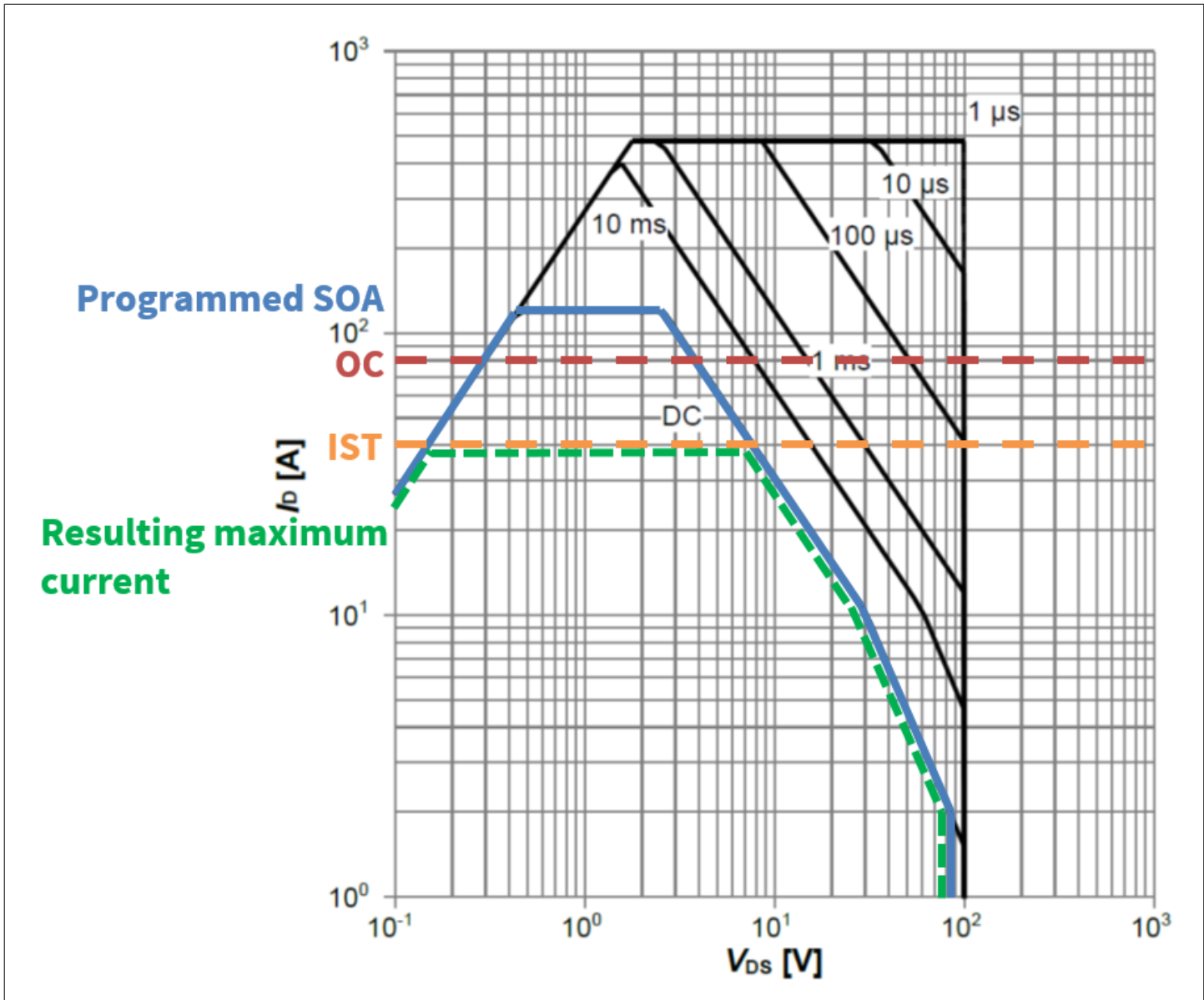
During a system initialization, XDP700 provides bias current to turn on the MOSFET in a controlled manner to avoid any SOA violations, while ensuring that the system is turned on without any inrush event.

During power-up, the lowest of the three limits:

- FET SOA
- OC: Programmed overcurrent limit
- IST: Programmed system startup current limit

defines the system maximum allowed current.

In the following example, the green dotted line indicates the maximum current allowed through the MOSFET (IPB020N10N5LF) during a startup. The programmed safe operating area (SOA) of the MOSFET is indicated by the solid blue line. In this example, the maximum current allowed by the controller is limited by IST since it is the lowest current limit allowed by this specific application.



**Figure 6** Safe operating area

SOA is digitally programmed in the SOA command as a look-up table with 80 values, corresponding to  $V_{DS} = 1\text{ V}$  to  $80\text{ V}$ . Each value represents the current  $I_D$  allowed for each voltage point. The following table contains the DC curve data shown in the previous figure for FET IPB020N10N5LF at  $65^\circ\text{C}$ . XDP700 target SOA has a resolution of  $0.5\text{ A}$  and a minimum regulation level of  $0.25\text{ A}$ . This level is limited by the combination of  $VSNS\_CS$ , chosen sense resistor and internal ADC resolution. To calculate the resulting level:

$$\text{Minimum regulation level} = 3 * \frac{V_{SNS\_CS}}{180.34 * R_{SNS}}$$

**Equation 1**

Where  $180.34$  is the resolution of the ADC and  $3$  is the margin in LSBs for noise protection.

The **Target SOA  $I_{SOA}$  (A)** column shows the rounded values:

**Table 16** SOA Table for IPB020N10N5LF

| $V_{DS}$ (V) | $I_D$ (A) | Target SOA $I_{SOA}$ (A) |
|--------------|-----------|--------------------------|
| 1            | 120       | 120                      |
| 2            | 120       | 120                      |
| 3            | 104.2     | 104                      |
| 4            | 78.1      | 78                       |
| 5            | 62.5      | 62.5                     |
| 6            | 52.1      | 52                       |
| 7            | 44.6      | 44.5                     |
| 8            | 39.1      | 39                       |
| ...          | ...       | ...                      |
| 73           | 2.5       | 2.5                      |
| 74           | 2.5       | 2.5                      |
| 75           | 2.4       | 2                        |
| 76           | 2.4       | 2                        |
| 77           | 2.3       | 2                        |
| 78           | 2.2       | 2                        |
| 79           | 2.2       | 2                        |
| 80           | 2.1       | 2                        |

As an example, a typical 48 V input application with the DC line of figure above is taken.

- Before the FET is turned on, there are -48 V at the input (with respect to RTN) and 0 V at the output, since the output capacitor is discharged. So  $V_{DS} = 48$  V.
- XDP700 starts charging the output capacitor by regulating the current through the FET according to the maximum allowed in the SOA. From [Figure 6](#), the DC line allows an  $I_{SOA} \cong 4.5$  A at 48 V.
- While the capacitor charges,  $V_{DS}$  of the FET will be reduced, allowing current increase according to SOA. For example,  $V_{DS} = 40$  V allows a current of  $I_{SOA} \cong 6.5$  A, so, when  $V_{DS}$  reaches 40 V, XDP700 increases the current through the FET to 6.5 A.
- Current keeps increasing while voltage keeps decreasing until output voltage is charged to the desired level and FET gets fully enhanced. This current limitation delays the charging of the output capacitor, significantly reducing the inrush current at start-up while keeping the FET safe at all times.

#### 4.1.4.1.1 Control loop

XDP700's control loop consists on a closed loop system that senses the FET current by means of the voltage drop on the sense resistor and input and output voltages. It calculates the FET's  $V_{DS}$  by sensing  $V_{OUT}$  with respect to GND and regulates the current according to the maximum allowed in the SOA table, depending on the sensed  $V_{DS}$ . This regulation is done by adjusting the FET's  $V_{GS}$ .

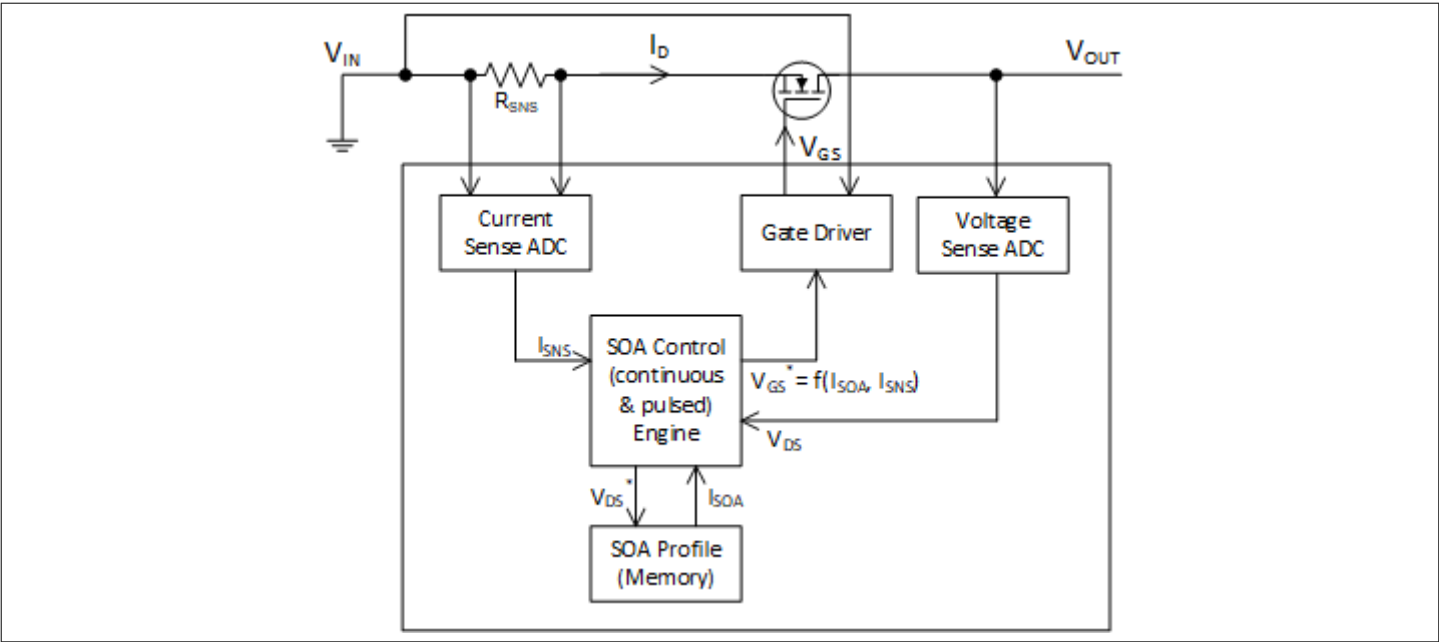


Figure 7 XDP700 Control loop block diagram

4.1.4.1.2 Setting OC and IST levels

In XDP700 FDM the current sense (CS) range and overcurrent (OC) level are set digitally by means of CS\_RNG bits in I\_SNS\_CFG PMBus command.

Table 17 CS\_RNG values

| CS_RNG[1:0] | OC Level (mV) |
|-------------|---------------|
| 00          | 12.5          |
| 01          | 25            |
| 10          | 50            |
| 11          | 100           |

If required, the Non-RMS and RMS OC levels can be trimmed by CS\_RNG\_TRIM.  
The start-up current limit (IST) through the FET is set digitally using dedicated START\_ILIM bits in I\_SNS\_CFG command:

Table 18 START\_ILIM current limit

| START_ILIM[2:0] | Start-up current limit (IST)         |
|-----------------|--------------------------------------|
| 000             | 100% of OC level (disabled, default) |
| 001             | 75% of OC level                      |
| 010             | 50% of OC level                      |
| 011             | 25% of OC level                      |
| 100             | 15% of OC level                      |

(table continues...)

**Table 18** (continued) **START\_ILIM current limit**

| START_ILIM[2:0] | Start-up current limit (IST) |
|-----------------|------------------------------|
| 101             | 12.5% of OC level            |
| 110             | 9% of OC level               |
| 111             | 5% of OC level               |

In AADM, the default OC range and the start-up current limit (IST) through the FET can be set by means of a voltage on IST pin. If settings different than the ones in [Table 19](#) are desired, they can be configured manually in the corresponding PMBus commands.

**Table 19** **IST pin configuration**

| IST pin voltage, V | V <sub>SNS_CS</sub> , mV | Start-up current limit (IST)                |
|--------------------|--------------------------|---------------------------------------------|
| IST > 2.8 (Open)   | 25                       | Set by START_ILIM bits in I_SNS_CFG command |
| 2.2 < IST ≤ 2.8    |                          | 50% of V <sub>SNS_CS</sub> (25mV)           |
| 1.7 < IST ≤ 2.2    |                          | 25% of V <sub>SNS_CS</sub> (25mV)           |
| 1.3 < IST ≤ 1.7    |                          | 12.5% of V <sub>SNS_CS</sub> (25mV)         |
| 0.9 < IST ≤ 1.3    | 12.5                     | 12.5% of V <sub>SNS_CS</sub> (12.5mV)       |
| 0.6 < IST ≤ 0.9    |                          | 25% of V <sub>SNS_CS</sub> (12.5mV)         |
| 0.3 < IST ≤ 0.6    |                          | 50% of V <sub>SNS_CS</sub> (12.5mV)         |
| IST ≤ 0.3 (GND)    |                          | Set by START_ILIM bits in I_SNS_CFG command |

Setting the voltage level (between 0.3 V and 2.8 V) at IST pin shall be done using external resistor connected to GND. To set the desired voltage level at the pin, choose the resistor by simply dividing desired voltage over sourced pin current (100 μA ± 7%).

The 1% (or lower) tolerant resistors are recommended in this case. For example:

**Table 20** **IST pin resistor**

| Voltage, V | IST pin resistor, kΩ |
|------------|----------------------|
| 2.49       | 24.9                 |
| 1.96       | 19.6                 |
| 1.5        | 15                   |
| 1.1        | 11                   |
| 0.75       | 7.5                  |
| 0.453      | 4.53                 |

#### 4.1.4.2 Control of Current during FET's Normal Operation

In normal operation (during ON and I\_REG states) the FET's current is limited by OC and FET's SOA limits. If RMS OC fault is enabled, the FET's current limitation set by OC limit is disregarded, the OC<sub>RMS</sub> event comes from the digital RMS overcurrent detector.

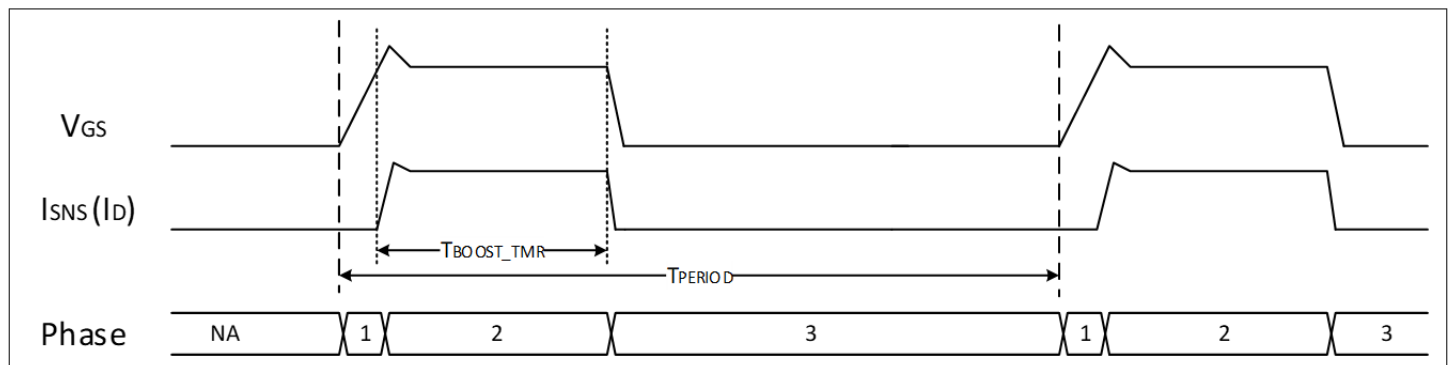
### 4.1.5 Boost mode power-up

For high  $V_{DS}$  values, the  $I_{SOA}$  target is often in low current range, that is, below 1 A. For some FETs it could be even lower than the minimum SOA current regulation level (0.25 A). Running FET's power-up with continuous SOA control under those conditions may result in FET overstress and failing, especially in the systems with large output capacitors.

There is a programmable option in the XDP700 which pulses ("boosts") the  $I_D$  to make use of FET's higher current capability with shorter pulses and sets a cool down time between boost pulses to keep the FET safe. MOSFET gate is enhanced in bursts to mimic switching type of operation and allow the output capacitor to be charged. This ensures the safety of the FET by cooling down in between bursts instead of constant flow. There are two types of boost mode:

1. **Automatic boost:** Pulses are applied to the gate of the FET until  $I_{SOA} \geq 0.5$  A. Then system continues power-up with continuous SOA regulation mode.
2. **Full boost:** Pulses are applied to the gate of the FET until  $V_{DS}$  of the FET is lower than 1 V. Then system continues power-up with continuous SOA regulation mode.

If this function is enabled by means of the BOOSTMODE\_EN bit in the REF\_CFG command, XDP700 executes the following procedure at power-up:



**Figure 8 Boost mode power-up**

1. **1st phase:** The  $V_{GS}$  starts ramping when INIT\_SOA\_REG state is entered. The  $T_{PERIOD}$  timer, defined by BOOSTMODE\_TMR and BOOSTMODE\_DC, activates at start of  $V_{GS}$  ramp.
2. **2nd phase:** The pulse timer  $T_{BOOST\_TMR}$  (value set in BOOSTMODE\_TMR) starts after the  $V_{GS}$  ramp has ended. The FET's current target is set to boost target  $I_{BOOST}$ :  
 - If  $I_{SOA}$  (programmed SOA current at actual  $V_{DS}$ ) programmed value  $> 0$ :  $I_{BOOST} = \text{multiplication factor} \times I_{SOA \text{ typ.}}$ . The multiplication factor is taken from a look up table stored in ROM and ranges from 1 to 8 for 1ms BOOSTMODE\_DC and from 4 to 128 for 100 $\mu$ s, depending on the selected FET and SOA line.  
 - If  $I_{SOA}$  programmed value = 0:  $I_{BOOST} = 0.25$  A typ.
3. **3rd phase:** After  $T_{BOOST\_TMR}$  has expired, the FET current is set to 0 by turning off the FET.
4. After  $T_{PERIOD}$  has expired, next  $V_{GS}$  ramp starts and system continues from 1st phase until target  $I_{SOA} \geq 0.5$  A for automatic boost or  $V_{DS}$  of the FET is lower than 1 V for full boost.
5. After target  $I_{SOA}$  or  $V_{DS}$  reach these points depending on the selected mode, FET's power-up will be finalized via continuous SOA.

Boost mode has a dynamic resolution that changes at the Resolution Breakpoint programmed in the SOA PMBus command. This value must be programmed according to the FET's SOA and it's the voltage point where the allowed current level is equal to 0.5A. Below this point, the resolution of the control loop is 1.95 mA. Above this point, the resolution changes to 0.5 A.

To calculate  $T_{PERIOD}$ :

$$T_{PERIOD} = \frac{BOOSTMODE\_TMR}{BOOSTMODE\_DC}$$

**Equation 2**

For example, if BOOSTMODE\_TMR = 1ms and BOOSTMODE\_DC = 10%:

$$T_{PERIOD} = \frac{1ms}{10\%} = 10ms$$

**Equation 3**

**Boost Mode Considerations**

- BOOSTMODE\_TMR and BOOSTMODE\_DC must be configured according to FET max SOA capabilities.

**4.1.6 Power good**

The power good signal is asserted to indicate when the following conditions are met:

- The input voltage is within the UV and OV/OVin limits, the output voltage is above OUV limit
- FET's and controller's over-temperature protection limits are not violated
- FET is fully enhanced ( $V_{GS} > 7.8\text{ V}$  and  $V_{DS} < 1.0\text{ V}$ ) after its power-up
- No fault is present

All above means that controller is in ON or I\_REG state.

The PWRGD assertion is performed after a programmable power good assertion deglitch time (see [Table 10](#)).

The PWRGD de-assertion also has a programmable power good de-assertion deglitch time, which helps to avoid unnecessary signal's re-toggling due to short voltage or current jumps.

PWRGD signal polarity is configurable (active low or active high) by means of the PWRGD\_POLARITY bit in order to support sequential turn-on capability.

**4.1.7 Support of sequential turn-on**

PWRGD, FAULT, WARN and UV/EN pins are used for communication between different devices if sequential turn-on implementation is desired based on "Master/Slave" approach.

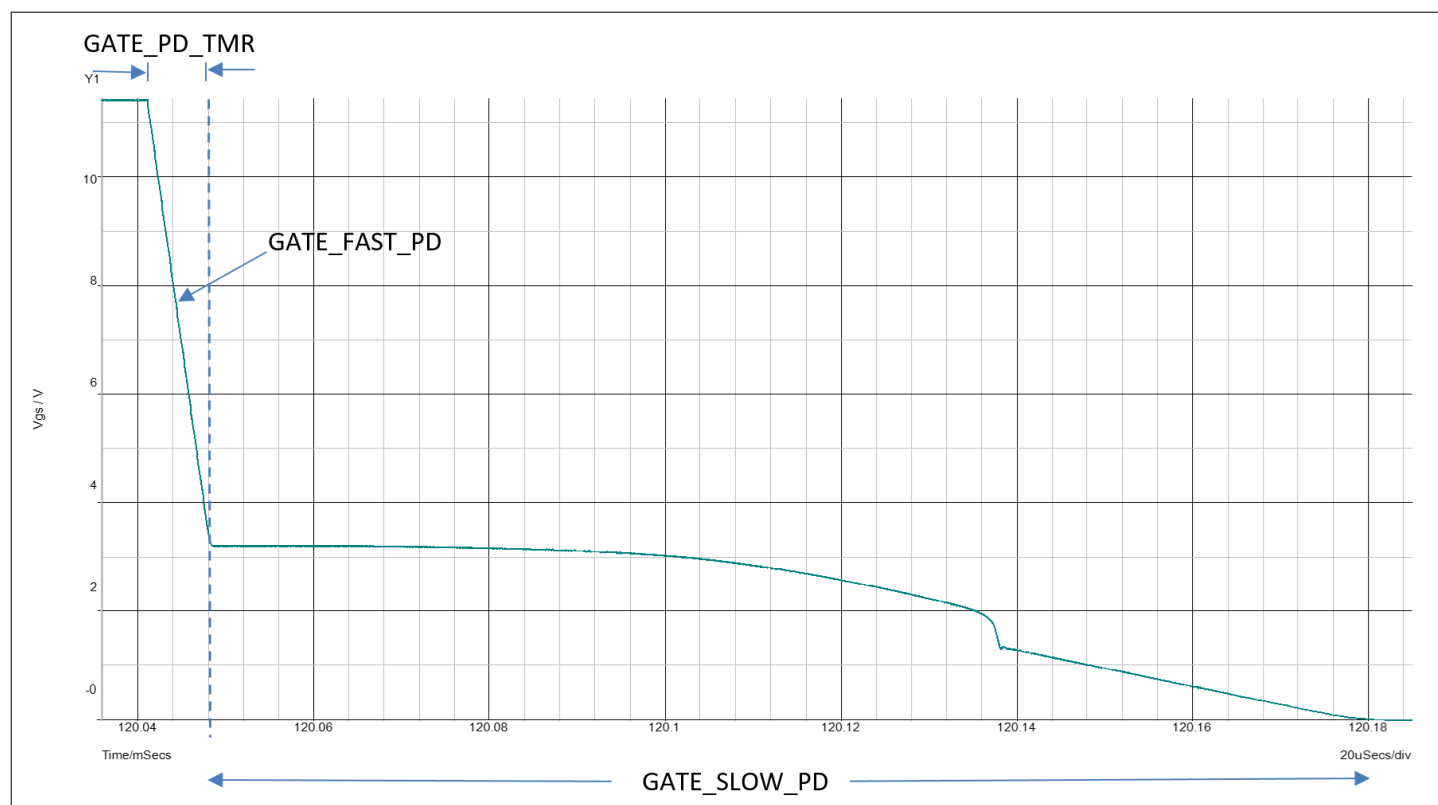
Voltage levels of UV/EN, PWRGD, FAULT and WARN pins are compatible so that PWRGD, FAULT or WARN pins of a "Master" device can drive the UV/EN pin of a "Secondary" device and control its turn-on or off.

**4.1.8 Support of OR-ing capability**

When PWRGD output pin is configured as active Low, two controllers can be connected to the same output voltage, so that, when output of the "Master" goes down, the "Secondary" can supply the necessary voltage. It is a backup supply scenario. A deglitch period can be configured between "Master" undervoltage and "Secondary" (backup) enable by means of an UV/EN pin response delay or deglitch period. System has to be designed so that a capacitor can supply the necessary power during this supply outage. The power-up latency of the "Secondary" controller has to be taken into account too.

**4.1.9 FET power down**

Turn-off of the FET can be triggered manually or automatically due to a fault. In general, FET is turned-off by pulling  $I_{GATE\_SPD}$  from its gate, except for the cases of OVIn, OVout and SOC faults. In these cases, a configurable two step turn-off has been implemented in order to avoid FET drain-source voltage overshoots.



**Figure 9 FET power down**

The first step is configurable to 1.5 A current source or 200  $\Omega$  resistor through the bit GATE\_FAST\_PD[0]. If 1.5 A is selected, this current will be pulled out of the gate of the FET until it is completely turned off, ignoring the second step. If the 200  $\Omega$  resistor is selected, it discharges the gate of the FET for a time defined by the GATE\_PD\_TMR timer. This timer will start running when the turn-off process starts as soon as fault is detected. The timer must be calculated depending on the FET gate charge so that the plateau voltage is passed in this first stage. This “fast” stage avoids the increase of the current by reaching the FET’s linear region as fast as possible.

Then, the second stage limits the voltage overshoot by slowing down the di/dt of the system. This stage starts when GATE\_PD\_TMR expires. When it does, level of current being pulled out of the gate changes according to what is programmed in GATE\_SLOW\_PD[1:0] bits. A lower level of current will keep the FET in linear region for a longer time, which will, as a result, slow down the di/dt until the threshold voltage of the FET is passed and the FET is completely off.

If GATE\_PD\_TMR is 0 and GATE\_FAST\_PD[0] = 1, gate discharges slowly with GATE\_SLOW\_PD only, without a fast pull-down phase. The minimum allowed time to be programmed in GATE\_PD\_TMR (if it's not 0) is 250ns.

**Note:** Due to the benefits of the two-step turn-off, it is recommended to always use it after OVin, OVout and SOC faults.

#### 4.1.10 Restart

A system reset can be triggered by issuing a RESTART PMBus command. If this command is sent, FET turns-off for 10 seconds (WAIT\_10S state in state machine), removing power from the output. After these 10 seconds, system transitions to STANDBY state and, if all the necessary conditions are met, FET automatically turns back on.

**Note:** OTP must not be manipulated during WAIT\_10S state.

## 4.2 Faults

XDP700 incorporates many protections that ensure safe operation for the FET, source and load in different scenarios. Faults are events that could stop system operation or even potentially damage some part of the circuit, so protective actions are taken in response to this kind of events.

For this purpose, different FET gate pull-down mechanisms are incorporated as described in [FET power down](#):

- Regular/slow pull-down: In case of a fault event that is not dangerous for the system, FET is turned off by pulling a typical current of 250  $\mu\text{A}$  / 500  $\mu\text{A}$  / 750  $\mu\text{A}$  / 1.25 mA (programmable by means of GATE\_SLOW\_PD bits in TURN\_OFF\_CTRL PMBus command) from its gate.
- Strong/fast pull-down: In case of an emergency fault,
  - 1) a typical current of 1.5 A are pulled from the FET's gate for extremely fast turn-off or
  - 2) a two step FET's turn-off is applied to keep FET's  $V_{DS}$  below avalanche breakdown. Method 1) or 2) has to be selected by means of GATE\_FAST\_PD bits in TURN\_OFF\_CTRL command depending on the system setup and requirements.

There are four ways in which XDP700 reports when a fault has occurred:

- Read Fault Status commands via PMBus interface: Each one of the faults has a corresponding bit in the STATUS\_FAULTS command which is set after a fault has occurred.
- The fault indication pins: FAULT, LED#, SMBALERT#:
  - GPO0/FAULT NMOS open drain pin (output polarity is programmable): The status bits can be reflected on the FAULT pin to alert the processor/MCU that any of these events has happened.
  - GPO1/LED# pin is also an NMOS open drain pin, which polarity is fixed. If a fault occurs, this pin is driven low. An LED can be connected from a voltage source (anode) to the LED# pin (cathode) for a visual indication of the fault. If VREG is used as the voltage source of the LED#, care must be taken not to exceed the maximum power capabilities of the XDP700 (see [Handling external current at VREG pin](#)). LED# pin has a maximum current sink capability of  $i_{GPO\_max}$ .
  - The SMBALERT# is an open drain pin with an active low polarity that can be configured to provide a summary of all triggered faults, warnings or both. Its output is a logic OR of all the faults or warnings, depending on its configuration in GPO\_CFG command. SMBALERT# can be output in pins GPO0 or GPO3. Care must be taken to configure only one of them as SMBALERT#.
    - Mask commands are provided for the user to select which faults are to be reflected on the FAULT, LED# and SMBALERT# pins.

As a result of the fault, PWRGD pin is also deasserted.

Faults can be disabled by clearing their enable bits, which means they are not detected nor reported.

The fault status bits and pins will remain set until they are cleared:

- by means of the CLEAR\_FAULTS PMBus command
- or by a controller restart (toggling EN pin) or a power cycle

The FAULT pin alerts the processor/MCU when any fault happens. This pin's state is an OR of all unmasked faults, leading to the possibility that if a masked higher priority fault is processed with the pin correctly in inactive state, a lower priority unmasked fault might cause the pin to be driven active.

For a proper detection, when a fault happens, the FAULT pin remains asserted for a minimum time of  $t_{FAULT\_MIN}$ , regardless of the duration of the fault conditions.

To service the faults properly, CLEAR\_FAULTS command and EN pin toggling are ignored in fault state and until fault process has finished and XDP700 has gone to LATCH\_OFF state, or, in case of automatic restart, STANDBY or ON. Once the controller has left FAULT state, faults can be cleared (if fault conditions are not present anymore) and device can be restarted. LATCH\_OFF state can be monitored by reading the STATUS\_LATCH\_OFF bit in STATUS\_MFR\_SPECIFIC command.

**Note:** For a correct functionality of the faults and in order to avoid enabling/disabling them while any fault conditions are actually present, all faults must only be enabled or disabled while controller is in STANDBY state.

Faults are divided in priority groups. In case a second fault with higher priority comes while servicing another fault, the first one is put on hold until the higher priority is served. When finished serving the high priority fault, system resumes servicing the fault that was put on hold. If the fault being serviced has same or higher priority than the second fault, system acts in a first-come, first-served fashion.

Priority groups and priorities are:

- 1: MEM
- 2: SDS, SGD, SGS, UR.
- 3: OVout.

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 4 Product features

- 4: SOC.
- 5: OT, TSD.
- 6: OVin.
- 7: OV.
- 8: UV.
- 9: OUV.
- 10: WD.
- 11: OC, SOAR.

The table below shows when particular faults detection and processing is active:

**Table 21** Faults during operation states

| Activation (X) of FAULT's detection during operation states |                     |              |             |             |                  |    |       |                 |              |                                 |
|-------------------------------------------------------------|---------------------|--------------|-------------|-------------|------------------|----|-------|-----------------|--------------|---------------------------------|
| FAULT NAME                                                  | State of controller |              |             |             |                  |    |       |                 |              |                                 |
|                                                             | POR_IN<br>IT        | READ_CF<br>G | CHK_FE<br>T | STANDB<br>Y | INIT_SOA_RE<br>G | ON | I_REG | FAULT           | WAIT_<br>10S | MEM_FAU<br>LT/<br>LATCH_OF<br>F |
| MEM                                                         | --                  | X            | --          | X           | --               | -- | --    | --              | --           | --                              |
| SDS                                                         | --                  | --           | X           | X           | --               | -- | --    | X               | --           | --                              |
| SGD                                                         | --                  | --           | X           | X           | --               | -- | --    | X               | --           | --                              |
| SGS                                                         | --                  | --           | --          | --          | X <sup>*1</sup>  | -- | --    | --              | --           | --                              |
| UR                                                          | --                  | --           | --          | --          | --               | -- | --    | X <sup>*2</sup> | --           | --                              |
| OVout                                                       | --                  | --           | --          | X           | X                | X  | X     | X               | --           | --                              |
| SOC                                                         | --                  | --           | --          | --          | X                | X  | X     | --              | --           | --                              |
| OT                                                          | --                  | --           | --          | X           | X                | X  | X     | X               | --           | --                              |
| TSD                                                         | --                  | --           | --          | X           | X                | X  | X     | X               | --           | --                              |
| UV                                                          | --                  | --           | --          | X           | X                | X  | X     | X               | --           | --                              |
| OV                                                          | --                  | --           | --          | X           | X                | X  | X     | X               | --           | --                              |
| OVin                                                        | --                  | --           | --          | X           | X                | X  | X     | X               | --           | --                              |
| OUV                                                         | --                  | --           | --          | --          | --               | X  | X     | --              | --           | --                              |
| WD                                                          | --                  | --           | --          | --          | X                | -- | --    | --              | --           | --                              |
| OC                                                          | --                  | --           | --          | --          | --               | X  | X     | --              | --           | --                              |
| SOAR                                                        | --                  | --           | --          | --          | --               | X  | X     | --              | --           | --                              |

Notes:

\*1): Right at the point when watchdog timer expires.

\*2): The UR fault can occur only in FAULT state when retry counter expires after any of the retry fault events (SOC, OUV, WD, OC, SOAR).

## 4.2.1 Memory fault

### Memory OTP (MEM) Fault

If an OTP read or write error is detected during READ\_CFG state, XDP700 switches to FAULT and consecutively to the MEM\_FAULT state, which initiates controller's latch-off. FET is switched off and PWRGD signal is deasserted. This fault can be cleared by means of a power cycle only, in which case the system restarts from the POR\_INIT state.

## 4.2.2 Damaged FET faults

There is a FET healthy check phase after READ\_CFG state and until STANDBY phase has finished.

The drain-source and gate-drain low voltage checks start as soon as the READ\_CFG phase is over at first plug-in or just before starting any retry attempt.

As a consequence of any of these faults, XDP700 switches to FAULT state and then passes directly to the LATCH\_OFF state.

### Shorted FET Drain-Source (SDS) Fault

If current above SDS limit (see table below) through the sense resistor is detected in CHK\_FET, STANDBY or FAULT states, and  $V_{GS}$  of the FET is lower than 1 V while gate pin is weakly driven low, an SDS fault is issued.

This fault is enabled, masked and monitored by means of the FET\_DS bits in ENABLE\_FAULTS, MASK\_FAULTS and STATUS\_FAULTS PMBus commands respectively.

The following table shows the corresponding typical current limit in Amp at  $R_{SNS} = 1\text{ m}\Omega$ .

**Table 22 SDS limit**

| $V_{SNS\_CS}$ (mV) | 12.5 | 25   | 50  | 100 |
|--------------------|------|------|-----|-----|
| SDS limit (A)      | 0.24 | 0.52 | 1.1 | 2.2 |

### Shorted FET Gate-Drain (SGD) Fault

SGD fault is triggered in the CHK\_FET, FAULT or STANDBY states:

- In CHK\_FET state: If the FET's  $V_{GS}$  goes above 1 V and current flow at the ISNS\_x pins exceeds the limits in [Table 22](#).
- When controller enters the FAULT or STANDBY state and activates any gate pull down. If the FET's  $V_{GS}$  does not go below 1 V within 10 ms.
- In FAULT and STANDBY state: If, after FET's  $V_{GS}$  goes below 1 V within 10 ms when FET's gate is weakly driven low (regular/slow gate pull down), the FET's  $V_{GS}$  goes back above 1 V and current flow at the ISNS\_x pins exceeds the limits in [Table 22](#).

This fault is enabled, masked and monitored by means of the FET\_GD bits in ENABLE\_FAULTS, MASK\_FAULTS and STATUS\_FAULTS PMBus commands respectively.

### Shorted FET Gate-Source (SGS) Fault

If no power good is achieved in power-up procedure when the watchdog timer expires and  $V_{GS} < 1\text{ V}$  at this point, SGS fault will be issued.

This fault is enabled, masked and monitored by means of the FET\_GS bits in ENABLE\_FAULTS, MASK\_FAULTS and STATUS\_FAULTS PMBus commands respectively.

**Note:** WATCHDOG timer is used for this fault even if watchdog fault is disabled. If a specific timer value is desired to cover SGS in this case, the timer must be configured accordingly.

Since boost mode pulses the FET's gate voltage on and off, it is possible that it is low at the time the watchdog timer expires, generating a false SGS fault. Therefore SGS fault must always be disabled when using boost mode.

### 4.2.3 Input voltage faults

#### System Input Undervoltage (UV) Fault

In FDM mode, if MODE bit = 1 (DCM), the UV fault limit is set digitally by VIN\_UV\_FAULT\_LIMIT.

In AADM mode or FDM mode, if MODE bit = 0 (ACM), the limit  $V_{UVEN\_LTH}$  is set by means of external components (see [Setting OV and UV in ACM](#)).

If the input voltage reaches or falls below the corresponding limit, UV\_TMR[2:0] starts running. If voltage raises above VIN\_UV\_FAULT\_LIMIT or  $V_{UVEN\_UTH}$  before the timer expires, system stays in ON state. Otherwise, if voltage is still low when timer expires, fault will be triggered and FET is turned off with a regular pull-down.

UV fault has a hysteresis configurable by means of the VIN\_UV\_HYST[3:0] bits and it depends on the configured VTLM\_RNG. In the case of 88V VTLM\_RNG, the hysteresis can be configured from 2 to 13 V. If VTLM\_RNG is configured to 44 or 22 V, it is scaled accordingly. This hysteresis is not only valid after a UV fault has happened, but also at power-up. System doesn't transition from STANDBY to INIT\_SOA\_REG if input voltage is lower than VIN\_UV\_FAULT\_LIMIT + VIN\_UV\_HYST.

In order to avoid false triggering of the UV fault when the voltage is ramping up at first power-up, the detection of this fault starts only when its programmed limit (analog or digital) is crossed and the EN\_DG timer has expired.

#### System Input Overvoltage (OV) Fault

In FDM mode, if MODE bit = 1 (DCM), OV fault limit is set digitally by VIN\_OV\_FAULT\_LIMIT.

In AADM mode or FDM mode, if MODE bit = 0 (ACM), the limit  $V_{OV\_UTH}$  is set by means of external components (see [Setting OV and UV in ACM](#)).

If the input voltage reaches or raises above the corresponding limit, OV\_TMR[2:0] starts running. If the voltage falls below VIN\_OV\_FAULT\_LIMIT or  $V_{OV\_LTH}$  before the timer expires, the system stays in ON state. Otherwise, if the voltage is still high when timer expires, a fault is triggered and FET is turned off with a regular pull-down.

XDP700 waits until FET is completely turned-off, then keep monitoring the input voltage and stay idle in the FAULT state until it falls below VIN\_OV\_FAULT\_LIMIT minus a hysteresis of 0x60 (DCM mode, see [Table 23](#)) or  $V_{OV\_LTH}$  (ACM mode). In this case, the power-up sequence is initiated.

**Table 23 Voltage hysteresis**

|                          |      |      |      |
|--------------------------|------|------|------|
| V <sub>TLM_RNG</sub> (V) | 88   | 44   | 22   |
| Voltage (V)              | 2.06 | 1.03 | 0.52 |

#### On-chip Input Overvoltage (OVin) Fault

If, during STANDBY, INIT\_SOA\_REG, normal operation or FAULT state, the input voltage goes above the limit set by OVIN\_FAULT\_LIMIT bits in V\_SNS\_CFG PMBus command, OVIN\_TMR starts running. When it expires, a fault is triggered and FET is immediately turned-off with a fast or two-step pull-down (depending on configuration). XDP700 waits until FET is completely turned-off, then stays idle in FAULT state until input voltage goes below the lower OVin threshold of OVIN\_FAULT\_LIMIT minus a hysteresis of 5 V. Then power-up sequence is initiated.

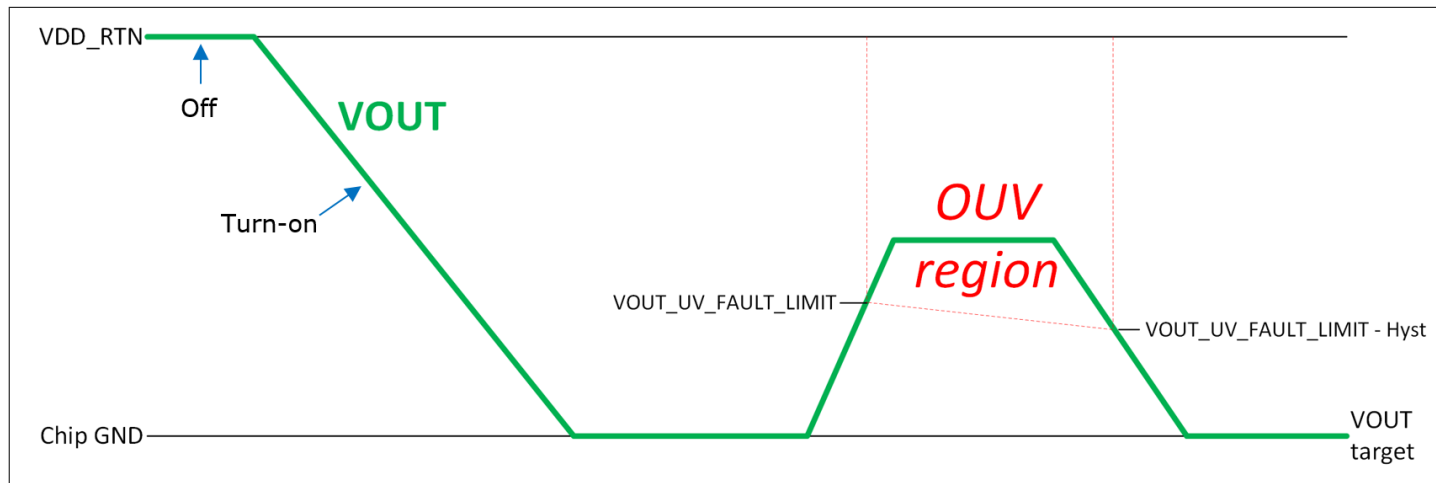
### 4.2.4 Output voltage faults

#### Output Undervoltage (OUV) Fault

If, during normal operation, the output voltage raises above the limit set by `VOUT_UV_FAULT_LIMIT`, `OUV_TMR[2:0]` timer starts running. If voltage goes back up before timer expires, the system continues normal operation. If OUV condition persists when timer expires, a fault is issued and FET is turned-off with a regular pull-down.

The system will retry to power-up after a cool-down period according to the `RETRY` command settings.

**Note:** It is important to take into account that, in case of a negative input voltage, the target `VOUT` in ON state is close to chip GND. Thus, an output undervoltage event means the output voltage level moves away from GND, towards `VDD_RTN`.



**Figure 10** Output undervoltage (OUV) fault

Therefore the limit is calculated as follows:

$$VOUT\_UV\_FAULT\_LIMIT = VDD\_RTN - (OUV - GND)$$

#### Equation 4

Where OUV is the desired output undervoltage level.

### Output Overvoltage (OVout) Fault

To protect the system from voltage surges at the output, if voltage raises above the `OVOUT_FAULT_LIMIT` in `V_SNS_CFG` command, a fault is triggered and FET is turned on as fast as possible (with a 10 mA pull-up) or kept on if it already is. The `OVOUT_HOLD[2:0]` timer starts running as soon as FET turn-on process starts. FET will remain on for a minimum time of `tOVOUT_min` and until the `OVOUT_HOLD` timer expires regardless of the output voltage level.

If `OVOUT_HOLD` timer is programmed to 0, the FET will remain on for `tOVOUT_min`.

After this process and as soon as output voltage falls below the `OVOUT_FAULT_LIMIT` minus a hysteresis of 5 V, FET is turned off with a two-step pull-down, pass through the `CHK_FET` state and make sure there are no FET issues. The `FAULT` pin is deasserted before `CHK_FET` state. Then FET is turned on again if it was on before the fault happened.

## 4.2.5 Current and temperature faults

### Overcurrent (OC) Fault

An OC condition is detected if, during normal operation, FET current reaches its programmed level of  $I_{OC}$ . If this condition occurs, the `SOAD_TMR[2:0]` timer starts. If the FET current goes below  $I_{OC}$  before timer expires, the system continues normal operation. If the OC condition persists when the timer expires, XDP700 starts the OC/SOA regulation timer (`SOAR_TMR[2:0]`) and current regulation at  $I_{OC}$  level (`I_REG` state) by lowering FET's  $V_{GS}$  voltage. If `I_REG` state

ends (FET is fully enhanced again) before this second timer expires, the system goes back to normal. Otherwise an OC fault is triggered and FET is turned off with a regular pull-down.

The system will retry power-up after cool down period according to RETRY command settings.

The SOA regulation timer configurable steps are compliant with common SOA lines so that the protection can be implemented according to the maximum allowed timer for a specific  $V_{DS}$  vs  $I_{DS}$  scenario.

**Note:** For safety reasons during I\_REG state, if current through the FET goes below 1 A, the regulation will stop, FET is turned off and a SOAR fault is declared.

### Severe Overcurrent (SOC) Fault

An SOC event is detected when, during INIT\_SOA\_REG or normal operation, FET's  $I_{DS}$  current reaches the level which creates a voltage drop over the sense resistor exceeding programmable level of  $V_{SNS\_SOC}$ . The detection is done by means of an analog comparator for a faster reaction. This comparator has a programmable SOC\_DG\_TMR deglitch time for detection.

If  $V_{SNS\_SOC}$  level of current is detected, SOC\_TMR will start running. If the SOC conditions are cleared before timer expires and no other fault conditions are present, the system goes back to normal. Otherwise a fault is triggered and FET is opened with a fast or two-step pull-down (depending on configuration) as soon as this timer expires.

The system will retry a power-up after a cool down period according to RETRY command setting. The fault indication pins are automatically deasserted when fault conditions are cleared and PWRGD asserted after a successful retry.

SOC fault configuration is done by means of the SOC\_FAULT\_LIMIT bits, and it depends on CS\_RNG configuration, according to the following table:

**Table 24 Configuration of SOC levels (in mV)**

|                                |     | I_SNS_CFG.CS_RNG[1:0] |    |      |    |
|--------------------------------|-----|-----------------------|----|------|----|
|                                |     | 00                    | 01 | 10   | 11 |
| I_SNS_CFG.SOC_FAULT_LIMIT[2:0] | 000 | 12.5                  |    | 25   |    |
|                                | 001 | 18.75                 |    | 37.5 |    |
|                                | 010 | 25                    |    | 50   |    |
|                                | 011 | 37.5                  |    | 75   |    |
|                                | 100 | 50                    |    | 100  |    |
|                                | 101 | 75                    |    | 150  |    |
|                                | 110 | 100                   |    | 200  |    |
|                                | 111 | 150                   |    | 300  |    |

### RMS Current (RMS)

OC protection can be configured to react at RMS current calculation limit instead of instantaneous measurements.

RMS\_EN bit in REG\_CFG command enables or disabled the RMS calculation function of the OC protection. If enabled, the protection level is based on RMS calculation. Since RMS is a sub-function of OC, OC must be enabled (by means of the OC bit in ENABLE\_FAULTS command) if the RMS function is desired.

RMS does not have mask and status bits, but OC corresponding mask and status bits are used instead.

RMS\_SAMPLE\_TMR specifies the integration time for the RMS current protection calculation.

If the RMS\_EN bit is set (RMS function is enabled), the CS\_RNG\_TRIM bits specifies the RMS current level (as a proportion of  $V_{SNS\_CS}$ ) at which the OC fault is triggered. If this RMS current level is exceeded, FET is turned off

immediately with a regular pull-down, skipping the deglitch and regulation phases configured in the SOAD\_TMR[2:0] and SOAR\_TMR[2:0] bits.

### SOA Regulation (SOAR) Fault

After ON state is reached and FET is fully enhanced, there could be different possible scenarios in which FET SOA limits are violated. For example:

- Input voltage suddenly increases generating a certain  $V_{DS}$  meanwhile the output cap is charged up to the new voltage level
- $R_{DS(on)}$  is too high
- During I\_REG state after an OC event,  $V_{DS}$  has to increase too much in order to keep the current at an appropriate level

In this scenario, the SOAD\_TMR[2:0] deglitch timer starts. If FET  $V_{DS}$  and  $I_{DS}$  go back within the SOA limits before the timer expires, the system continues normal operation in ON state. Otherwise the SOAR\_TMR[2:0] regulation timer starts while the system continues to regulate the current to stay within the SOA limits. If SOAR condition is cleared before this second timer expires, system goes back to ON state. If it persists, a SOA regulation fault is triggered and FET is opened with a regular pull-down.

If the regulated current through the FET goes below a level of 1 A, regulation stops, FET is turned off and a SOAR fault is declared.

The system will retry power-up after a cool down period according to RETRY command settings.

**Note:** The SOAR fault disabling means that a fault is never triggered and FET is never turned off in case of a SOA limits violation. It is recommended to keep the SOAR fault enabled for safety reasons.

### Overtemperature (OT) Fault

If, during STANDBY, INIT\_SOA\_REG, normal operation or FAULT, the temperature measured between the TSNS\_P and TSNS\_N pins raises above the OT\_FAULT\_LIMIT value, a fault is triggered and FET is opened with a regular pull-down. XDP700 waits until FET is completely turned off, then keeps monitoring the FET temperature and stays in the FAULT state until it drops below OT\_FAULT\_LIMIT - 25°C. In this case, the power-up sequence initiates and PWRGD pin asserts as soon as the necessary conditions are met.

### On-chip Thermal Shut-down (TSD) Fault

XDP700 has an on-chip temperature sensor with a programmable fault limit of  $T_{TS\_UTH}$ . If die temperature exceeds this value, a fault is triggered and FET is opened with a regular pull-down. XDP700 waits until FET is completely turned-off, then remains idle in the FAULT state until the temperature drops below  $T_{TS\_LTH}$  (which is equivalent to  $T_{TS\_UTH} - 10^{\circ}\text{C}$ ), at which point the power-up procedure is started.

## 4.2.6 Power-up faults

### Unsuccessful Power-up (Watchdog, WD) Fault

The watchdog timer can be configured by means of the WATCHDOG[3:0] bits. Its configurable steps are compliant with common SOA lines so that protection can be implemented according to the maximum allowed timer for a specific  $V_{DS}$  vs  $I_{DS}$  scenario. It starts running as soon as power-up procedure starts in the INIT\_SOA\_REG state. If FET is not fully enhanced ( $V_{DS} < 1.0\text{ V}$  and  $V_{GS} > 7.8\text{ V}$ ) before the timer expires, a WD fault is triggered and FET is turned-off with a regular pull-down.

A power-up is retried according to the RETRY command settings, in which case, the fault indication pins are cleared when leaving FAULT state before any retry attempt. The corresponding status bit remains set until it is manually cleared or device is restarted or power cycled.

### Unsuccessful Retry (UR) Fault

The UR fault can only occur in FAULT state when the retry counter expires after one of the retry fault events (SOC, OUV, WD, OC, SOAR). The retry counter decrements on each retry event. If it reaches a value of zero (maximum number of programmed retries has been reached), a UR fault is triggered and the system goes to and remains in LATCH\_OFF state.

## 4.2.7 Internal protection fault

### VREG Fault

If, at any point of operation, voltage at VREG pin goes below 4.1 V, system will trigger a power-on reset. This fault is not signaled at the fault indication pins, nor does it have a bit in the STATUS\_FAULTS PMBus command.

## 4.3 Retry

XDP700 can be configured to automatically retry FET's power-up after FET shut down due to the following faults: OUV, Watchdog, OC, SOAR, SOC.

The number of retries can be configured from 0 (system latches off after first fault event) to 32 by setting the corresponding number in the RETRY\_COUNTER[2:0] bits in the RETRY PMBus command.

The retry counter can also be disabled, which means the system will keep retrying an infinite number of times until it is turned off or reset.

The controller waits for a cool down period configurable from 0 to 64 seconds (COOLD\_TMR[2:0] bits in RETRY PMBus command) before every retry attempt. During this period, the controller remains in FAULT state and CLEAR\_FAULTS command and EN pin toggling will be ignored.

Retry mask bits are provided so that the cool down period can be turned on or off for any of the faults individually. If both RETRY\_COUNTER and fault retry masks are set to 0, system will keep retrying indefinitely, skipping the cool down period.

If a successful FET's power-up is achieved during a retry attempt, the retry OK deglitch timer (RETD\_TMR[2:0] bits in RETRY PMBus command) starts running as soon as ON state is reached.

If no fault has occurred when this timer expires, the retry counter is set to its initial state.

If the maximum number of retries is reached without success, an unsuccessful retry fault, which initiates Latch-off, is issued.

If the retry feature is used to avoid long start-up times due to the fault that caused the retry, it is recommended to enable the watchdog (WD) fault and its corresponding watchdog retry mask in MASK\_FAULTS PMBus command.

### Gate Voltage Fast Recovery

The gate voltage fast recovery is turning FET on as fast as possible avoiding FET's regulation during retry attempts after an SOC fault.

When the feature is enabled by setting the GATE\_REC\_EN bit in the RETRY command, the cool down period before retry is ignored after an SOC fault.

For all cases when GATE\_REC\_EN='1' and entering INIT\_SOA\_REG, if the control loop recognizes NO regulation conditions (FET's  $V_{DS} < 1.0$  V), the gate strong pull-up with typically 10 mA current capability is activated for a fast FET turn-on within a time of 100  $\mu$ s. System retries with fast recovery as many times as configured by the RETRY\_COUNTER. If recovery is not successful before RETRY\_COUNTER expires, system goes to latch-off state.

## 4.4 Latch-off

LATCH\_OFF and MEM\_FAULT are latch-off states. In case of a latch-off fault, the controller's FAULT state is followed by the LATCH\_OFF or MEM\_FAULT state and controller:

#### 4 Product features

- Keeps FET off and remains in LATCH\_OFF or MEM\_FAULT state
- Latches the state of all status commands including fault and warning ones, except for STATUS\_CML. This is in order to support reporting of COM warning in LATCH\_OFF state
- Latches the state of status pins (PWRGD, FAULT, LED#, SMBALERT#, WARN)
- Keeps service blocks (including VREG), telemetry, communication PMBus interface and necessary digital running to support data communication

Latch-off is immediately triggered by the following faults:

- Memory OTP fault
- FET's Drain-source short fault
- FET's Gate-drain short fault
- FET's Gate-source short fault

Latch-off is triggered if during the following faults the max number of retries has been reached without successful recovery from fault (Unsuccessful retry (UR) fault occurs):

- Output undervoltage (OUV) fault
- Unsuccessful power-up (watchdog) fault
- Overcurrent (OC) fault
- SOA regulation fault
- Severe overcurrent (SOC) fault

If the retry counter set to zero the Latch-off is triggered right after any fault listed above occurs.

XDP700 can go out of LATCH\_OFF or MEM\_FAULT states by means of a power cycle. In which case, it starts operation from POR\_INIT state.

Alternative ways to go out of LATCH\_OFF (not applicable to MEM\_FAULT) are the PMBus CLEAR\_FAULTS command or the external EN signal High-to-Low transition (if the pin is configured as EN, see [Enable and Disable](#)). If either of these methods is used, the following actions take place:

- De-assert/release status pins (PWRGD, FAULT, WARN)
- Clear the FAULT and WARNING status commands
- Continue operation from CHK\_FET state

## 4.5 Warnings

Warnings are defined as alerts that do not turn off the FET. They are alerted through the WARN pin to the processor/MCU so that it can decide if any action is needed in response.

Each one of the warnings has a corresponding bit in the STATUS\_WARN command that is set when a warning has occurred.

These bits can be reflected in the GPO1/WARN pin to alert the processor/MCU that any of these events has happened. GPO1/WARN is an NMOS open drain pin (output polarity is programmable).

The SMBALERT# pin can be configured to provide a summary of all triggered faults, warnings or both. Its output is a logic OR of all the faults or warnings, depending on its configuration in GPO\_CFG command. A mask command is provided for the user to select which warnings are to be reflected on the WARN and SMBALERT# pins.

Warnings can be disabled by clearing their enable bits, which means they are not detected and are not reported.

Each one of the warnings descriptions below specifies when the "warning is cleared". This indicates when the conditions that generate one or more warnings are cleared.

The warning status bits and pins remain set until they are cleared:

- by means of the CLEAR\_FAULTS PMBus command
- or by a controller restart or a power cycle

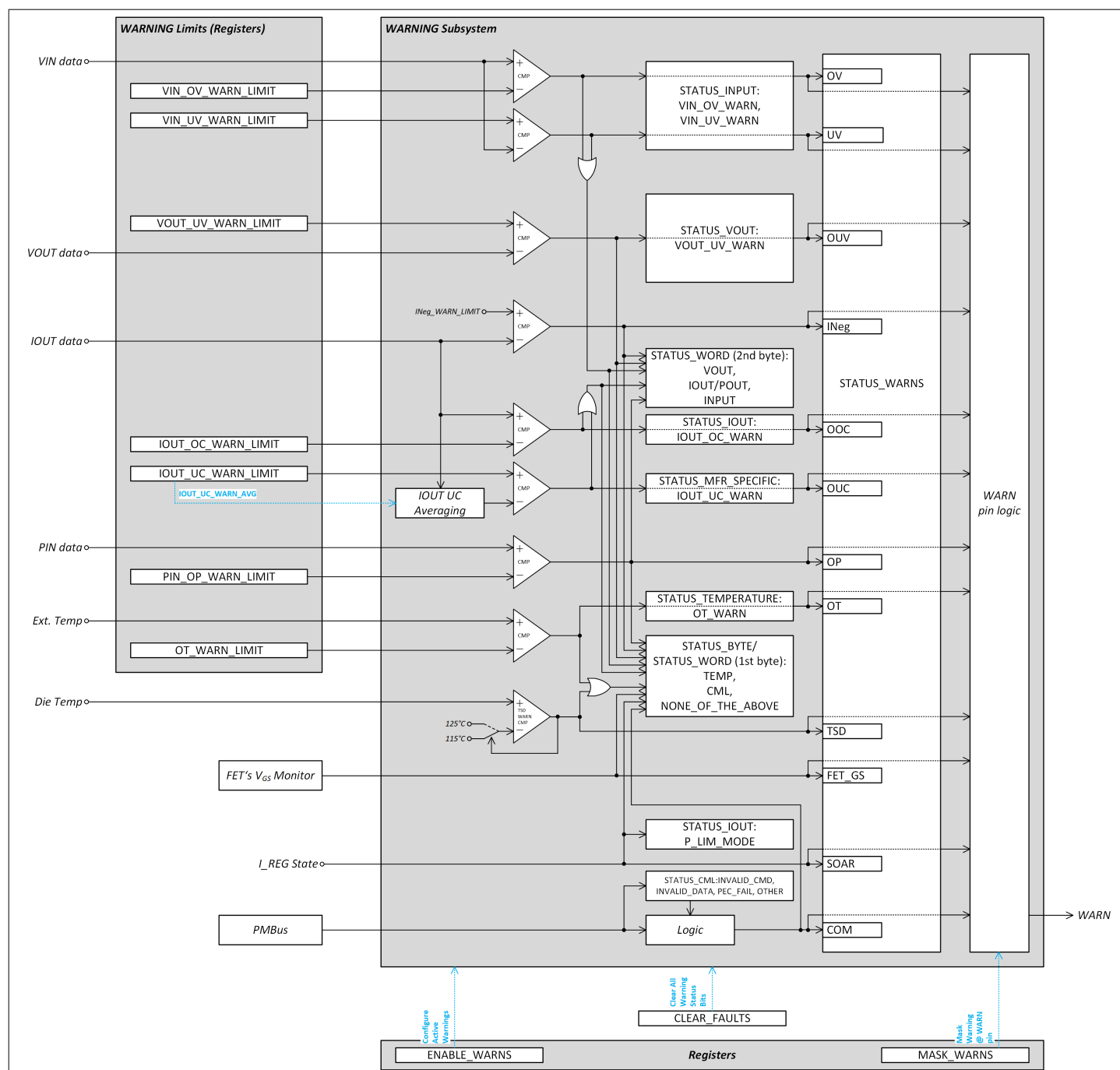
**Note:** Due to the nature of the COM warning, there are some exceptions on the way it is reported through the WARN pin and the way it is cleared. See details in [Communication warning](#).

The table below shows when particular warning's processing is active.

**Table 25**                      **Warnings during operation states**

| Activation (X) of WARNING's processing during operation states |                     |              |             |             |                      |    |       |       |              |                                 |
|----------------------------------------------------------------|---------------------|--------------|-------------|-------------|----------------------|----|-------|-------|--------------|---------------------------------|
| WARNIN<br>G NAME                                               | State of controller |              |             |             |                      |    |       |       |              |                                 |
|                                                                | POR_<br>INIT        | READ_<br>CFG | CHK_<br>FET | STANDB<br>Y | INIT_<br>SOA_RE<br>G | ON | I_REG | FAULT | WAIT_10<br>S | MEM_FA<br>ULT/<br>LATCH_<br>OFF |
| VGSL                                                           | --                  | --           | --          | --          | --                   | X  | --    | --    | --           | --                              |
| OT                                                             | --                  | --           | --          | X           | X                    | X  | X     | X     | --           | --                              |
| TSD                                                            | --                  | --           | --          | X           | X                    | X  | X     | X     | --           | --                              |
| UV                                                             | --                  | --           | --          | X           | X                    | X  | X     | X     | --           | --                              |
| OV                                                             | --                  | --           | --          | X           | X                    | X  | X     | X     | --           | --                              |
| OUV                                                            | --                  | --           | --          | --          | --                   | X  | X     | --    | --           | --                              |
| SOAR                                                           | --                  | --           | --          | --          | --                   | X  | X     | --    | --           | --                              |
| OUC                                                            | --                  | --           | --          | --          | --                   | X  | X     | --    | --           | --                              |
| OOC                                                            | --                  | --           | --          | --          | --                   | X  | X     | --    | --           | --                              |
| INeg                                                           | --                  | --           | --          | --          | --                   | X  | X     | --    | --           | --                              |
| OP                                                             | --                  | --           | --          | --          | X                    | X  | X     | --    | --           | --                              |
| COM                                                            | --                  | --           | --          | X           | X                    | X  | X     | X     | X            | X                               |

The following figure shows flow of all warnings.



**Figure 11** Warnings flow

## 4.5.1 Damaged FET warning

### Gate-Source Low Voltage (VGSL) Warning

If, during ON state,  $V_{GS}$  of the FET goes below 7.8 V, a VGSL warning is triggered indicating that there might be gate-source or gate-drain issues over life time. The warning is cleared as soon as  $V_{GS}$  of the FET raises above the same limit.

## 4.5.2 Input voltage and power warnings

### Input Undervoltage (UV) Warning

If the input voltage reaches or falls below VIN\_UV\_WARN\_LIMIT, a warning is triggered. If the voltage raises above this limit plus a hysteresis of 0x60 (see Table 23), the warning is cleared.

### Input Overvoltage (OV) Warning

If the input voltage reaches or raises above VIN\_OV\_WARN\_LIMIT, a warning is triggered. If the voltage falls below this limit minus a hysteresis of 0x60 (see Table 23), the warning is cleared.

### Input Overpower (OP) Warning

If the input power (as a product of VIN \* IOU) goes above the programmed PIN\_OP\_WARN\_LIMIT, the system generates an OP warning. If the input power goes below the limit minus a digital hysteresis of 0x100 (which corresponds to typically 0.4% of the maximum power), the warning is cleared. Averaging of power for this warning is done by the same setting as telemetry: P\_TELEMETRY\_AVG bits in TELEMETRY\_AVG PMBus command.

## 4.5.3 Output voltage warning

### Output Undervoltage (OUV) Warning

If the output voltage reaches or falls below VOUT\_UV\_WARN\_LIMIT, a warning is triggered. If the voltage raises above this limit plus a hysteresis of 0x60 (see Table 23), the warning is cleared.

## 4.5.4 Current and temperature warnings

### Output Overcurrent (OOC) Warning

An OOC warning is detected if the load current sensed by the voltage drop in the sense resistor exceeds the limit set by the IOU\_OC\_WARN\_LIMIT PMBus command. The warning is cleared if the current goes below the IOU\_OC\_WARN\_LIMIT minus a digital hysteresis of 0x80 (see Table 26).

### Output Undercurrent (OUC) Warning

If, during normal operation, the FET I<sub>DS</sub> current is less than a programmable value of the IOU\_UC\_WARN\_LIMIT PMBus command, an undercurrent event is triggered. The warning is cleared as soon as the current goes back above the IOU\_UC\_WARN\_LIMIT value plus a digital hysteresis of 0x80, which corresponds to the following current levels, depending on the V<sub>SNS\_RNG</sub> setting and assuming a 1 mΩ sense resistor:

**Table 26** Current hysteresis

| V <sub>SNS_CS</sub> (mV) | 12.5 | 25   | 50  | 100 |
|--------------------------|------|------|-----|-----|
| Current (A)              | 0.55 | 1.11 | 2.2 | 4.4 |

In order to avoid false triggering of OUC warning due to low current levels during INIT\_REG\_SOA or at the beginning of ON states, its detection starts only after current goes above the programmed OUC level for the first time in ON state.

### SOA Regulation (SOAR) Warning

A warning is issued when the controller enters the I\_REG state due to OC or SOA conditions violation if SOAR\_TMR[2:0] is not programmed to 0. The warning remains set until the controller leaves the I\_REG state.

### **Negative Current (INeg) Warning**

If negative current through the FET over  $I_{NEG\_MAX}$  level is detected, an INeg warning is triggered. The warning is cleared when the FET/load current sample returns to positive level ( $\geq 0$  A).

### **Overtemperature (OT) Warning**

If temperature raises above OT\_WARN\_LIMIT, an OT warning is issued. The warning is cleared when the temperature falls below OT\_WARN\_LIMIT minus a hysteresis of 25°C.

### **On-chip Thermal Shut-Down (TSD) Warning**

XDP700 has an on-chip temperature sensor. If, during power-up procedure, normal operation or FAULT state, temperature exceeds an upper threshold of 125°C, a warning is triggered. The warning is cleared when the temperature falls below 115°C.

## **4.5.5 Communication warning**

### **PMBus Interface Communication (COM) Warning**

This warning is triggered if the PMBus communication (read or write) is detected with fails. COM is the only warning that is enabled during LATCH\_OFF state. Since the WARN pin status is latched during this state, the warning is not reported through the pin. The only way to detect this warning during LATCH\_OFF is to read the STATUS\_CML command.

**Note:** WARN pin is not cleared by clearing STATUS\_CML after a COM warning. WARN pin is a reflection of COMM bit in STATUS\_WARN command, so this is the bit that has to be cleared in order for the WARN pin to be cleared.

## **4.6 Telemetry**

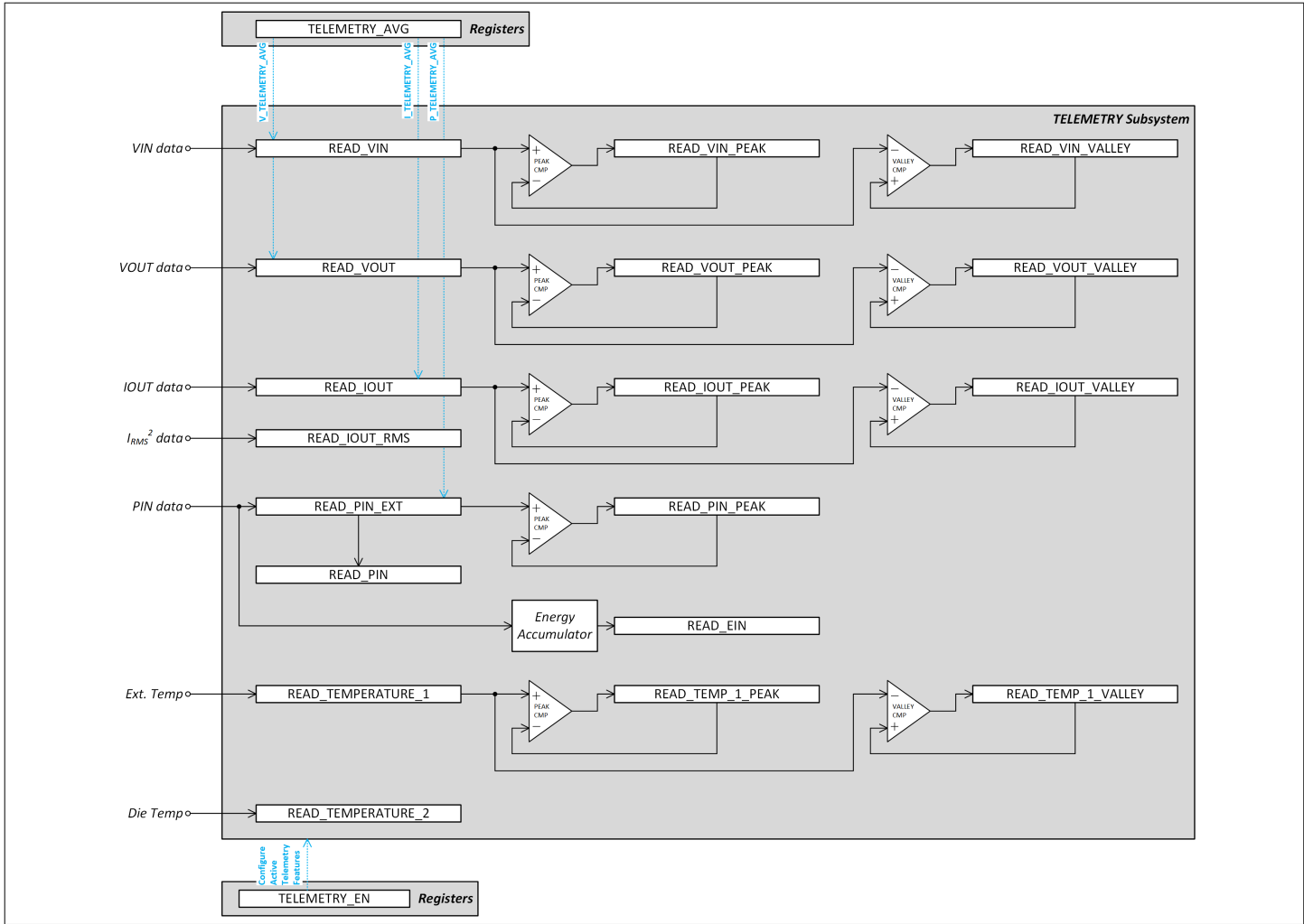
XDP700 provides real time accurate measurement and calculation data for:

- Input voltage
- Output voltage
- Load/FET current (by means of voltage drop over external shunt resistor), including its squared RMS value (if enabled)
- Input power
- Energy
- External FET temperature
- On-chip temperature

All information is provided through the PMBus interface by issuing the corresponding commands.

The figure below shows the telemetry flow:

**4 Product features**



**Figure 12** Telemetry flow

**4.6.1 Telemetry summary table**

The following table shows the sensing points of the different telemetry features and the commands to be used for configuration and to get the data read.

**Table 27** Telemetry summary

| Parameter            | Sensing            | Averaging configuration | Instantaneous/ averaged | Peak           | Valley           |
|----------------------|--------------------|-------------------------|-------------------------|----------------|------------------|
| Input voltage        | VDD_RTNS pin       | V_TELEMETRY_AVG         | READ_VIN                | READ_VIN_PEAK  | READ_VIN_VALLEY  |
| Load/FET current     | ISNS_REF/ISNS pins | I_TELEMETRY_AVG         | READ_IOUT               | READ_IOUT_PEAK | READ_IOUT_VALLEY |
| RMS Load/FET current | ISNS_REF/ISNS pins |                         | READ_IOUT_RMS           |                |                  |
| Output voltage       | VOUT pin           | V_TELEMETRY_AVG         | READ_VOUT               | READ_VOUT_PEAK | READ_VOUT_VALLEY |

(table continues...)

**Table 27** (continued) Telemetry summary

| Parameter                | Sensing                           | Averaging configuration | Instantaneous/averaged | Peak             | Valley             |
|--------------------------|-----------------------------------|-------------------------|------------------------|------------------|--------------------|
| Input power (16 bits)    | Input voltage x Load/FET current  | P_TELEMETRY_AVG         | READ_PIN               |                  |                    |
| Input power (24 bits)    |                                   |                         | READ_PIN_EXT           | READ_PIN_PEAK    |                    |
| Energy                   | Input power accumulated over time |                         | READ_EIN               |                  |                    |
| External FET temperature | TSNS_P/TSNS_N pins                |                         | READ_TEMPERATURE_1     | READ_TEMP_1_PEAK | READ_TEMP_1_VALLEY |
| On-Chip temperature      | On-chip temperature sensor        |                         | READ_TEMPERATURE_2     |                  |                    |

## 4.6.2 Averaged and instantaneous telemetry

### 4.6.2.1 Averaging telemetry data

Input voltage and power and output voltage and current measurements can be averaged by means of their corresponding bit fields: V\_TELEMETRY\_AVG[2:0], I\_TELEMETRY\_AVG[2:0] and P\_TELEMETRY\_AVG[2:0]. Each one consisting in 3 bits.

**Table 28** Telemetry averaging

| Bits settings | Averaged amount of samples |
|---------------|----------------------------|
| 000           | 1                          |
| 001           | 2                          |
| 010           | 4                          |
| 011           | 8                          |
| 100           | 16                         |
| 101           | 32                         |
| 110           | 64                         |
| 111           | 128                        |

### 4.6.2.2 Instantaneous telemetry data

Instantaneous measurements can be obtained by setting the corresponding x\_TELEMETRY\_AVG[2:0] bits to 000, so that only one sample is taken.

## 4.6.3 Peaks and valleys

x\_PEAK and x\_VALLEY commands report the maximum and minimum values (respectively) measured since the last time the command was cleared.

Peaks apply for the following parameters:

- Input voltage
- Output voltage

**4 Product features**

- Load/FET current
- Input power
- External FET temperature

Valleys apply for the following parameters:

- Input voltage
- Output voltage
- Load/FET current
- External FET temperature

The x\_PEAK and x\_VALLEY commands are cleared after reading their contents or by means of a power on reset. After reset, the first value read is compared to 0x000 (peaks) or 0xFFFF (valleys) and it becomes a new peak or valley respectively.

**Note:** Since the output voltage VOUT is measured with respect to GND pin in XDP700, increase of the VOUT\_PEAK level shows that the system output voltage drops and comes closer to RTN level and decrease of the VOUT\_VALLEY level shows that the system output voltage increases and comes closer to target.

**4.6.4 Telemetry via PMBus**

The following formula converts from PMBus direct format to "real world" values:

$$X = \frac{1}{m} * (Y * 10^{-R} - b)$$

**Equation 5**

Where:

X = Calculated "real world" value in the appropriate units (A, V, °C, etc)

m = Slope coefficient, is a two byte, two's complement integer

Y = Two byte two's complement integer received from the PMBus device

b = Offset, is a two byte, two's complement integer

R = Exponent, is a one byte, two's complement integer

To convert from "real world" values to PMBus direct format, use the following formula:

$$Y = (mX + b) * 10^R$$

**Equation 6**

Where:

Y = two byte two's complement integer to be sent to the unit

m = Slope coefficient, is the two byte, two's complement integer

X = "real world" value, in units such as Amperes or Volts, to be converted for transmission

b = Offset, is the two byte, two's complement integer

R = Exponent, is the decimal value equivalent to the one byte, two's complement integer.

Coefficients for these formulas are specified in the following table:

**Table 29 PMBus coefficients**

| Command                                     | VTLM_RNG | VSNS_CS | m    | b | r  |
|---------------------------------------------|----------|---------|------|---|----|
| VOUT_UV_WARN_LIMIT,<br>VOUT_UV_FAULT_LIMIT, | 88       | -       | 4653 | 0 | -2 |

(table continues...)

**Table 29** (continued) PMBus coefficients

| Command             | VTLM_RNG | VSNS_CS | m     | b | r  |
|---------------------|----------|---------|-------|---|----|
| VIN_OV_FAULT_LIMIT, | 44       |         | 9307  | 0 | -2 |
| VIN_OV_WARN_LIMIT,  | 22       |         | 18614 | 0 | -2 |
| VIN_UV_FAULT_LIMIT, |          |         |       |   |    |
| READ_VIN,           |          |         |       |   |    |
| READ_VIN_PEAK,      |          |         |       |   |    |
| READ_VIN_VALLEY,    |          |         |       |   |    |
| READ_VOUT,          |          |         |       |   |    |
| READ_VOUT_PEAK,     |          |         |       |   |    |
| READ_VOUT_VALLEY    |          |         |       |   |    |
| IOUT_OC_WARN_LIMIT, | -        | 12.5    | 23165 | 0 | -2 |
| IOUT_UC_WARN_LIMIT, |          | 25      | 11582 | 0 | -2 |
| READ_IOUT,          |          | 50      | 5791  | 0 | -2 |
| READ_IOUT_PEAK,     |          | 100     | 28956 | 0 | -3 |
| READ_IOUT_VALLEY    |          |         |       |   |    |
| READ_IOUT_RMS       | -        | 12.5    | 20808 | 0 | -2 |
|                     |          | 25      | 5202  | 0 | -2 |
|                     |          | 50      | 13005 | 0 | -3 |
|                     |          | 100     | 32513 | 0 | -4 |
| READ_PIN_EXT,       | 88       | 12.5    | 10780 | 0 | 0  |
| READ_PIN_PEAK       |          | 25      | 5390  | 0 | 0  |
|                     |          | 50      | 26949 | 0 | -1 |
|                     |          | 100     | 13474 | 0 | -1 |
|                     | 44       | 12.5    | 21559 | 0 | 0  |
|                     |          | 25      | 10780 | 0 | 0  |
|                     |          | 50      | 5390  | 0 | 0  |
|                     |          | 100     | 26949 | 0 | -1 |
|                     | 22       | 12.5    | 4312  | 0 | 1  |
|                     |          | 25      | 21559 | 0 | 0  |
|                     |          | 50      | 10780 | 0 | 0  |
|                     |          | 100     | 5390  | 0 | 0  |
| PIN_OP_WARN_LIMIT,  | 88       | 12.5    | 4211  | 0 | -2 |
| READ_PIN,           |          | 25      | 21054 | 0 | -3 |
| READ_EIN            |          | 50      | 10527 | 0 | -3 |
|                     |          | 100     | 5263  | 0 | -3 |
|                     | 44       | 12.5    | 8422  | 0 | -2 |

(table continues...)

**Table 29** (continued) PMBus coefficients

| Command                                                                                             | VTLM_RNG | VSNS_CS | m     | b     | r  |
|-----------------------------------------------------------------------------------------------------|----------|---------|-------|-------|----|
|                                                                                                     |          | 25      | 4211  | 0     | -2 |
|                                                                                                     |          | 50      | 21054 | 0     | -3 |
|                                                                                                     |          | 100     | 10527 | 0     | -3 |
|                                                                                                     | 22       | 12.5    | 16843 | 0     | -2 |
|                                                                                                     |          | 25      | 8422  | 0     | -2 |
|                                                                                                     |          | 50      | 4211  | 0     | -2 |
|                                                                                                     |          | 100     | 21054 | 0     | -3 |
| OT_FAULT_LIMIT,<br>OT_WARN_LIMIT,<br>READ_TEMPERATURE_1,<br>READ_TEMP_1_PEAK,<br>READ_TEMP_1_VALLEY | -        | -       | 52    | 14321 | -1 |
| READ_TEMPERATURE_2                                                                                  | -        | -       | 23    | 6225  | -1 |

**Note:** Current and power coefficients are normalized to a 1 mΩ sense resistor. See [Calculating PMBus direct format limits from "real world" values and vice-versa](#) for examples on how to calculate current and power.

#### 4.6.5 RMS current calculation

RMS current is calculated by integrating the current measurements over a specific period of time set by RMS\_SAMPLE\_TMR[1:0] bits in the SOA\_TMR command.

#### 4.6.6 Input power calculation

Input power is a multiplication of the load/FET current and the input voltage values.

Each time a current measurement is performed, a power calculation is performed, multiplying the recent values of load/FET current and the input voltage together before their corresponding averaging. Input power can be reported in 16 bits format (READ\_PIN) or an extended 24 bits format (READ\_PIN\_EXT).

#### 4.6.7 Energy calculation

Energy is the input power accumulated over time.

The calculated input power value is added to a power accumulator command that may increment a rollover counter if the value exceeds the maximum accumulator value. The power accumulator command also increments a power sample counter. The power accumulator and power sample counter are read using the same READ\_EIN command to ensure that the accumulated value and sample count are from the same point in time.

The MCU reading the data assigns a time stamp when the data is read. By calculating the time difference between consecutive uses of READ\_EIN and determining the delta in power consumed, it is possible for the MCU to determine the total energy consumed over that period.

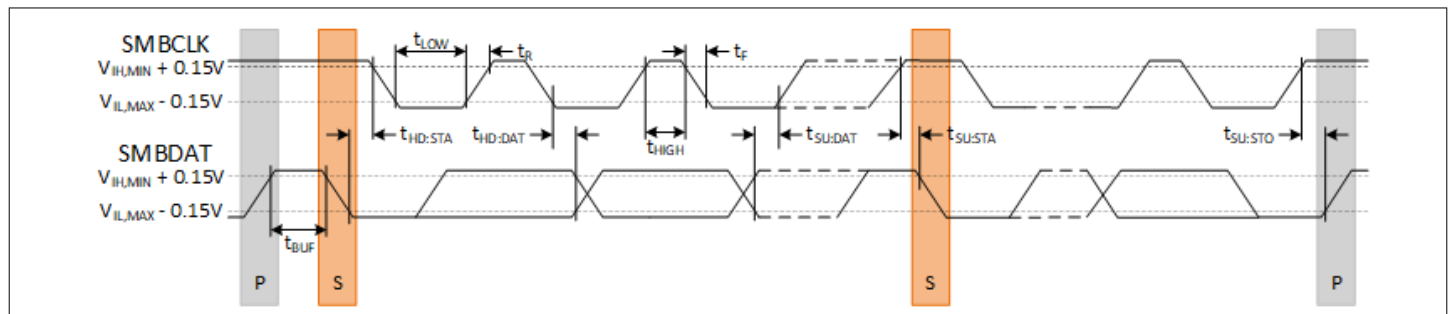
## 4.7 Communication interface

### 4.7.1 PMBus

The power management bus (PMBus) is an open-standard digital power management protocol: simple, standard, flexible, extensible, and easy to program. The PMBus command language enables communication between components of a power system: CPUs, power supplies, power converters, and more.

XDP700 supported features and commands are based on the PMBus Specification Rev 1.3.1 parts I, II and III.

Communication via PMBus is possible right after internal circuitry initialization, which takes around 2 ms after input voltage is applied.



**Figure 13** PMBus timing diagram

PMBus communication is enabled by default. It is possible to disable it by means of the PMBus enable signal, which can be configured in GPO3 pin in the GPO\_CFG command. If it is configured as PMBus enable, a low level on this pin will disable PMBus communication. This feature is useful in case it is desired to configure different addresses in many devices connected to a single bus.

#### 4.7.1.1 Supported functions

The PMBus is specified to cover a lot of different applications in the realm of power management. For a hot-swap application, only a subset of commands is used.

##### 4.7.1.1.1 Addressing

The device has a slave address controlled by PMBUS\_CFG command or by address pins. There are 16 different addresses available for external resistor setting. See [Table 13](#).

##### 4.7.1.1.2 Protocol violations

XDP700 supports the following protocol violations:

- Command not valid
- Command too short
- Data not valid
- Error at repeated start
- Extra Byte in command
- Page not valid
- Read bit set in address
- Read too few bits
- Read too few bytes
- Read too many bytes
- Send too few bits
- Send too many bytes

4.7.1.1.3 Timeout

If a device is holding onto the bus then the bus may freeze. If the microcontroller sees such an issue it may stop the clock for  $t_{\text{TIMEOUT}}$ . This may also happen if another slave holds the bus incorrectly. This causes all slaves to reset their PMBus interfaces and be ready for a new start command.

4.7.1.2 Protocol

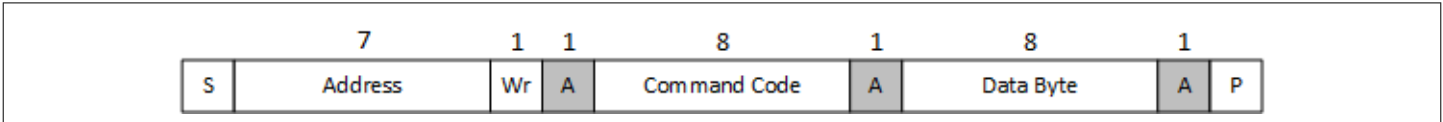


Figure 14 Write Byte protocol

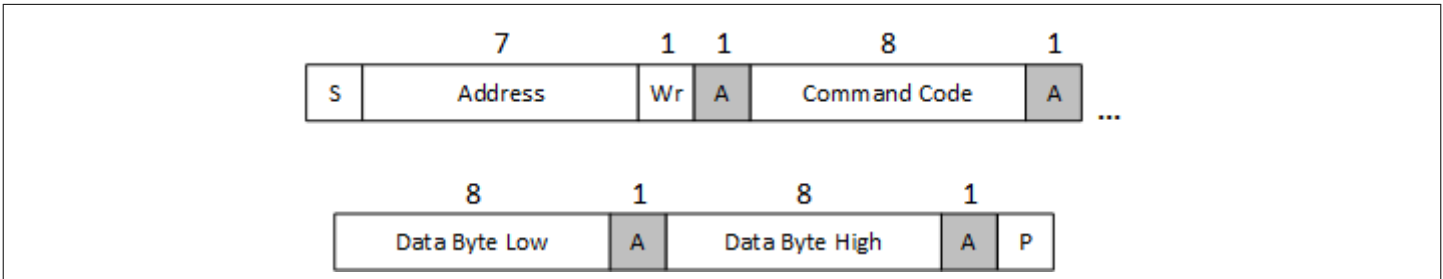


Figure 15 Write Word protocol

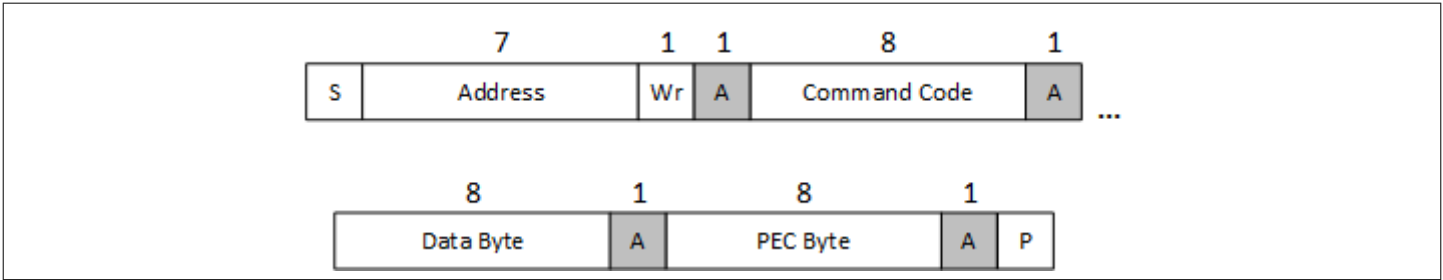


Figure 16 Write Byte protocol with PEC

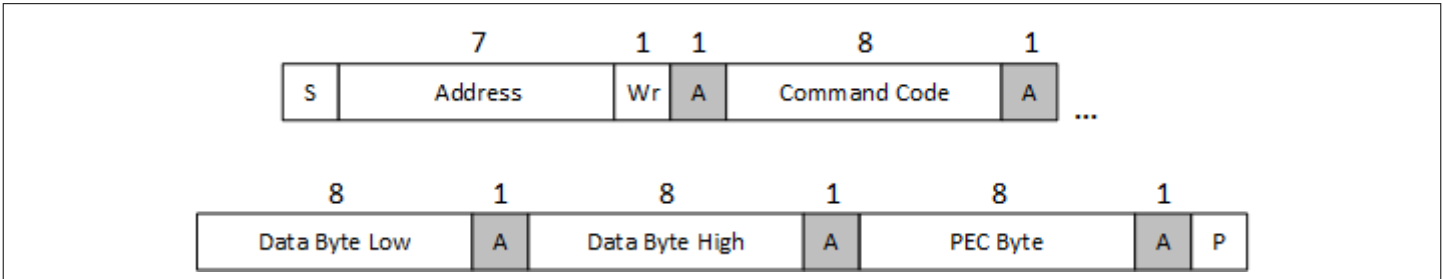


Figure 17 Write Word protocol with PEC

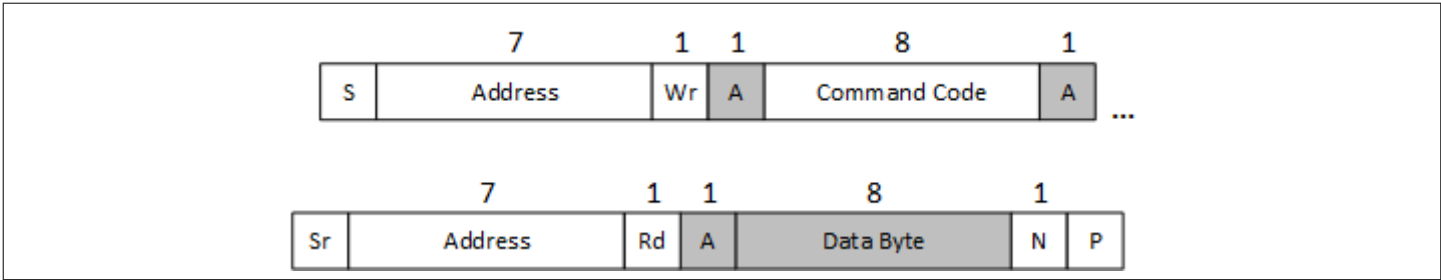


Figure 18 Read Byte protocol

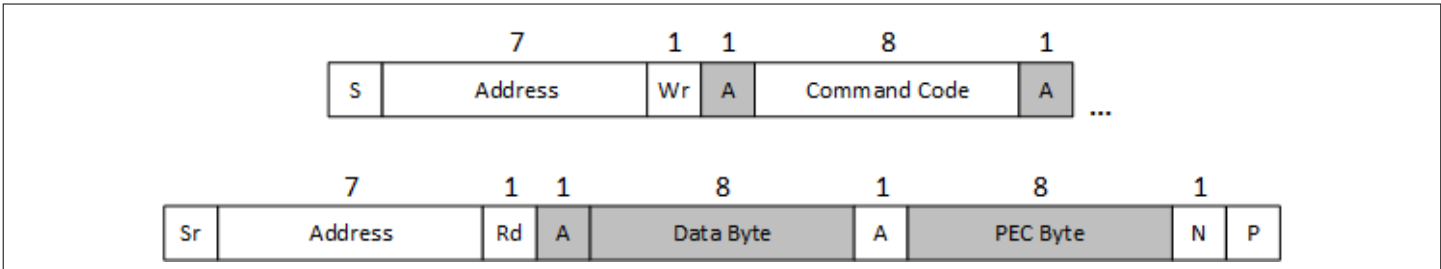


Figure 19 Read Byte protocol with PEC

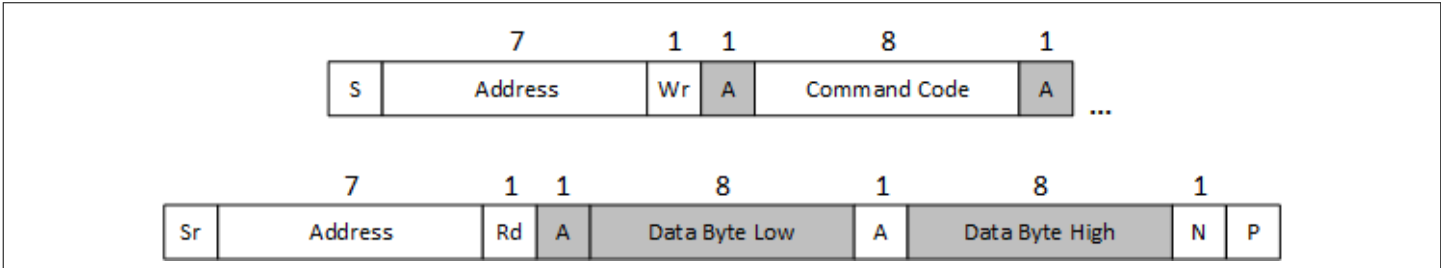


Figure 20 Read Word protocol

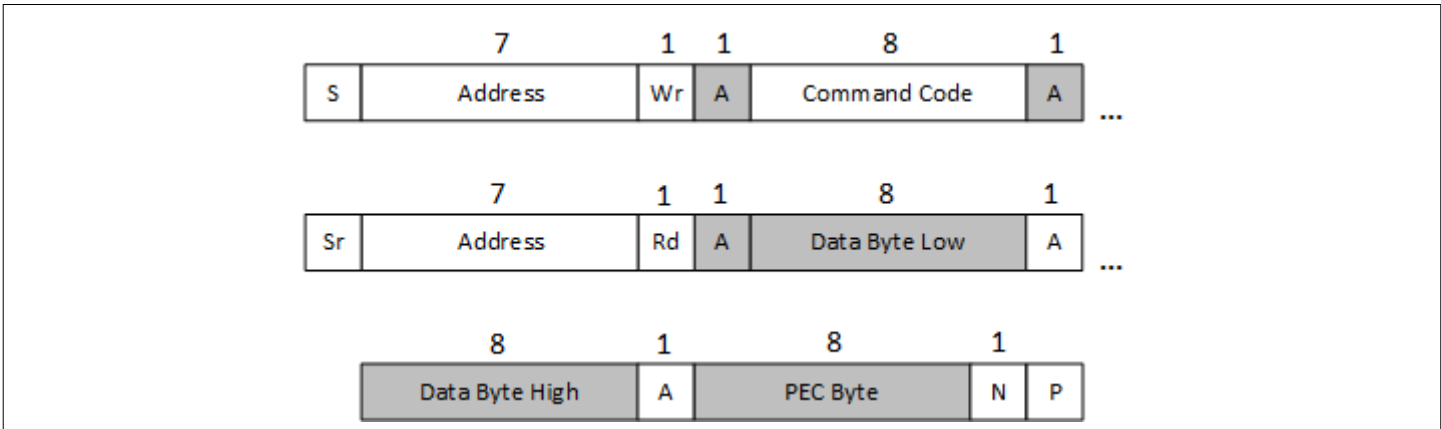


Figure 21 Read Word protocol with PEC

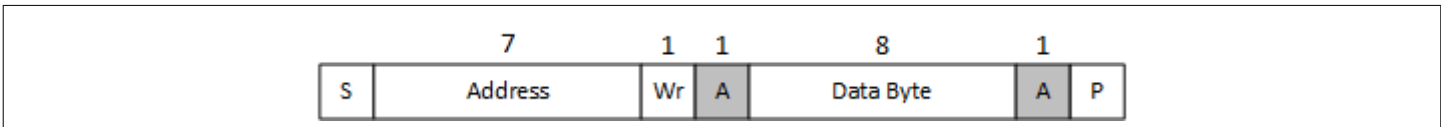


Figure 22 Send Byte protocol

4 Product features

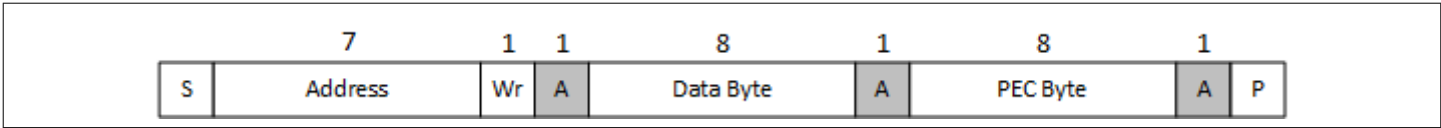


Figure 23 Send Byte protocol with PEC

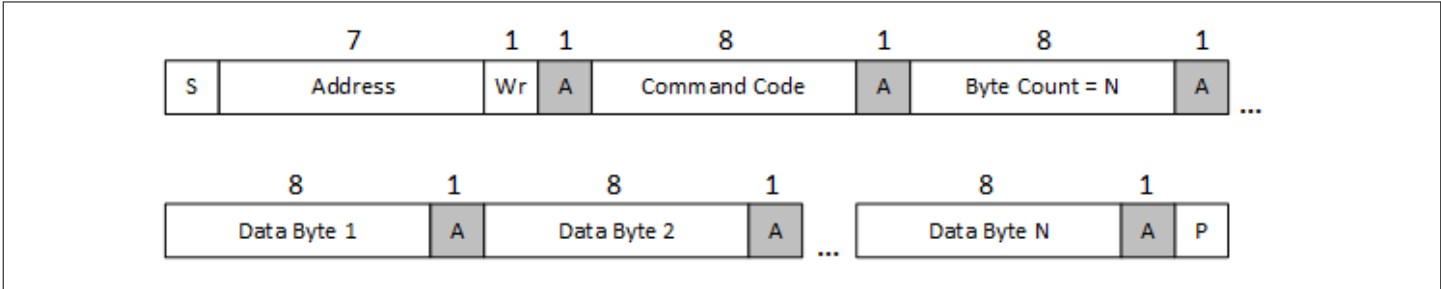


Figure 24 Block Write

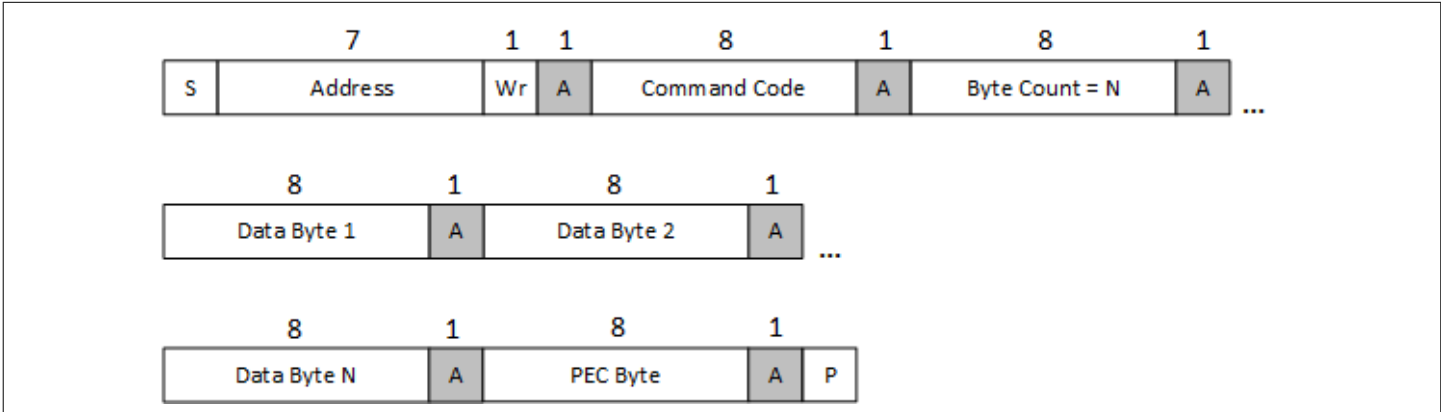


Figure 25 Block Write with PEC

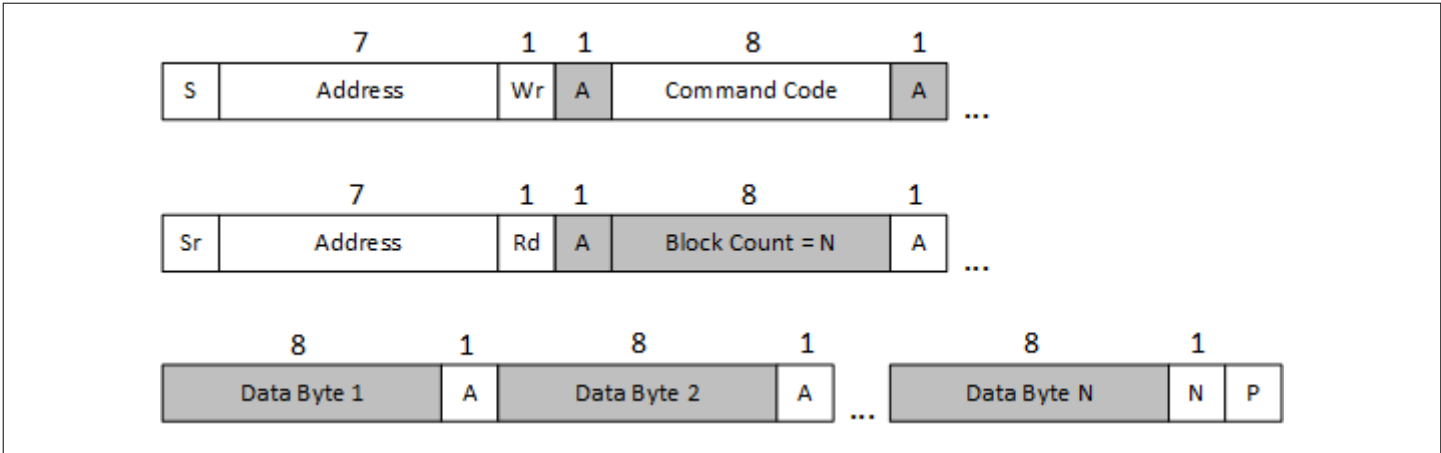


Figure 26 Block Read

4 Product features

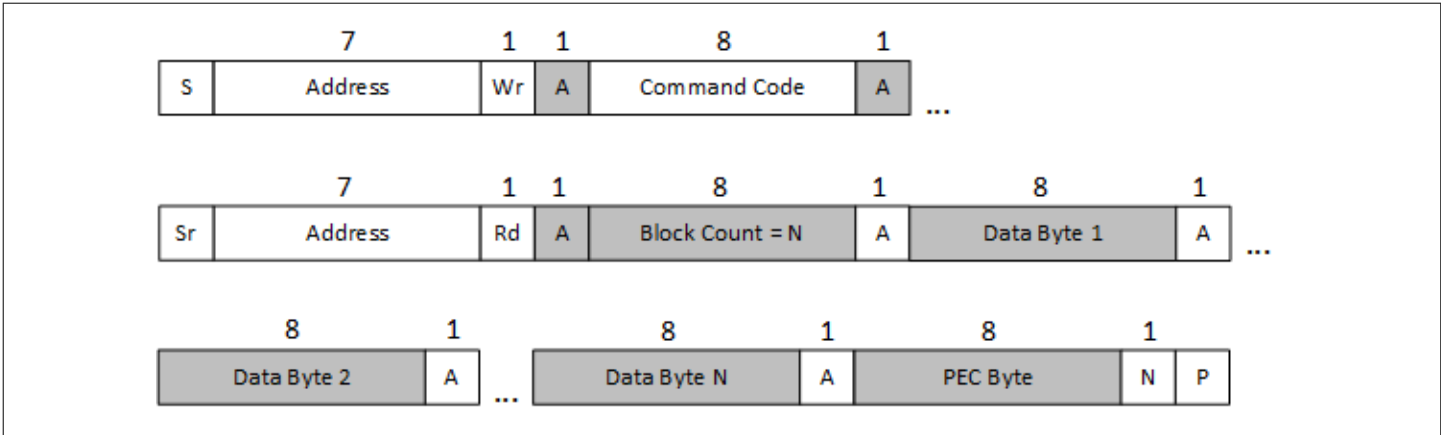


Figure 27 Block Read with PEC

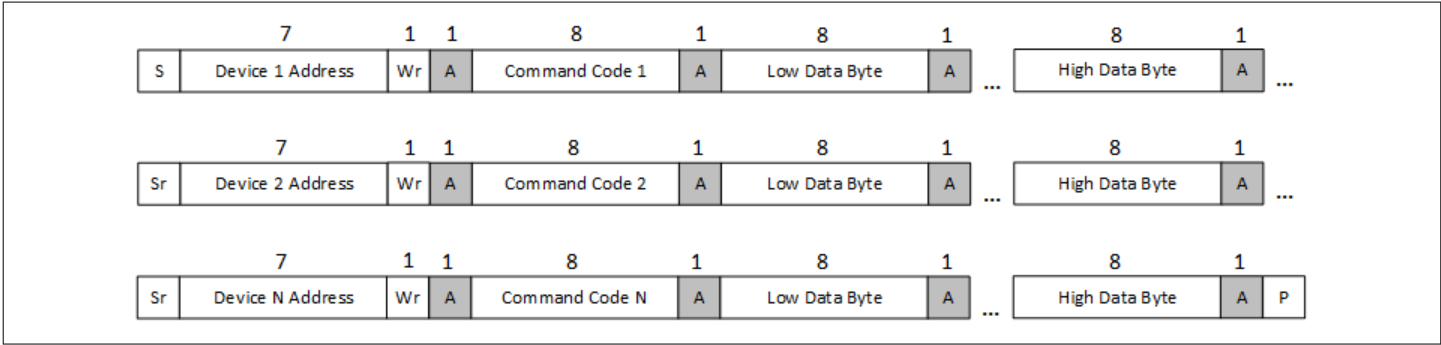


Figure 28 Group Command protocol

4 Product features

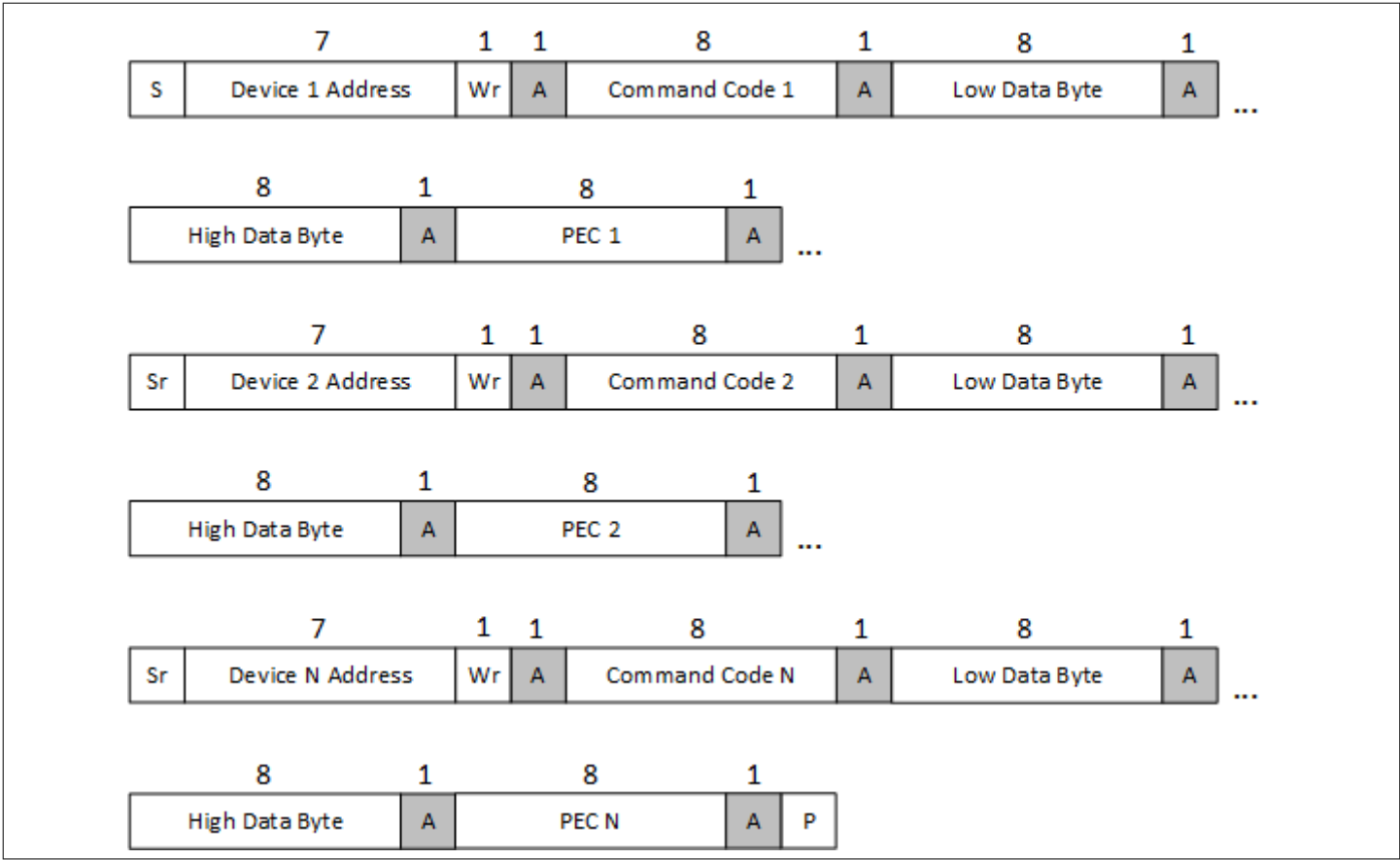


Figure 29 Group Command protocol with PEC

Alert Response Address

XDP700 supports SMBus alert response address. This is a method to allow the microcontroller to locate the device that has issued an alert if there are multiple devices connected to the same bus.

1. Device issues an SMBALERT on GPO1 or GPO3 (depending on GPO\_CFG command configuration). This is just a normal fault being signaled.
2. Microcontroller sends a special address 0x0C with READ bit "1" (i.e. 0x19).
3. Device responds with its own address:
  - If more than one device responds, the lowest address wins and disables its alert.
4. The microcontroller continues to process all alerts by the same process until there are no alerts signaled.

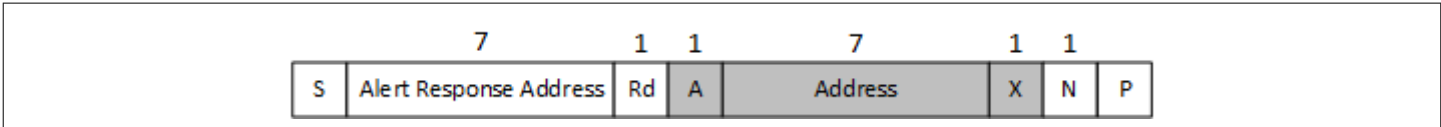


Figure 30 A 7-bit-Addressable Device responds to an ARA



Figure 31 A 7-bit-Addressable Device responds to an ARA with PEC

## 4.8 Memory

XDP700 has three types of memory for programmability:

- Volatile memory
- One time programmable (OTP)
- Multiple time programmable (MTP)

The one time programmable (OTP) memory can be used to fix and save specific command settings. At power-up, during READ\_CFG state, all the settings saved in the OTP memory are copied into volatile memory. OTP memory is partitioned into two sub-sections: One for storing PMBus Register values and another for storing user defined SOA data (SOA PMBus command).

XDP700 contains 10 pages of MTP for a multiple time programmability. When the number of reprogramming reaches 10 (indicated by MTP\_FULL bit in STATUS\_MEM command), the circuit keeps the latest programmed values. The command contained in this memory section is I\_SNS\_CFG, which contains the following configuration bits: CS\_RNG, CS\_RNG\_TRIM, SOC\_FAULT\_LIMIT and START\_ILIM.

To program the desired settings in internal commands or OTP at power-up, the following steps must be followed:

- Apply a voltage at the VDD\_RTN pin:
  - $\geq 6.5$  V to program commands
  - $\geq 20$  V to program OTP or MTP memory
- Keep VDD\_RTNS pin connected to the input voltage source that supplies VDD\_RTN pin. Input voltage level is sensed through VDD\_RTNS to make sure the level is appropriate for OTP programming.
- Keep the UV/EN pin at chip GND potential
- Communication via PMBus is possible as soon as STANDBY state is entered. At this point, commands, OTP or MTP memory can be programmed.
- For a successful programming, internal temperature of the device must stay below 125°C at all times.

To program OTP or MTP sections:

1. Program the commands in volatile memory as desired.
2. Select the section to be programmed by means of the SEL\_SEC bits in WRITE\_OTP command.
3. Set the WRITE\_OTP bit.
4. The command configuration is automatically copied to the selected section.

If the MTP section is selected, XDP700 automatically locates the latest available page and program it.

PROG\_BLOCK and OTP\_FAIL indicate the status of the OTP and MTP memory programming according to the following table:

**Table 30**      **OTP programming status**

| PROG_BLOCK | OTP_FAIL | Meaning                                                                                                                             |
|------------|----------|-------------------------------------------------------------------------------------------------------------------------------------|
| 0          | 0        | OTP, MTP or OTP SOA programming has succeeded if OTP_USER, MTP_USER or SOA_PRG bits are set. Otherwise, programming hasn't started. |
| 0          | 1        | OTP programming started but failed during programming because of OTP issue. Part must be discarded.                                 |
| 1          | 0        | OTP programming must not be started since temperature or input supply are out of range.                                             |

(table continues...)

**Table 30** (continued) OTP programming status

| PROG_BLOCK | OTP_FAIL | Meaning                                                                                                                                             |
|------------|----------|-----------------------------------------------------------------------------------------------------------------------------------------------------|
| 1          | 1        | OTP programming started but failed during programming because temperature or voltage going out of range during programming. Part must be discarded. |

Once programmed, OTP\_USER bit indicates that the OTP memory has been programmed successfully and MTP\_USER bits indicates that MTP memory is in use.

Before programming, PROG\_BLOCK must be checked in order to determine if temperature and VIN are in range and programming is allowed. PROG\_BLOCK indicates the temperature and voltage status in real time. If, after checking PROG\_BLOCK, but before programming starts, any of these conditions goes out of range, programming will be blocked, PROG\_BLOCK will be set and OTP\_FAIL will remain 0. It is possible that, after a blocked attempt of programming, temperature and voltage go back in range, so PROG\_BLOCK will read 0 again. Due to this, it is important to bear in mind that, as long as OTP\_USER and OTP\_FAIL are 0, it is still possible to program OTP.

If temperature and voltage conditions go out of range during programming, OTP\_FAIL will indicate an unsuccessful programming after the operation. If temperature and voltage go back in range, PROG\_BLOCK will read 0 again and it is only OTP\_FAIL that indicates the programming failed.



**Figure 33** Fully digital mode ACM (MODE:MODE=0x0) application schematic

### Equation 7

where  $I_{OC}$  is the maximum desired/allowed constant OC current in Amperes.

Once the resistor is calculated, its value must be chosen from the list provided in the description of the  $RSNS[5:0]$  bits of the  $REG\_CFG$  command. Its value must be set accordingly in these bits. To reduce the power dissipation and for an optimum regulation performance, a sense resistor value between 0.2 mΩ and 10 mΩ is mandatory.

The current sense ADC is designed to sense a maximum current of 83.3 A. Care must be taken when selecting the sense resistor value so that this limit is not exceeded. In addition to the  $V_{SNS\_CS}$  level, the current limit can be trimmed by means of the  $CS\_RNG\_TRIM[7:0]$  bits, according to the following formula:

$$LIMIT = \frac{I_{OC\_TRIMMED} * R_{SNS} * 180.31}{V_{SNS\_CS}}$$

**Equation 8**

Where  $LIMIT$  is the decimal value to be programmed in the command,  $I_{OC\_TRIMMED}$  is the desired current limit value in Amperes,  $R_{SNS}$  is the value of the chosen current sense resistor in mΩ and  $V_{SNS\_CS}$  is the programmed OC value in mV.

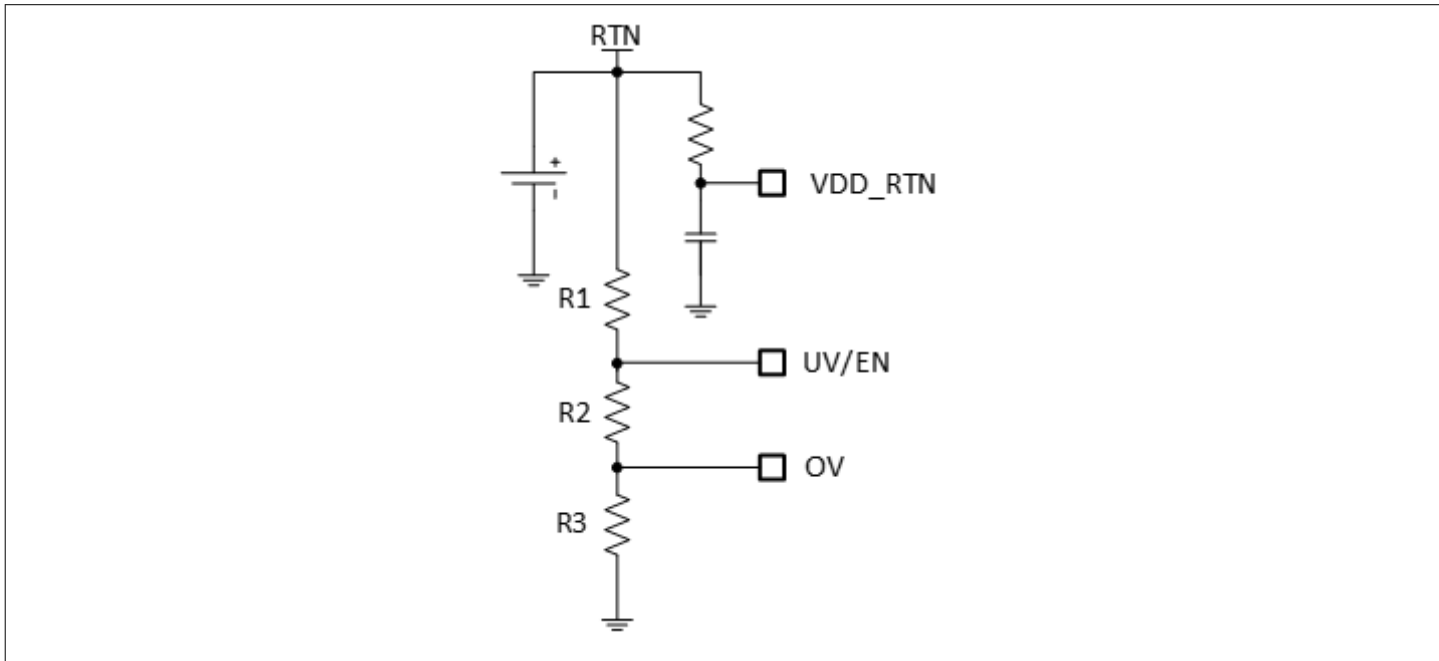
**Note:** For an optimum stability operation,  $I_{OC}$  must be  $\geq I_{OC\_MIN}$ . If a current limit lower than this is needed, it can be trimmed by means of the  $CS\_RNG\_TRIM[7:0]$  bits. The following table shows minimum and maximum recommended sense resistor values for each one of the  $V_{SNS\_CS}$  settings:

**Table 31** Minimum and maximum recommended sense resistor values

| $V_{SNS\_CS}$ | Min $R_{SNS}$ (mΩ) | Equivalent $I_{OC}$ with Min $R_{SNS}$ (A) | Max $R_{SNS}$ (mΩ) | Equivalent $I_{OC}$ with Max $R_{SNS}$ (A) |
|---------------|--------------------|--------------------------------------------|--------------------|--------------------------------------------|
| 12.5          | 0.2                | 62.5                                       | 2.5                | 5                                          |
| 25            | 0.3                | 83.3                                       | 5                  | 5                                          |
| 50            | 0.6                | 83.3                                       | 10                 | 5                                          |
| 100           | 1.2                | 83.3                                       | 10                 | 10                                         |

### 5.3 Setting OV and UV in ACM

OV and UV values are set with a three resistor voltage divider, as shown in the following figure:



**Figure 35** Setting OV and UV in ACM

Calculate the resistors values according to the application specific parameters using the following formulas:

$$R3 = \frac{R_{TOTAL} * OV_{REF}}{V_{OV}}$$

**Equation 9**

$$R2 = \frac{R_{TOTAL} * UV_{REF}}{V_{UV}} - R3$$

**Equation 10**

$$R1 = R_{TOTAL} - R2 - R3$$

**Equation 11**

Where  $V_{OV}$  and  $V_{UV}$  are desired OV and UV levels respectively,  $OV_{REF} = V_{OV\_UTH}$ ,  $UV_{REF} = V_{UVEN\_LTH}$  and  $R_{TOTAL}$  is calculated after the desired current flow (typically hundreds of  $\mu A$ ).

Care must be taken to avoid exceeding the maximum voltage level at the OV or UV pins.

## 5.4 Setting the voltage at MODE1/0 pins in AADM

To set the desired voltage at the MODE1/0 pins, choose the resistor from corresponding pin to GND by dividing desired voltage over pin current ( $100 \mu A \pm 7\%$ ).

Due to the wide voltage range, 5% tolerance resistors can be used:

**Table 32** Setting MODEx pins voltage

| Voltage (V) | MODE1/0 pin resistor (k $\Omega$ ) |
|-------------|------------------------------------|
| 1.2         | 12                                 |
| 2.0         | 20                                 |

## 5.5 Setting the voltage at ADDR1/0 pins

To set the voltage at the ADDR1/0 pins, choose the resistor from corresponding pin to GND by dividing desired voltage over pin current ( $100 \mu A \pm 7\%$ ).

Due to the wide voltage range, 5% tolerance resistors can be used:

**Table 33** Setting ADDRx pins voltage

| Voltage (V) | ADDR1/0 pin resistor (k $\Omega$ ) |
|-------------|------------------------------------|
| 1.2         | 12                                 |
| 2.0         | 20                                 |

## 5.6 Handling external current at VREG pin

An internal LDO provides 5 V (typically) supply for the internal circuitry and could also be used as voltage reference for communication pull-up resistors.

Its current capability to supply external circuitry is 10 mA. Make sure not to exceed the package maximum power dissipation  $P_{PAK}$ .

To calculate the additional power due to external load:

$$P_{REG\_EXT} = ABS(VDD\_RTN - VREG) * i_{REG}$$

**Equation 12**

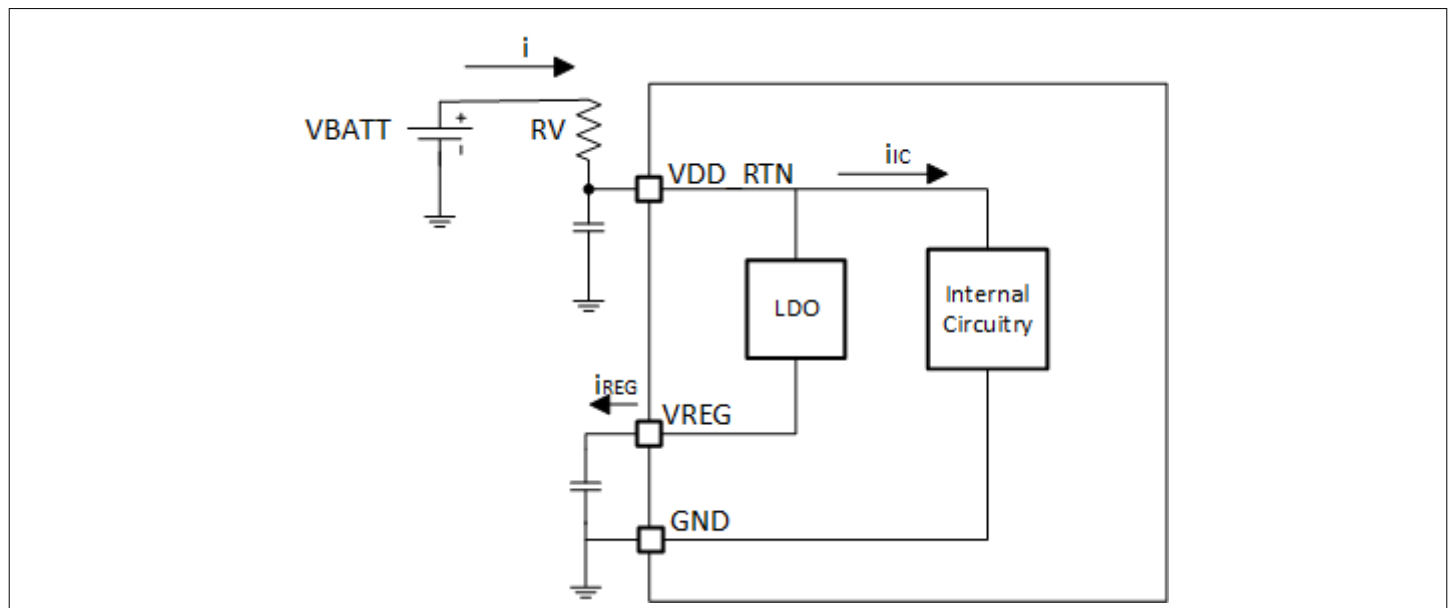
So, in the case of a -48 V input application (where  $VDD\_RTN = 48$  V with respect to the input voltage), with a 10 mA load on  $VREG = 5$  V:

$$P_{REG\_EXT} = ABS(48V - 5V) * 10mA = 430mW$$

**Equation 13**

The rest of current consumption comes from controller's circuitry.

To keep the package power dissipation within the  $P_{PAK}$  limit and allow additional consumption due to external load of LDO, a shunt resistor may be required at the  $VDD\_RTN$  pin in high input voltage applications. It helps not to exceed the  $P_{PAK}$  limit:



**Figure 36 Handling external current at VREG pin.**

To calculate RV:

$$RV = \frac{P_{TOT} - P_{PAK}}{i^2} = \frac{VBATT}{i} - \frac{V_{REG} \times i_{REG} + P_{PAK}}{i^2}$$

**Equation 14**

where:

$$P_{TOT} = VBATT \times i - VREG \times i_{REG}$$

**Equation 15**

and  $P_{PAK} = 0.8\text{ W}$ ,  $V_{REG} = 5\text{ V}$  (typically),  $i_{REG}$  is the expected current consumption of the external circuitries supplied by  $V_{REG}$  and  $i$  is the expected current consumption of the whole device supplied by  $V_{BATT}$ .

So, for an expected maximum internal current consumption ( $i_{IC}$ ) of 10 mA:

$$i = i_{IC} + i_{REG} = 10\text{ mA} + 10\text{ mA} = 20\text{ mA}$$

#### Equation 16

$$RV = \frac{VBATT}{i} - \frac{VREG \times i_{REG} + P_{PAK}}{i^2} = \frac{48\text{ V}}{20\text{ mA}} - \frac{5\text{ V} \times 10\text{ mA} + 0.8\text{ W}}{(20\text{ mA})^2} = 275\Omega$$

#### Equation 17

The power dissipated by the resistor is:

$$P_{RV} = i^2 \times RV = (20\text{ mA})^2 \times 275\Omega = 0.11\text{ W}$$

#### Equation 18

**Note:** A negative result in the calculation of the resistance  $RV$  means that the total power dissipation of the package  $P_{PAK}$  is not being exceeded. In this case,  $RV$  is not needed.

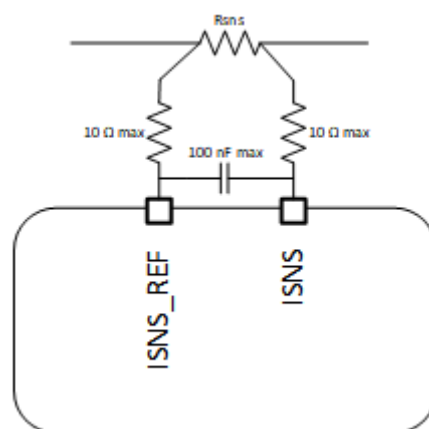
To protect XDP700, if the die temperature goes above  $163 \pm 10^\circ\text{C}$ ,  $V_{REG}$  is turned off. Thus, communication is not possible and the status of FAULT, WARN, PWRGD and GPOs is not reliable.

#### Special considerations:

- $RV$  must be limited to  $1\text{ k}\Omega$  max.
- If  $RV$  is used, a  $100\text{ nF}$  cap from  $V_{DD\_RTN}$  to GND is mandatory.
- If it is desired to program OTP, care must be taken that the necessary voltage ( $20\text{ V}$ ) is applied directly at  $V_{DD\_RTN}$  pin, taking into account the voltage drop on  $RV$ .

## 5.7 ISNS input filter

In noisy or high  $dV/dt$  applications, an input filter from  $RSNS$  to  $ISNS\_REF$  and  $ISNS$  pins is recommended as shown in the following figure.



**Figure 37** ISNS input filter

## 5.8 FET selection considerations

Due to the increased gate current of Infineon's Linear FET over 125°C, its compatibility with XDP700 is limited to this temperature level. Make sure that the junction temperature of the Linear FET does not exceed this value and that the corresponding temperature protections are set accordingly.

When selecting a FET, the following guidelines must be observed:

- Plateau voltage of the FET must be lower than XDP700 detection level of enhancement (7.8 V typically).
- SOA of the FET and system input voltage will determine the current with which the output capacitor will be charged, thus, the start-up time. Wide SOA will translate into faster start-up time. If a specific start-up time is required, care must be taken to select a FET with an SOA that allows it.
- Control loop's minimum current regulation capability in continuous SOA regulation start-up mode is 0.25 A. Any FET's target  $I_{SOA}$  values lower than this value will be rounded up. Therefore, if, for example, a specific FET's SOA specifies a maximum current  $I_D$  of 0.1 A at a  $V_{DS}$  of 48 V, the current is regulated to 0.25 A and the SOA is violated. It is recommended for the FET to withstand a minimum current of 0.25 A at any point of its SOA. Alternatively, Boost Mode can be used to turn on weak FETs.
- If multiple FETs in parallel are used, their SOA must not be divided by the number of FETs, but single FET SOA must be programmed. Paralleling must be considered to reduce  $R_{ds(on)}$  only.
- IREG feature must be disabled when using Linear FET in the system. In other words, SOAR\_TMR must be set to 0.
- At FET power up, the  $V_{gs}$  control by the loop might be affected by reaching FET's plateau level, but FET's current continues to be limited as well as SOA target follows FET's  $V_{ds}$ . This can be more pronounced with LinearFETs. For LinearFETs, it is recommended to set start-up current limit IST in the way that  $V_{gs}$  is below plateau level at the end of regulation phase. It will ensure a smooth start-up behavior. The same is valid for OC level with standard FETs to ensure proper current regulation.
- Low  $Z_{th(jc)}$  helps with power dissipation during linear mode.
- Low zero temperature coefficient (ZTC) point avoids staying in thermal instability region for too long.

## 5.9 Calculating PMBus direct format limits from "real world" values and vice-versa

### 5.9.1 Voltage

Voltage limits calculations are straight forward using the formulas and coefficients specified in [Telemetry via PMBus](#). As an example, the VIN\_OV\_FAULT\_LIMIT is taken.

System characteristics and configuration:

VTLM\_RNG = 88 V

Based on VTLM\_RNG value, from the coefficients table:

$m = 4653$

$b = 0$

$R = -2$

For a VIN\_OV\_FAULT\_LIMIT of 64 V, the following formula is applied:

$$Y = (mX + b) * 10^R$$

**Equation 19**

$$Y = (4653 * 64 + 0) * 10^{-2}$$

**Equation 20**

$$Y = 2978 = 0xBA2$$

#### Equation 21

So the value to be programmed in VIN\_OV\_FAULT\_LIMIT is 0xBA2.

To convert from PMBus direct format to "real world" value, let's suppose the value from the ADC in the READ\_VIN command is 0x8B9 = 2233 decimal. System characteristics, configuration and coefficients are the same as above. The following formula is applied:

$$X = \frac{1}{m} * (Y * 10^{-R} - b)$$

#### Equation 22

$$X = \frac{1}{4653} * (2233 * 10^2 - 0)$$

#### Equation 23

$$X = 48V$$

#### Equation 24

### 5.9.2 Current

Values in [Table 29](#) are normalized to a 1 mΩ resistor. Therefore, to convert to a PMBus direct format value, result has to be divided over the value of the sense resistor in mΩ. And to convert to a "real world" value, the result must be multiplied. For example, if a value of 35 A is desired for IOUT\_OC\_WARN\_LIMIT:

System characteristics and configuration:

$R_{sns} = 0.5 \text{ m}\Omega$

$V_{SNS\_CS} = 12.5 \text{ mV}$

Based on  $V_{SNS\_CS}$  value, the coefficients are:

$m = 23165$

$b = 0$

$R = -2$

To get the limit value, the following formula is applied:

$$Y = ((mX + b) * 10^R) * R_{sns}(m\Omega)$$

#### Equation 25

$$Y = ((23165 * 35 + 0) * 10^{-2}) * 0.5$$

#### Equation 26

$$Y = 4054 = 0xFD5$$

#### Equation 27

So the value 0xFD5 must be programmed in IOUT\_OC\_WARN\_LIMIT.

Similarly, to obtain the "real world" value from the ADC reading in READ\_IOUT. Let's suppose the reading is 0x910 = 2320 decimal. The following formula is applied:

$$X = \frac{\frac{1}{m} * (Y * 10^{-R} - b)}{Rsns(m\Omega)}$$

**Equation 28**

$$X = \frac{\frac{1}{23165} * (2320 * 10^2 - 0)}{0.5}$$

**Equation 29**

$$X = \frac{10}{0.5} = 20A$$

**Equation 30**

READ\_IOUT\_RMS is a 16 bit field, so coefficients are different:

m = 20808

b = 0

R = -2

If the ADC reading is 0x1048 = 4168 decimal, the "real world" value is obtained as follows:

$$X = \frac{\frac{1}{20808} * (4168 * 10^{-2} - 0)}{0.5}$$

**Equation 31**

$$X = \frac{20}{0.5} = 40A^2$$

**Equation 32**

### 5.9.3 Power

Input power is the result of multiplying input voltage times the current. Power coefficients are also normalized to 1 mΩ, so it is also necessary to multiply or divide by the sense resistor value in mΩ to obtain direct format or "real world" values respectively.

If a 1100 W value is desired as PIN\_OP\_WARN\_LIMIT:

System characteristics and configuration:

VTLM\_RNG = 88 V

Rsns = 0.5 mΩ

V<sub>SNS\_CS</sub> = 12.5 mV

Based on these, coefficients are:

m = 4211

b = 0

R = -2

To obtain the limit, the following formula is applied:

$$Y = ((mX + b) * 10^R) * Rsns(m\Omega)$$

**Equation 33**

$$Y = ((4211 * 1100 + 0) * 10^{-2}) * 0.5$$

**Equation 34**

$$Y = 23159 = 0x5A77$$

**Equation 35**

So the value 0x5A77 must be programmed in PIN\_OP\_WARN\_LIMIT.

The power reading can be 16 bits (READ\_PIN) or 24 bits (READ\_PIN\_EXT). In the case of READ\_PIN, coefficients are the same as specified for PIN\_OP\_WARN\_LIMIT. So, if the reading of READ\_PIN is 0xCD9A = 52634 decimal, the following formula is applied:

$$X = \frac{\frac{1}{m} * (Y * 10^{-R} - b)}{Rsns(m\Omega)}$$

**Equation 36**

$$X = \frac{\frac{1}{4211} * (52634 * 10^2 - 0)}{0.5}$$

**Equation 37**

$$X = 2500W$$

**Equation 38**

If 24 bits power reading is desired (READ\_PIN\_EXT), corresponding coefficients based on the system characteristics and configuration specified above are:

$m = 10780$

$b = 0$

$R = 0$

For an example reading of 0xB4EE53 = 11857491 decimal, the formula becomes:

$$X = \frac{\frac{1}{10780} * (11857491 * 10^0 - 0)}{0.5}$$

**Equation 39**

$$X = 2200W$$

**Equation 40**

### 5.9.4 Temperature

Temperature calculation is straight forward too and it only requires to apply the coefficients to the formulas. If an OT\_FAULT\_LIMIT of 150°C is desired, the corresponding coefficients are:

$$m = 52$$

$$b = 14321$$

$$R = -1$$

By applying the direct format formula, the following is obtained:

$$Y = (mX + b) * 10^R$$

#### Equation 41

$$Y = (52 * 150 + 14321) * 10^{-1}$$

#### Equation 42

$$Y = 2212 = 0x8A4$$

#### Equation 43

So the value 0x8A4 must be programmed in OT\_FAULT\_LIMIT.

**Note:** OT\_FAULT\_LIMIT can be programmed from -273°C (0x000) to 512°C (0xFFFF). Care must be taken to program it within the FET operating temperature range.

The reading from READ\_TEMPERATURE\_1 is translated to "real world" by solving the equation for X. If the reading is 0x7A0 = 1952 decimal:

$$X = \frac{1}{m} * (Y * 10^{-R} - b)$$

#### Equation 44

$$X = \frac{1}{52} * (1952 * 10^1 - 14321)$$

#### Equation 45

$$X = 100^{\circ}\text{C}$$

#### Equation 46

### 5.9.5 Energy

Energy is calculated based on 16 bits power, therefore, the same coefficients shall be used. Two readings of the READ\_EIN register are required. Since energy is power times time, it is also required to know the time between the samples.

In the following example, system characteristics and configuration are:

$$VTLM\_RNG = 88 \text{ V}$$

$$Rsns = 0.5 \text{ m}\Omega$$

# XDP700-002 Hot-swap Controller

## Wide input voltage range (-6.5 V to -80 V) system monitoring and protection IC



### 5 Application information

$V_{SNS\_CS} = 12.5 \text{ mV}$

Based on these, from [Table 29](#), coefficients are:

$m = 4211$

$b = 0$

$R = -2$

The samples read are:

**Table 34** Energy read samples

|                       | First Sample |      | Second Sample |       |
|-----------------------|--------------|------|---------------|-------|
|                       | Hex          | Dec  | Hex           | Dec   |
| <b>SAMPLE_COUNT</b>   | 1000         | 4096 | 3DC7          | 15815 |
| <b>ROLLOVER_COUNT</b> | 10           | 16   | FF            | 255   |
| <b>ENERGY_COUNT</b>   | 01FF         | 511  | 1FAC          | 8108  |

First, the power difference is calculated by subtracting the ENERGY\_COUNT of the first sample from the second sample. Note that the ENERGY\_COUNT is concatenated with the ROLLOVER\_COUNT:

$$\text{Power difference} = 0xFF1FAC - 0x1001FF = 0xEF1DAD$$

#### Equation 47

Next step is to calculate the SAMPLE\_COUNT difference by subtracting the SAMPLE\_COUNT of both samples:

$$\text{Sample count difference} = 0x3DC7 - 0x1000 = 0x2DC7 = 11719d$$

#### Equation 48

Then the average power per sample is calculated by dividing the power difference over the sample count difference:

$$\text{Average power} = \frac{0xEF1DAD}{0x2DC7} = 0x539 = 1337d$$

#### Equation 49

Now X can be determined by using the PMBus direct format formula:

$$X = \frac{\frac{1}{m} * (Y * 10^{-R} - b)}{Rsns(m\Omega)}$$

#### Equation 50

$$X = \frac{\frac{1}{4211} * (1337 * 10^2 - 0)}{0.5}$$

**Equation 51**

$$X = 63.5W$$

**Equation 52**

The time between samples can either be measured or calculated. XDP700 ADC conversion rate is 102.4μs. This is also the time it takes to get a sample of energy, so the time between samples can be determined by multiplying the SAMPLE\_COUNT difference times 102.4μs:

$$11719 * 102.4\mu s = 1.2s$$

**Equation 53**

Finally, energy is determined by multiplying power times time:

$$E = 63.5W * 1.2s$$

**Equation 54**

$$E = 76.2J$$

**Equation 55**

## 5.10 Layout guidelines

The following guidelines shall be followed when designing an XDP700 PCB:

- Maximum supply current of the XDP700 is 10mA. The traces at supply pin VDD\_RTN don't need to be that thick.
- VREG capacitor must be placed right next to the VREG pin. - I2C traces need a single-ended controlled impedance of 50 Ω. Therefore their width must be adjusted accordingly. - TSNS filter capacitor must be placed right next to the TSNS pins.
- If used, TSNS BJT shall be placed right next to the FET or to the point to be sensed. It is best to place the sensor next to the hottest part of the FET package. In the case of our D2PAK FETs, the die is attached to the drain pad on bottom of the package, so this is the section that will get hotter in case of high power dissipation.
- Keep gate trace as short as possible in order to reduce parasitics. This trace and the source one must be able to handle 1.5 A current, which is the current that will flow through them in order to discharge the gate of the FET in case of a fast turn-off event.
- ISNS filter capacitor also has to be placed right next to the ISNS pins. - Exposed pad must have a solid connection to GND through many vias.
- The path that will need to handle the highest amount of current goes from the input voltage source, through the sense resistor, FET and output capacitor to the load, including its corresponding return path to ground. Make sure this path is robust enough to support the current level required by the system.
- ISNS lines must be connected directly to sense pins of the sense resistor, separately from the power plane.

6 Ordering information

Table 35 Ordering information

| Basic part number | Orderable part number | Description                                 |
|-------------------|-----------------------|---------------------------------------------|
| XDP700-002        | XDP700002XUMA1        | Negative input voltage hot-swap controller. |

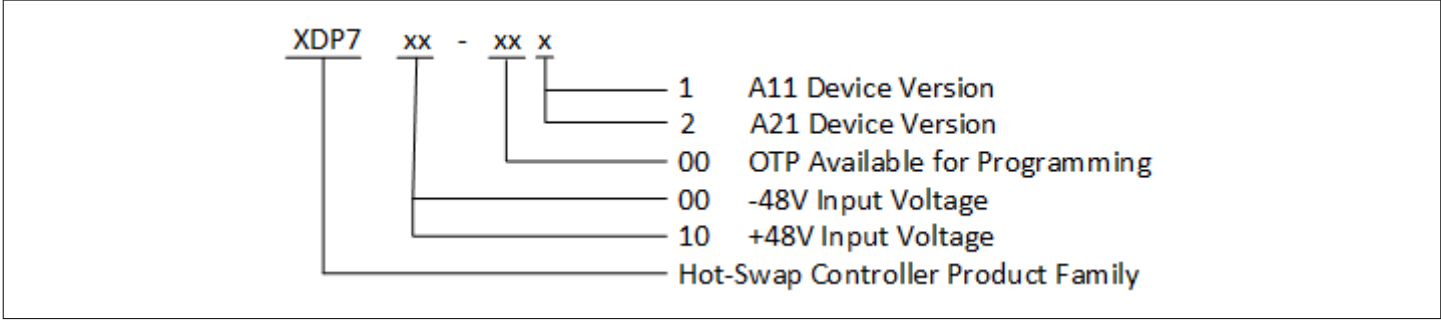


Figure 38 Naming conventions



7Revision history

| Revision | Date       | Subjects (major changes since last revision) |
|----------|------------|----------------------------------------------|
| 1.0      | 2024-01-15 | First release.                               |
|          |            |                                              |

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**Edition 2024-01-15**

**Published by**

**Infineon Technologies AG**  
**81726 Munich, Germany**

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